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NAGOYA, JAPAN

DATA COMPILATION OF ANGULAR DISTRIBUTIONS OF SPUTTERED ATOMS

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I. INTRODUCTION

Sputtering at a surface is generally caused by a collision cascade developed near the surface. The process is in principle the same as those causing radiation damage in the bulk of a solid. Sputtering has long been regarded as an undesired dirty effect which destroys the cathodes and grids in gas discharge tubes or ion sources and contaminates a plasma and the surrounding walls. However, sputtering is used today for many applications. The removal of atoms from a surface is successfully applied in sputter ion sources, a mass spectrometer and to the deposition of thin films on a large variety of substrates. Plasma contamination and surface erosion of the first wall due to sputtering are still one major problem in fusion research.

From the early 1960's a lot of measured angular distributions of sputtered atoms at normal incidence and oblique incidence have been accumulated. For better understanding of the sputtering phenomena and for the extensive use of the sputtering data for the design of the fusion reactors, we need to compile experimental data of the energy dependent sputtering yields and the differential sputtering yields such as angular distribution and energy distribution of sputtered particles. Concerning the energy-dependent sputtering yields a series of IPPJ-AM reports have been published at the Institute of Plasma Physics, Nagoya University [1,2,3].

The angular distribution of particles sputtered from solid surfaces can possibly provide more detailed informations on the collision cascade in the interior of the target. This report presents a compilation of the angular distribution of sputtered atoms at normal incidence and at oblique incidence for various combinations of incident ions and target atoms. The main concern of this report is the angular distribution of sputtered atoms from monatomic solids at normal incidence and oblique incidence.

II. ANGULAR DISTRIBUTIONS OF SPUTTERED ATOMS FROM MONATOMIC SOLID AT NORMAL INCIDENCE

The collision cascade theory of sputtering [4], which is generally considered to give a good quantitative description of the sputtering process, predicts a cosine distribution of the sputtered atoms. According to the linear collision theory, the recoil flux per incident ion with energy E and angle of incidence θ is the average number of recoils flying at depth x with energy (E_0, dE_0) in the direction (Ω_0,

$d\Omega_0$) per unit time which is given as [5]

$$F(E,\theta\ ;\ E_0,\Omega_0)dE_0d\Omega_0 = dE_0d\Omega_0 \frac{\Gamma\ F_D(E,\theta\ ;x)}{4\pi\ E_0^2}, \quad (1)$$

where $F_D(E,\theta\ ;\ x)$ is the average energy deposited into recoils at depth (x,dx) and Γ is a numerical constant. The corresponding angular distributions $Y(E,0;\theta_2)$ at normal incidence show the cosine distribution, i.e.,

$$Y_2(E,\ 0;\theta_2) = \frac{\Gamma\ F_D(E,0,0)\cos\theta_2}{8\pi\ (1-m)(1-2m)U_s^{1-2m}}, \quad (2)$$

where U_s is the surface binding energy, θ_2 is the ejection angle of a sputtered atom, and m is the number between 0 and 1 for the power approximation.

It has long been realized that the expected cosine distribution was not found universally even for the ion energy in the region where cascade theory describes the yields with good accuracy and that the experimental angular distribution varies with energy of incidence [6]. At very low energy - close to the threshold - it is difficult that a low-energy projectile produces a well-developed collision cascade [7,8], and the resulting distributions are heart-shaped in the polar diagram. At higher projectile energies, a cosine distributions is obtained but at even higher energies the distributions becomes over-cosine, i.e., more outward peaked than the cosine.

Now, there are two possible explanations for the over-cosine distributions. The one possibility is that the surface introduces an asymmetry causing the recoil flux in the cascade to be anisotropic at the surface [9]. Another explanation is done by so called "missing-plane model" that the distributions are strongly influenced by outward scattering neighboring atoms at the topmost layer. Within the solid such a scattering does also take place within any plane but is compensated by scattering in the plane at the surface above. The nonexistence of this "-1" plane at the surface makes the angular distributions outward peaked [10].

The over-cosine distributions are well fitted by the fitting formula $\cos^n\theta$, and the exponent n is a good index of the over cosine distribution. The sputtering yields are measured under the rough surface of which the topography is induced by heavy ion-bombardment used for the measurement, mostly larger than 10^{18} ions/cm^2. The ion-induced surface roughness reduces the degree of the over cosine distribution. Another important factor which affect the angular distribution is a surface contamination. The surface contamination brings the strong outward-peaked distribution.

III . ANGULAR DISTRIBUTIONS OF SPUTTERED ATOMS FROM MONATOMIC SOLID AT OBLIQUE INCIDENCE.

The angular distributions of sputtered atoms at grazing incidence are composed of two parts, i.e., the random part and a few collision process, where the random part means the contribution of well developed collision cascades near the surface. Since the well-developed cascades do not have the memory of the ion-beam direction, the angular distribution of sputtered atoms due to well-developed cascades will obey the cosine distribution. While the angular distributions due to a few-collision process have the explicit preferential angle of ejection.

It is very difficult to estimate analytically the preferential ejection angle due to a few collision process. In place of a few collision process for sputtering, let us consider a single collision process for sputtering, i.e., a direct knock-out process. According to the direct knock-out model [11], the preferential angle β of ejection due to a single collision between an incident ion with energy E and a target atom is roughly given as [11]

$$\beta = \sin^{-1} \{(\cos\theta + q)(\cos\theta + 2q)\}^{1/2} , \qquad (3)$$

where $q = [U_s/\gamma E]^{1/2}$ with $\gamma = 4M_1M_2/(M_1 + M_2)^2$, and β is measured from the surface normal. This simple relation tells us that we can get the following scaling rule for the preferential ejection angle

$$\frac{\sin\beta}{\cos\theta} = \{(1 + X)(1 + 2X)\}^{1/2} , \qquad (4)$$

where $X = [U_s/\gamma E]^{1/2}/\cos\theta$.

Ⅳ. COMPILATION OF THE DATA OF ANGULAR DISTRIBUTIONS OF SPUTTERED ATOMS

The angular distribution of sputtered atoms for all available combinations of the incident ions and target atoms up to the early 1989 have been compiled and stored in the computer. Table 1 shows a classification of available papers concerning angular distributions of sputtered atoms published for these four decades. Table 2 shows a list of available publications, and we classified these references into four categories, i.e., monatomic target (Table 3), multi-component material (Table 4), theory and computer simulation (Table 5) and review work (Table 6). Table 7 shows brief reviews of experimental works listed in Tables 3 and 4. In order to know the magnitude of the over-cosine distributions of sputtered atoms from monatomic solids we employed the fitting formula $\cos^n\theta$. In Table 8 the best-fit n values of experimental angular distributions at normal incidence are listed for monatomic solids, and these n values are plotted against γE in Fig. 1. Table 9 shows experimental preferential ejection angles, where the ejection angle is measured from the surface normal. Plots of $\sin\beta_{ex}/\cos\theta$ are shown in Fig. 2 for various angles of incidence, various ion-target combinations in monatomic solids. All compiled experimental angular distributions are presented in the polar diagram in Fig. 3, where angular distributions of sputtered atoms from multi-component solids are also included.

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Captions of tables

Table 1 Classification of papers concerning the angular distribution of sputtered atoms published from 1960 to 1988.

Table 2 List of publications concerning the angular distribution of sputtered atoms, where the references are numbered in a chronological order, and this numbering of references is used in the following tables and figures.

Table 3 List of publications of experimental works on the angular distribution of sputtered atoms from a monatomic solid.

Table 4 List of publications of experimental works on the angular distribution of sputtered atoms form a multi-component solid.

Table 5 List of theoretical and computational works on the angular distribution of sputtered atoms.

Table 6 List of review papers.

Table 7 Brief review of experimental works on the angular distribution of sputtered atoms. A crystal target is denoted by "CRYS" in the column of "STRUCTURE".

Table 8 The best-fit n values of an empirical fitting formula $\cos^n\theta$ for the angular distribution at normal incidence on a monatomic solid.

Table 9 The preferential ejection angle β of measured angular distributions at oblique incidence on a monatomic solid.

Table 1 Classification of papers concering the angular distribution of sputtered atoms published from 1960 to 1989

	EXPERIMENT						SIMULATION	THEORY	REVIEW
	Monatomic			Multi-component					
	Polycrystal Amorphous		Crystal	Polycrystal Amorphous		Crystal			
	Normal	Oblique		Normal	Oblique				
1950	1	0	0	0	0	0	0	0	0
1960	3	1	0	0	0	0	0	1	5
1970	5	7	9	2	2	1	2	7	7
1980	31	16	8	14	6	1	11	15	6
Sum	40	24	17	16	8	2	13	23	18

Table 2 List of publications concerning the angular distribution of sputtered atoms

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CATHODE SPUTTERING (1968)

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DEFECTS AND RADIATION DAMEGE IN METALS (1968)

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70 5 A.V.VEEN, J.M.FLUIT
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RADIAT. EFF. 31 (1977) 153-156

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Z. PHYS. B 28 (1977) 37-42

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J. APPL. PHYS. 48 JUNE (1977) 2274-2279

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PHYSICA STATUS SOLIDI (A) 47 (1978) K9-K10

78 4 P.HUCKS, G.STOCKLIN, E.VIETZKE, K.VOGELBRUCH
J. NUCL. MATER. 76&77 (1978) 136-142

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J. NUCL. MATER. 84 (1979) 101-108

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J. APPL. PHYS. 51(5) MAY (1980) 2884-2887

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JPN. J. APLL. PHYS. 25 (1986) 8-11

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86 16 E.TAGLAUER, J.ONSGAARD
APPL. PHYS. LETT. 48(9) (1986) 575-577

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86 18 S.KUNDU, D.GHOSE, D.BASU, S.B.KARMOHAPATRO
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IEEE. TRANS. NUCL. SCI. NS-26 FEBRUARY (1979) 1292-1295

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Table 7 Brief review of experimental works on the angular distributions of sputtered atoms

NO.		REFERENCE	ION	ENERGY(KEV)	ANGLE	TARGET	STRUCTURE
57	1	G.K.WEHNER	HG	0.03-0.4	0	CU, AG, AU, V, ZR, NB, SI, C, PT, AL, FE	
60	1	G.K.WEHNER	HG	0.1-1	0	NI, PT, GE, FE, MO	
61	2	H.PATTERSON	A	5, 8, 10	0, 20	AU	
69	2	B.M.GURMIN	KR	5, 10, 19	60	W	
70	2	V.E.DUBINSKI	AR	70		TA	CRYS
70	3	V.E.DUBINSKII	AR, N2	70		AU, TA, W	CRYS
70	4	O.I.KAPUSTA					
70	5	A.V.VEEN	KR	250	70	AG	CRYS
73	1	V.M.BUKHANOV	NE	22		CU(001)	CRYS
73	4	J.RICHARDS	AR	15	45	K-BR, NA-CL	CRYS
73	5	V.E.YURASOVA	IN, CU, NE	9, 5	0, 45	CU, IN-SB	CRYS
74	1	K.RODELSPERGER					

Table 7 (continued)

NO.		REFERENCE	ION	ENERGY(KEV)	ANGLE	TARGET	STRUCTURE
74	4	S.YA.LEBEDEV	AR, N	70		AU	CRYS
76	1	K.RODELSPERGER	AR	130, 300, 1000	0, 60	FE, CU, AU	
76	2	S.YA.LEBEDEV					CRYS
77	1	D.HILDEBRANDT	NE, AR, KR	5-15	0	CU, ZN, PB	
77	2	R.R.OLSON	HG, AR	1		NI-CU, FE-NI	
77	3	K.RODELSPERGER	AR	130, 300, 1000	0, 60	AU, PT, CU, FE, TA	
77	4	Y.CHOUAN	AR	1.8		TA	
78	2	P.ERLENWEIN					
78	4	P.HUCKS	AR, HE, H	15, 30	70	AU, CU	
78	5	B.EMMOTH	HE, AR	20, 40, 65	0	MO, AG	
79	1	J.N.SMITH.JR	H3	5-10	30, 45, 60, 75	CR	
79	2	J.ROTH	H, HE	1, 4	0-80	NI, W, TA-C	

Table 7 (continued)

NO.		REFERENCE	ION	ENERGY(KEV)	ANGLE	TARGET	STRUCTURE
79	3	R.R.OLSON	HG, AR	0.3		NI-FE, AG-AU, NI-CU	
79	6	J.N.SMITH.JR	H3	10	30, 45, 60, 75	CR	
79	7	R.YAMADA	NE	0.6, 1.5	45	MO	
79	8	D.HILDEBRANDT	NE, AR,KR	10	0, 40, 60	AL, NB, AG, PB	
80	1	T.OKUTANI	AR	3, 10	0, 60	SI	
80	3	J.L.WHITTON	AR	40		CU	CRYS
80	4	V.S.CHERNYSH	A, H	80, 400		CO	CRYS
80	7	H.L.BAY	H, HE	1, 4	0, 20, 40, 60, 70, 80	NI, W	
81	1	H.TSUGE	AR	0.5, 1.0	0	AU, PT, AL	
81	2	H.H.ANDERSEN	AR	20, 80		AG-AU, CU-PT	
81	3	J.BOHDANSKY	H, D	0.45, 1.0, 4.0, 0.4, 2.0, 8.0	0, 20, 40, 60, 80, 0, 30, 50, 70	NI, NB-B2	
81	5	S.YA.LEBEDEV		70	80, 90		CRYS

Table 7 (continued)

NO.	REFERENCE	ION	ENERGY(KEV)	ANGLE	TARGET	STRUCTURE
81 10	K.SAIKI	HE	0.3, 1, 6	0	MO	
81 12	M.MANNAMI	AR	50	0, 30, 52, 80	AU	
81 13	D.HILDEBRANDT	KR, NE, AR, XE	10, 20, 30	-40, 0, 45	AL, NB, AG	
82 1	H.H.ANDERSEN	AR	160	0	PT-CU	
82 2	J.BOHDANSKY	D, HE	50, 100	0, 25, 50, 75	MO	
82 3	R.G.ALLAS	CU, NI, AL	60, 90, 120		CU, NI, AL	
82 5	W.SZYMCZAK	NE, XE	0.2-30	0	AU	CRYS
82 7	W.O.HOFER	HE, H	0.5, 4	0	V	
82 8	T.MOTOHIRO					
82 11	V.ORLINOV	AR	40	0	AL, AL2O3	
83 1	M.F.DUMKE	AR	15	0	GA, I	
83 2	H.J.KANG	AR	3	0	AU-CU	

Table 7 (continued)

NO.	REFERENCE	ION	ENERGY(KEV)	ANGLE	TARGET	STRUCTURE
83 4	M.R.WELLER	AR	100	0	AU-AG	
83 5	J.ROTH	NI, MO, W	0.3-50		NB-B2, TI-B2, B4-C, TA-C, C	
83 7	H.H.ANDERSEN	BI, AR, O	1.25-320	0	CU-PT, CU, NI5-PD	
84 1	S.ICHIMURA	AR	3	0	CU-NI, CO-NI, FE-NI	
84 2	H.H.ANDERSEN	AR	20, 80		CU-PT	
84 3	P.R.MALMBERG	AU	125	0-60	CU	
84 4	J.LINDERS	AR	20, 40	80	AG	CRYS
84 5	R.BECERRA-ACEVEDO	D	4, 1.33	80	NI, MO	
85 2	G.BRAUER	AR, XE	100-900	0, 80, 85	CU, ZR, AU	
85 3	S.KUNDU	NE, AR, KR, XE	20-30	0-40(DEG)	AG	
85 4	H.H.ANDERSEN	AR,	1.25-320	0-90(DEG)	CU, PT, GE	
85 5	T.MOTIHIRO	AR	2.35, 5.0, 7.8	0 (DEG)	AU	

Table 7 (continued)

NO.	REFERENCE	ION	ENERGY(KEV)	ANGLE	TARGET	STRUCTURE
85 11	V.A.BURDOVITSIN	N, N2, AR	10	0-75	SI-N	
85 13	I.I.BONDAR			30 45		
86 1	H.J.KANG	AR	0.8	0, 60	AU-CU	
86 2	J.P.O'CONNOR	BR	70, 100		NB	
86 3	YASUHIRO NAGAI	AR	1	0-60	NI-FE	
86 6	Y.MATSUDA	AR	0.6, 1, 2, 3	0	FE	
86 7	M.SZYMONSKI	AR	5		AG	
86 8	F.LAMA	AR	5-20		U-O2	
86 9	M.ERDMANN	AR, O2	20, 22, 24, 40		AG, AU	CRYS
86 12	M.SAIDOH	HE, AR	2.5-6	70	MO	
86 14	J.P.BAXTER	AR	5	0	RH	AMOR, CRYS
86 15	J.P.BAXTER	AR	5	0	IN, RH	

Table 7 (continued)

NO.	REFERENCE	ION	ENERGY(KEV)	ANGLE	TARGET	STRUCTURE
86 16	E.TAGLAUER	AR	2	0	CU	
86 17	W.HUANG	AR N2	5	0	AG	
86 18	S.KUNDU	AR	20	0 40	AG	
87 2	C.SCHWEBEL	XE, AR, KR	10-20	15, 45	SI	
87 3	M.SAIDOH	HE	6	70	MO	
87 5	H.SHIMIZU					
87 6	J.A.SPRAGUE	CU	100	0	CU	CRYS
87 11	W.O.HOFER	AR	5	0	CU(111)	CRYS
87 12	Y.MATSUDA	AR	1, 2, 3	0	TI, FE	
88 1	W.HUANG	N	5	0	AG, AR	
88 2	A.I.DODONOV	AR	30	96, 94, 92,88, 85, 75,70, 65, 60,50, 40, 0	CU	

Table 8 The best-fit n values of an empirical fitting formula $\cos^n\theta$

ENERGY(KEV)	ION	TARGET	N-VALUE	REF.	NO.
0.30	HG	NI	0.45	60. 1.	1
0.30	HG	NI	0.48	60. 1.	2
0.10	HG	PT	0.29	60. 1.	3
0.25	HG	PT	0.55	60. 1.	4
0.50	HG	PT	0.54	60. 1.	5
0.75	HG	PT	0.58	60. 1.	6
1.00	HG	PT	0.62	60. 1.	7
0.10	HG	NI	0.02	60. 1.	8
0.25	HG	NI	0.71	60. 1.	9
0.50	HG	NI	0.66	60. 1.	10
0.75	HG	NI	0.85	60. 1.	11
1.00	HG	NI	1.09	60. 1.	12
0.15	HG	GE	0.11	60. 1.	13
0.25	HG	GE	0.43	60. 1.	14
0.50	HG	GE	0.69	60. 1.	15
0.75	HG	GE	0.91	60. 1.	16
1.00	HG	GE	1.06	60. 1.	17
0.15	HG	MO	0.01	60. 1.	18
0.25	HG	MO	0.47	60. 1.	19
0.50	HG	MO	0.29	60. 1.	20
0.75	HG	MO	0.55	60. 1.	21
1.00	HG	MO	0.64	60. 1.	22
0.15	HG	FE	0.03	60. 1.	23
0.25	HG	FE	0.22	60. 1.	24
0.50	HG	FE	0.48	60. 1.	25
0.75	HG	FE	0.54	60. 1.	26
1.00	HG	FE	0.89	60. 1.	27
300.00	AR	AU	1.49	76. 1.	4
300.00	AR	AU	1.17	76. 1.	5
5.00	KR	CU	0.33	77. 1.	1
8.00	KR	CU	0.44	77. 1.	2
14.00	KR	CU	0.46	77. 1.	3
300.00	AR	PT	2.28	77. 3.	2
130.00	AR	AU	1.85	77. 3.	4
130.00	AR	AU	1.44	77. 3.	5
1000.00	AR	AU	2.28	77. 3.	8

Table 8 (continued)

ENERGY(KEV)	ION	TARGET	N-VALUE	REF.	NO.
130.00	AR	CU	1.71	77. 3.	10
300.00	AR	CU	1.82	77. 3.	12
300.00	AR	TA	0.99	77. 3.	16
65.00	HE	MO	0.88	78. 5.	1
40.00	HE	AG	1.22	78. 5.	2
40.00	AR	MO	1.08	78. 5.	3
20.00	AR	AG	2.56	78. 5.	4
1.00	H3	NI	2.09	79. 2.	6
4.00	H2	NI	1.63	79. 2.	12
4.00	HE	NI	0.72	79. 2.	16
4.00	H2	W	0.73	79. 2.	19
3.00	AR	SI	1.54	80. 1.	1
10.00	AR	SI	0.87	80. 1.	2
1.00	AR	AU	1.36	81. 1.	1
1.00	AR	AL	0.60	81. 1.	2
1.00	AR	AL	0.44	81. 1.	4
1.00	AR	AU	1.08	81. 1.	5
1.00	AR	PT	0.79	81. 1.	6
1.00	AR	PT	0.76	81. 1.	7
1.00	AR	TA	0.81	81. 1.	8
1.00	AR	SI	0.72	81. 1.	9
0.50	AR	AU	1.19	81. 1.	10
0.50	AR	SI	0.58	81. 1.	14
0.45	H	NI	1.15	81. 3.	1
0.45	H	NI	0.75	81. 3.	5
1.00	H	NI	0.81	81. 3.	6
4.00	H	NI	1.54	81. 3.	7
50.00	AR	AU	2.27	81.12.	1
100.00	D	MO	1.29	82. 2.	4
100.00	HE	MO	1.11	82. 2.	8
50.00	HE	MO	1.11	82. 2.	12
60.00	CU	CU	1.26	82. 3.	1
90.00	CU	CU	1.35	82. 3.	2
120.00	CU	CU	1.33	82. 3.	3
60.00	NI	NI	1.05	82. 3.	4
90.00	NI	NI	0.90	82. 3.	5
120.00	NI	NI	0.75	82. 3.	6

Table 8 (continued)

ENERGY(KEV)	ION	TARGET	N-VALUE	REF.	NO.
90.00	CU	CU	1.30	82. 3.	7
90.00	CU	CU	1.00	82. 3.	8
90.00	CU	CU	0.77	82. 3.	9
90.00	CU	CU	1.35	82. 3.	10
90.00	CU	CU	0.82	82. 3.	11
90.00	CU	CU	1.07	82. 3.	12
4.00	HE	V	1.19	82. 7.	1
4.00	HE	V	0.93	82. 7.	2
0.50	H	V	1.17	82. 7.	3
40.00	AR	AL	0.96	82.11.	1
40.00	AR	AL	0.86	82.11.	2
125.00	AU	CU	1.99	84. 3.	1
125.00	AU	CU	2.35	84. 3.	2
125.00	AU	CU	2.01	84. 3.	6
125.00	AU	CU	2.14	84. 3.	7
500.00	AR	AU	2.02	85. 2.	1
500.00	AR	CU	1.99	85. 2.	6
500.00	AR	ZR	1.33	85. 2.	12
30.00	NE	AG	0.98	85. 3.	1
20.00	AR	AG	0.84	85. 3.	2
20.00	KR	AG	1.15	85. 3.	3
30.00	XE	AG	1.31	85. 3.	4
80.00	AR	GE	1.17	85. 4.	1
80.00	AR	CU	1.82	85. 4.	2
80.00	AR	PT	1.96	85. 4.	3
2.30	AR	AU	0.54	85. 5.	1
5.00	AR	AU	0.30	85. 5.	2
7.80	AR	AU	1.04	85. 5.	3
100.00	BR	NB	1.36	86. 2.	2
1.00	AR	FE	1.12	86. 6.	1
3.00	AR	FE	1.45	86. 6.	2
2.00	AR	FE	1.31	86. 6.	3
0.60	AR	FE	0.93	86. 6.	4
5.00	AR	AG	1.18	86. 7.	1
5.00	AR	AG	0.20	86. 7.	2
5.00	AR	AG	1.74	86. 7.	3
5.00	AR	RH	1.11	86.14.	1

Table 8 (continued)

ENERGY(KEV)	ION	TARGET	N-VALUE	REF.	NO.
5.00	AR	RH	2.03	86.14.	2
5.00	AR	IN	1.31	86.15.	1
5.00	AR	RH	1.81	86.15.	2
5.00	AR	IN	1.06	86.15.	3
5.00	AR	IN	1.31	86.15.	4
5.00	AR	IN	1.49	86.15.	5
5.00	AR	RH	1.22	86.15.	6
5.00	AR	RH	1.56	86.15.	7
5.00	AR	RH	2.11	86.15.	8
2.00	AR	CU	0.72	86.16.	1
2.00	AR	CU	0.88	86.16.	2
2.00	AR	CU	1.12	86.16.	3
2.00	AR	CU	1.17	86.16.	4
5.00	AR	AG	1.23	86.17.	1
5.00	AR	AG	1.77	86.17.	2
5.00	N2	AG	1.11	86.17.	3
5.00	N2	AG	1.38	86.17.	4
20.00	AR	AG	0.85	86.18.	1
5.00	N	AG	0.88	88. 1.	1
5.00	N	AR	1.13	88. 1.	2
30.00	AR	CU	3.26	88. 2.	12

Table 9 The preferential ejection angle β of measured distributions at oblique incidence on a monatomic solid.

ENERGY(KEV)	ION	TARGET	θ	β	REF.	NO.
5.00	KR	V	60.0	53.8	69. 2.	1
10.00	KR	V	60.0	50.0	69. 2.	2
19.00	KR	V	60.0	23.0	69. 2.	3
130.00	AR	CU	60.0	0.0	76. 1.	1
300.00	AR	CU	60.0	30.0	76. 1.	2
300.00	AR	CU	60.0	0.0	76. 1.	3
130.00	AR	AU	60.0	0.0	76. 1.	6
130.00	AR	PT	60.0	0.0	76. 1.	7
130.00	AR	CU	60.0	5.0	76. 1.	8
130.00	AR	FE	60.0	5.0	76. 1.	9
130.00	AR	TA	60.0	5.0	76. 1.	10
1000.00	AR	AU	60.0	5.0	76. 1.	11
1000.00	AR	PT	60.0	5.0	76. 1.	12
1000.00	AR	CU	60.0	0.0	76. 1.	13
1000.00	AR	FE	60.0	20.0	76. 1.	14
1000.00	AR	TA	60.0	0.0	76. 1.	15
130.00	AR	PT	60.0	10.0	77. 3.	1
300.00	AR	PT	60.0	10.0	77. 3.	3
130.00	AR	AU	60.0	0.0	77. 3.	6
130.00	AR	AU	60.0	0.0	77. 3.	7
1000.00	AR	AU	60.0	0.0	77. 3.	9
130.00	AR	CU	60.0	0.0	77. 3.	11
300.00	AR	CU	60.0	0.0	77. 3.	13
1000.00	AR	CU	60.0	0.0	77. 3.	14
130.00	AR	TA	60.0	29.0	77. 3.	15
1000.00	AR	TA	60.0	0.0	77. 3.	17
130.00	AR	FE	60.0	20.0	77. 3.	18
130.00	AR	FE	60.0	0.0	77. 3.	19
130.00	AR	FE	60.0	0.0	77. 3.	20
1000.00	AR	FE	60.0	20.0	77. 3.	21
1.00	H3	NI	80.0	45.0	79. 2.	1
1.00	H3	NI	70.0	43.0	79. 2.	2
1.00	H3	CR	60.0	49.0	79. 2.	3
1.00	H3	NI	40.0	50.0	79. 2.	4
1.00	H3	NI	20.0	50.0	79. 2.	5
4.00	H2	NI	80.0	21.0	79. 2.	7

Table 9 (continued)

2 ENERGY(KEV)	ION	TARGET	θ	β	REF.	NO.
4.00	H2	NI	70.0	33.7	79. 2.	8
4.00	H2	NI	60.0	42.0	79. 2.	9
4.00	H2	NI	40.0	50.0	79. 2.	10
4.00	H2	NI	20.0	50.0	79. 2.	11
4.00	HE	NI	80.0	15.0	79. 2.	13
1.30	H3	NI	60.0	50.0	79. 2.	14
4.00	HE	NI	40.0	55.0	79. 2.	15
4.00	H2	W	80.0	45.0	79. 2.	17
4.00	H2	W	60.0	45.0	79. 2.	18
3.00	AR	SI	60.0	20.0	80. 1.	3
10.00	AR	SI	60.0	15.0	80. 1.	4
0.45	H	NI	40.0	45.9	81. 3.	2
0.45	H	NI	60.0	45.0	81. 3.	3
0.45	H	NI	80.0	49.3	81. 3.	4
100.00	D	MO	75.0	20.0	82. 2.	1
100.00	D	MO	50.0	50.0	82. 2.	2
100.00	D	MO	25.0	50.0	82. 2.	3
50.00	D	MO	75.0	25.0	82. 2.	5
50.00	D	MO	50.0	45.0	82. 2.	6
50.00	D	MO	25.0	45.0	82. 2.	7
100.00	HE	MO	25.0	60.0	82. 2.	9
100.00	HE	MO	50.0	50.0	82. 2.	10
100.00	HE	MO	75.0	5.0	82. 2.	11
50.00	HE	MO	75.0	0.0	82. 2.	13
50.00	HE	MO	50.0	40.0	82. 2.	14
50.00	HE	MO	25.0	40.0	82. 2.	15
2.00	D	MO	80.0	25.0	83. 5.	1
125.00	AU	CU	30.0	0.0	84. 3.	3
125.00	AU	CU	45.0	0.0	84. 3.	4
125.00	AU	CU	60.0	30.0	84. 3.	5
125.00	AU	CU	30.0	0.0	84. 3.	8
125.00	AU	CU	45.0	0.0	84. 3.	9
125.00	AU	CU	60.0	0.0	84. 3.	10
500.00	AR	AU	85.0	10.0	85. 2.	2
150.00	AR	AU	85.0	5.0	85. 2.	3
900.00	AR	AU	85.0	5.0	85. 2.	4
200.00	XE	AU	85.0	5.0	85. 2.	5

Table 9 (continued)

ENERGY(KEV)	ION	TARGET	θ	β	REF.	NO.
500.00	AR	CU	80.0	10.0	85. 2.	7
500.00	AR	CU	85.0	5.0	85. 2.	8
150.00	AR	CU	85.0	5.0	85. 2.	9
900.00	AR	CU	85.0	5.0	85. 2.	10
200.00	XE	CU	85.0	5.0	85. 2.	11
500.00	AR	ZR	80.0	11.0	85. 2.	13
500.00	AR	ZR	85.0	9.0	85. 2.	14
150.00	AR	ZR	85.0	9.0	85. 2.	15
900.00	AR	ZR	85.0	8.0	85. 2.	16
200.00	XE	ZR	85.0	5.0	85. 2.	17
6.00	HE	MO	70.0	35.0	86.12.	1
6.00	HE	MO	70.0	30.0	86.12.	2
6.00	HE	MO	70.0	30.0	86.12.	3
20.00	XE	SI	15.0	13.9	87. 2.	1
20.00	XE	SI	45.0	52.2	87. 2.	2
20.00	XE	SI	45.0	0.0	87. 2.	3
20.00	AR	SI	45.0	0.0	87. 2.	4
20.00	AR	SI	45.0	52.2	87. 2.	5
20.00	KR	SI	45.0	10.0	87. 2.	6
20.00	KR	SI	45.0	45.9	87. 2.	7
20.00	XE	SI	45.0	0.0	87. 2.	8
20.00	XE	SI	45.0	52.2	87. 2.	9
6.00	HE	MO	70.0	29.2	87. 3.	1
6.00	HE	MO	70.0	25.0	87. 3.	2
30.00	AR	CU	86.0	10.0	88. 2.	1
30.00	AR	CU	84.0	15.0	88. 2.	2
30.00	AR	CU	82.0	15.0	88. 2.	3
30.00	AR	CU	78.0	20.0	88. 2.	4
30.00	AR	CU	75.0	25.7	88. 2.	5
30.00	AR	CU	65.0	30.0	88. 2.	6
30.00	AR	CU	60.0	29.7	88. 2.	7
30.00	AR	CU	55.0	30.5	88. 2.	8
30.00	AR	CU	50.0	0.0	88. 2.	9
30.00	AR	CU	40.0	0.0	88. 2.	10
30.00	AR	CU	30.0	0.0	88. 2.	11

Fig. 1

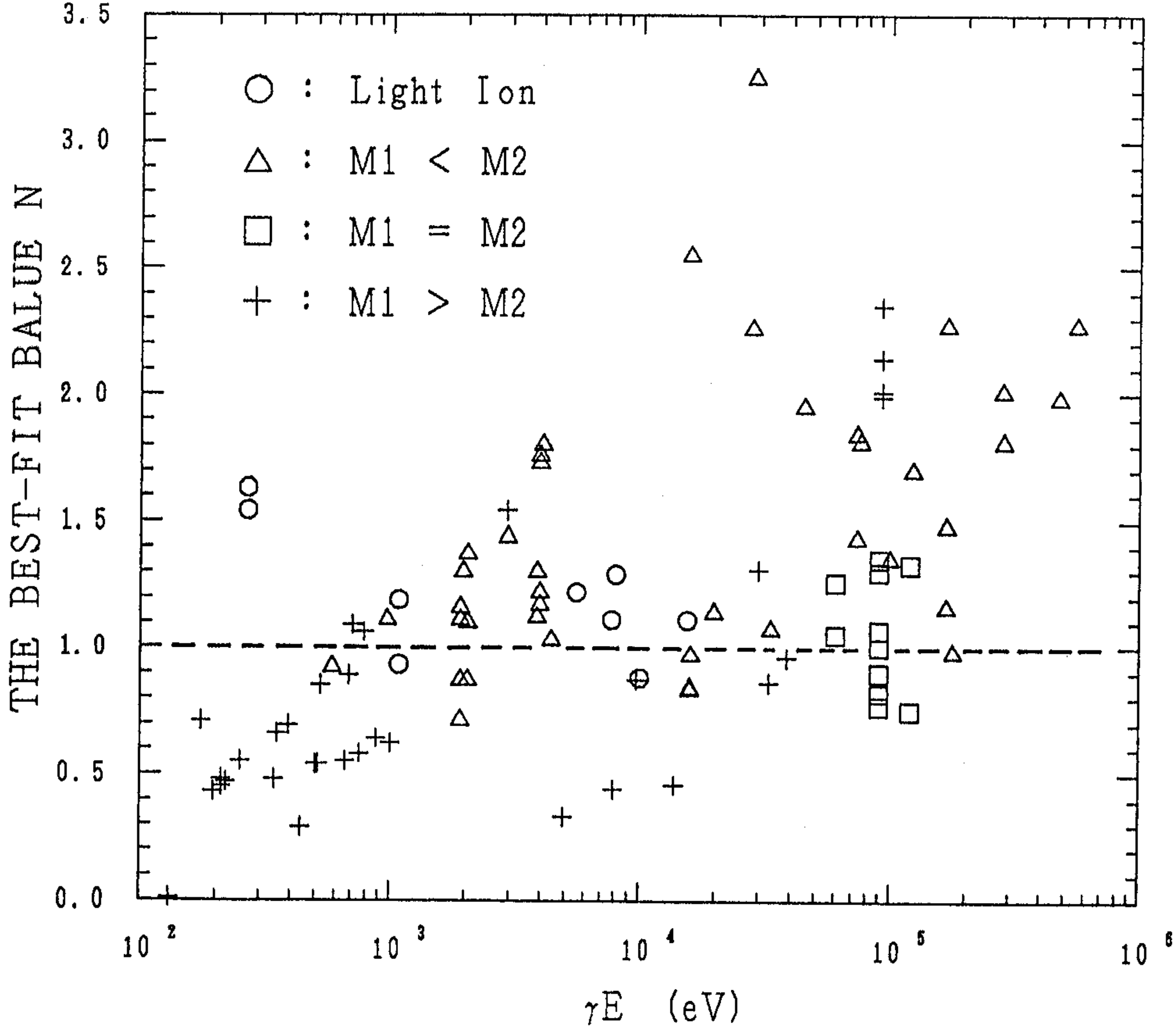

○ : Light Ion
△ : M1 < M2
□ : M1 = M2
+ : M1 > M2
THE BEST-FIT BALUE N
3.5
3.0
2.5
2.0
1.5
1.0
0.5
0.0
10 2
10 3
10 4
10 5
10 6
γE (eV)

Fig. 1

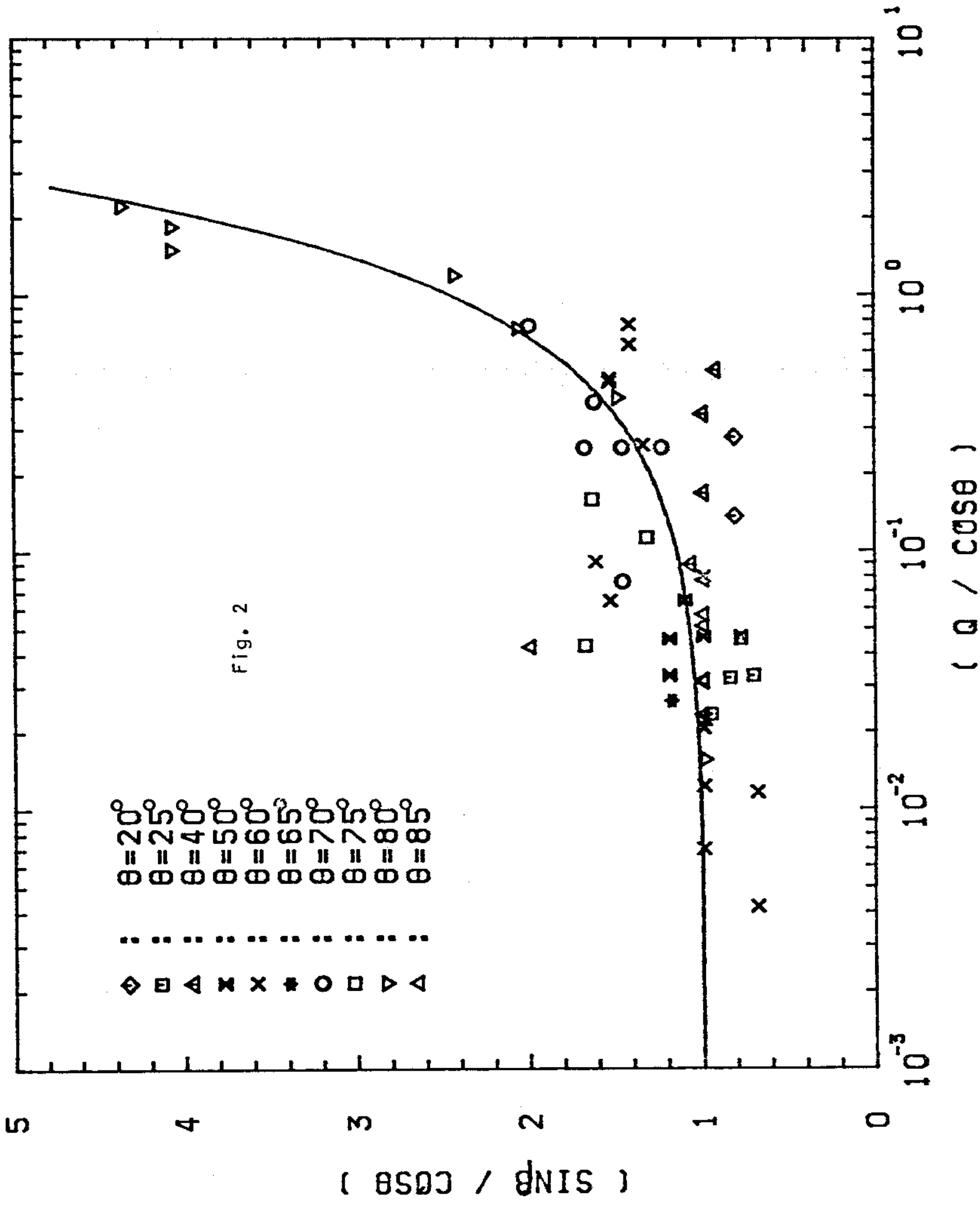


Fig. 2
θ=20°
θ=25°
θ=40°
θ=50°
θ=60°
θ=65°
θ=70°
θ=75°
θ=80°
θ=85°
(SINθ / COSθ)
(Q / COSθ)
0
1
2
3
4
5
10^{-3}
10^{-2}
10^{-1}
10^{0}
10^{1}

Captions of figures

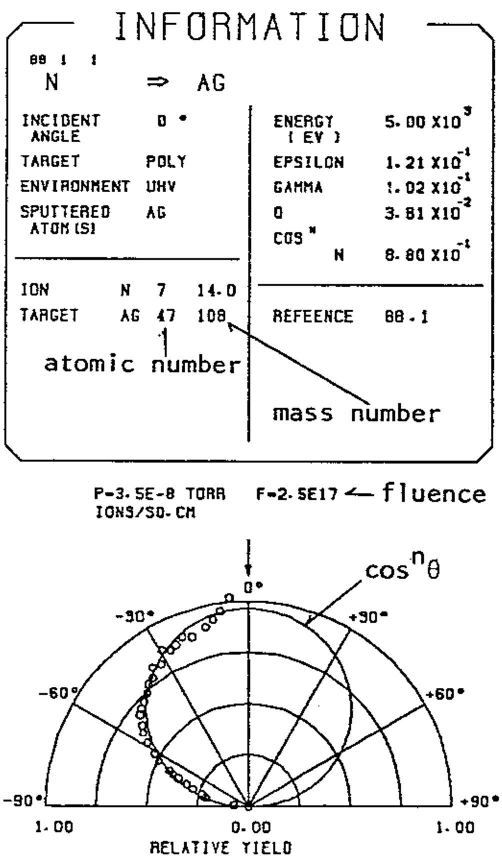
Fig. 1 The best-fit n values of the fitting formula $\cos^n\theta$ of angular distributions of sputtered atoms from monatomic solids are plotted as a function of γE for various ion-target combination.

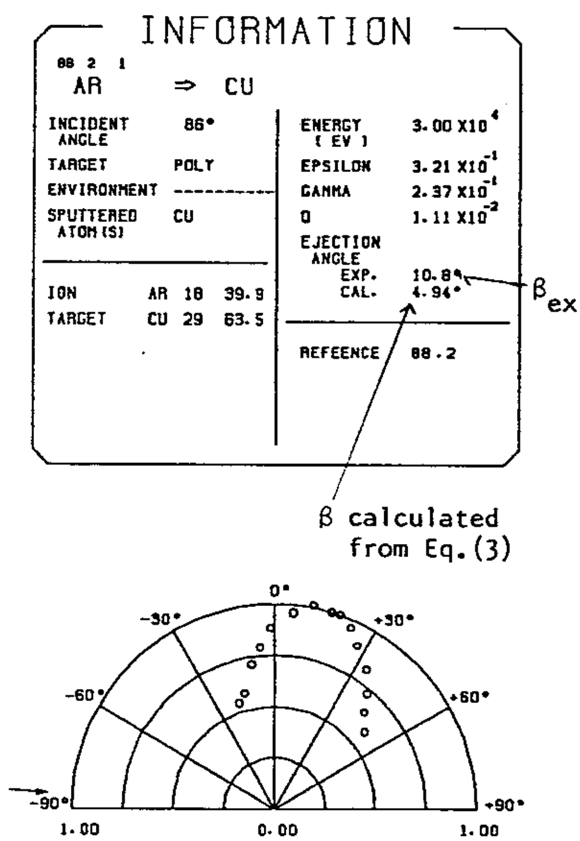
Fig. 2 The scaling rule for the preferential ejection angle β, where the ratio $\sin\beta_{ex}/\cos\theta$ are plotted against X. The solid line is

$$\frac{\sin\beta}{\cos\theta} = \{(1+X)(1+2X)\}^{1/2} ,$$

where $X = [U_s/\gamma E]^{1/2}/\cos\theta$.

Fig. 3 Plots of all experimental angular distributions reported from 1960 to 1988. The notations used in the figures are indicated below:





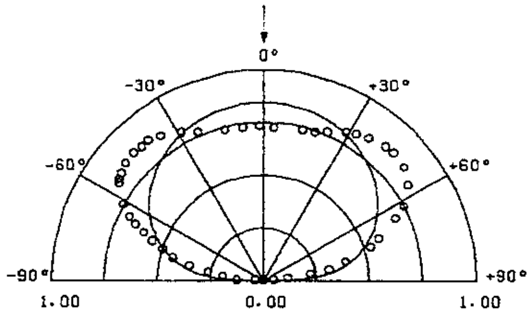
INFORMATION

60 1 1

HG ⇒ NI

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{2}
TARGET	POLY	EPSILON	2.11×10^{-4}
ENVIRONMENT	----------	GAMMA	7.01×10^{-1}
SPUTTERED ATOM (S)	NI	Q	1.45×10^{-1}
		$\cos^N$ N	4.50×10^{-1}
ION	HG 80 201	REFERENCE	60 . 1
TARGET	NI 28 58.7		

TRANSVERSE DIRECTION



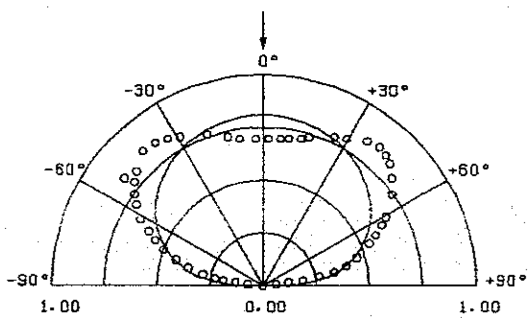
INFORMATION

60 1 2

HG ⇒ NI

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{2}
TARGET	POLY	EPSILON	2.11×10^{-4}
ENVIRONMENT	----------	GAMMA	7.01×10^{-1}
SPUTTERED ATOM (S)	NI	Q	1.45×10^{-1}
		$\cos^N$ N	4.80×10^{-1}
ION	HG 80 201	REFERENCE	60 . 1
TARGET	NI 28 58.7		

ROLLING DIRECTION



2

INFORMATION

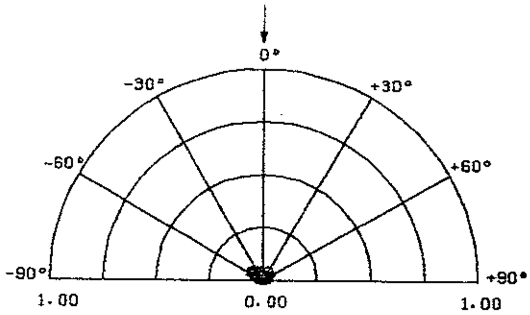
60 1 3

HG ⇒ PT

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{2}
TARGET	POLY	EPSILON	4.78×10^{-5}
ENVIRONMENT	----------	GAMMA	10.00×10^{-1}
SPUTTERED ATOM (S)	PT	Q	2.42×10^{-1}
		COS^{N} N	2.90×10^{-1}

ION	HG	80	201
TARGET	PT	78	195

REFERENCE 60.1



INFORMATION

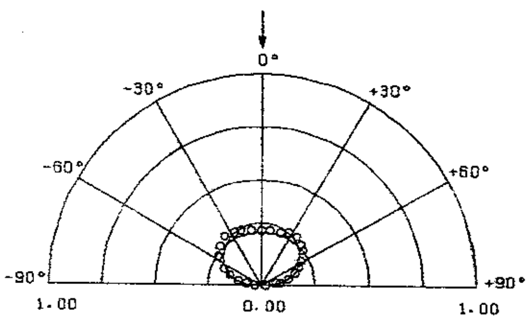
60 1 4

HG ⇒ PT

INCIDENT ANGLE	0 °	ENERGY (EV)	2.50×10^{2}
TARGET	POLY	EPSILON	1.20×10^{-4}
ENVIRONMENT	----------	GAMMA	10.00×10^{-1}
SPUTTERED ATOM (S)	PT	Q	1.53×10^{-1}
		COS^{N} N	5.50×10^{-1}

ION	HG	80	201
TARGET	PT	78	195

REFERENCE 60.1

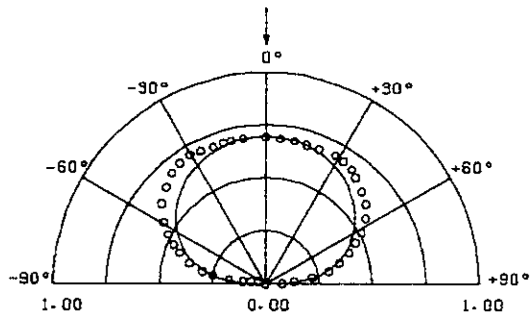


INFORMATION

60 1 5

HG ⇒ PT

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{2}
TARGET	POLY	EPSILON	2.39×10^{-4}
ENVIRONMENT	----------	GAMMA	10.00×10^{-1}
SPUTTERED ATOM (S)	PT	Q	1.09×10^{-1}
		COS^{N} N	5.40×10^{-1}
ION	HG 80 201		
TARGET	PT 78 195	REFERENCE	60 - 1

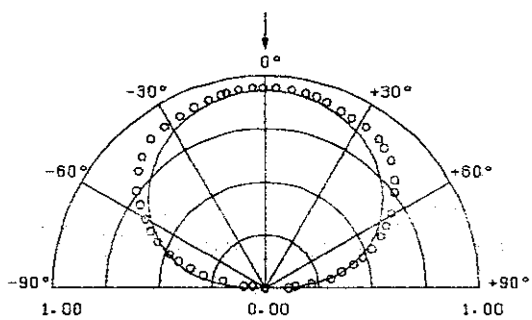


INFORMATION

60 1 6

HG ⇒ PT

INCIDENT ANGLE	0 °	ENERGY (EV)	7.50×10^{2}
TARGET	POLY	EPSILON	3.59×10^{-4}
ENVIRONMENT	----------	GAMMA	10.00×10^{-1}
SPUTTERED ATOM (S)	PT	Q	8.83×10^{-2}
		COS^{N} N	5.80×10^{-1}
ION	HG 80 201		
TARGET	PT 78 195	REFERENCE	60 - 1



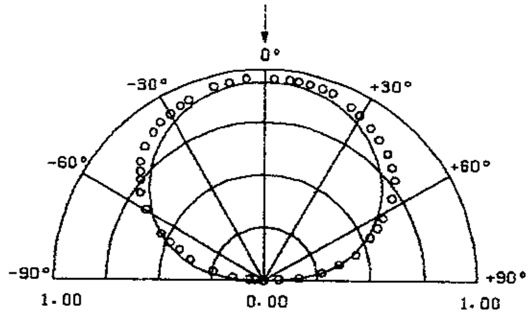
4

INFORMATION

60 1 7

HG ⇒ PT

INCIDENT ANGLE	0 °		ENERGY (EV)	1.00×10^{3}
TARGET	POLY		EPSILON	4.78×10^{-4}
ENVIRONMENT	----------		GAMMA	10.00×10^{-1}
SPUTTERED ATOM(S)	PT		Q	7.64×10^{-2}
			COS * N	6.20×10^{-1}
ION	HG 80	201		
TARGET	PT 78	195	REFERENCE	60.1

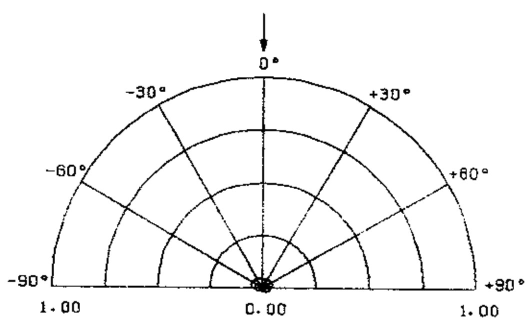


INFORMATION

60 1 8

HG ⇒ NI

INCIDENT ANGLE	0 °		ENERGY (EV)	1.00×10^{2}
TARGET	POLY		EPSILON	7.04×10^{-5}
ENVIRONMENT	----------		GAMMA	7.01×10^{-1}
SPUTTERED ATOM(S)	NI		Q	2.52×10^{-1}
			COS * N	2.00×10^{-2}
ION	HG 80	201		
TARGET	NI 28	58.7	REFERENCE	60.1



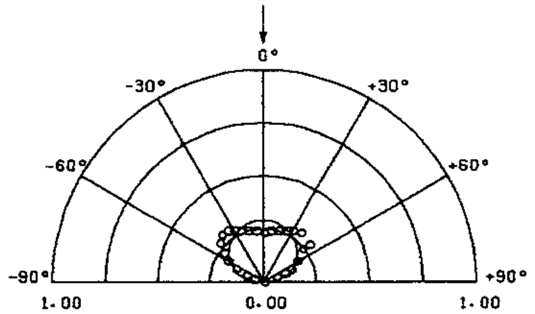
INFORMATION

60 1 8

HG ⇒ NI

INCIDENT ANGLE	0 °	ENERGY (EV)	2.50×10^{2}
TARGET	POLY	EPSILON	1.76×10^{-4}
ENVIRONMENT	----------	GAMMA	7.01×10^{-1}
SPUTTERED ATOM (S)	NI	Q	1.59×10^{-1}
		$\cos^{N}$ N	7.10×10^{-1}

ION	HG	80	201	REFERENCE	60.1
TARGET	NI	28	58.7		



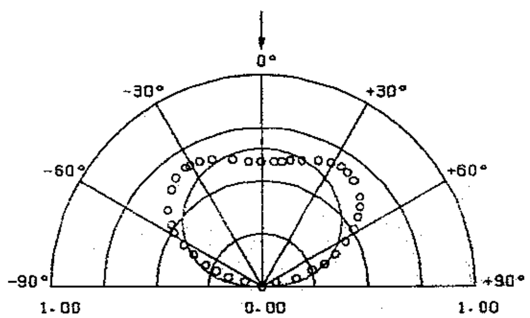
INFORMATION

60 1 10

HG ⇒ NI

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{2}
TARGET	POLY	EPSILON	3.52×10^{-4}
ENVIRONMENT	----------	GAMMA	7.01×10^{-1}
SPUTTERED ATOM (S)	NI	Q	1.13×10^{-1}
		$\cos^{N}$ N	6.60×10^{-1}

ION	HG	80	201	REFERENCE	60.1
TARGET	NI	28	58.7		



6

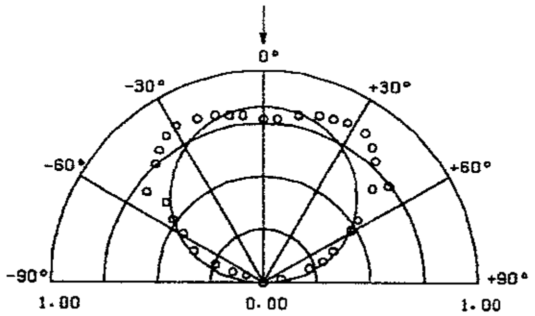
INFORMATION

60 1 11

HG ⇒ NI

INCIDENT ANGLE	0 °	ENERGY (EV)	7.50×10^{2}
TARGET	POLY	EPSILON	5.28×10^{-4}
ENVIRONMENT	----------	GAMMA	7.01×10^{-1}
SPUTTERED ATOM (S)	NI	Q	9.19×10^{-2}
		COS N	8.50×10^{-1}

ION	HG	80	201	REFERENCE	60 . 1
TARGET	NI	28	58. 7		



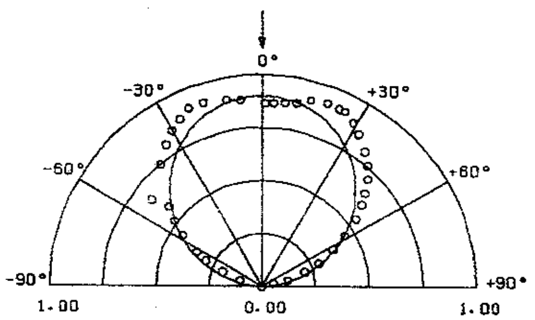
INFORMATION

60 1 12

HG ⇒ NI

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	7.04×10^{-4}
ENVIRONMENT	----------	GAMMA	7.01×10^{-1}
SPUTTERED ATOM (S)	NI	Q	7.96×10^{-2}
		COS N	1.09

ION	HG	80	201	REFERENCE	60 . 1
TARGET	NI	28	58. 7		



INFORMATION

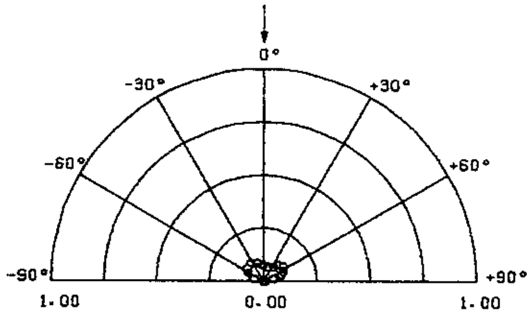
60 1 13

HG ⇒ GE

INCIDENT ANGLE	0 °		ENERGY (EV)	1.50×10^{2}
TARGET	POLY		EPSILON	1.07×10^{-4}
ENVIRONMENT	----------		GAMMA	7.80×10^{-1}
SPUTTERED ATOM (S)	GE		Q	1.81×10^{-1}
			COS^{N} N	1.10×10^{-1}

ION	HG	80	201
TARGET	GE	32	72.5

REFERENCE 60.1



INFORMATION

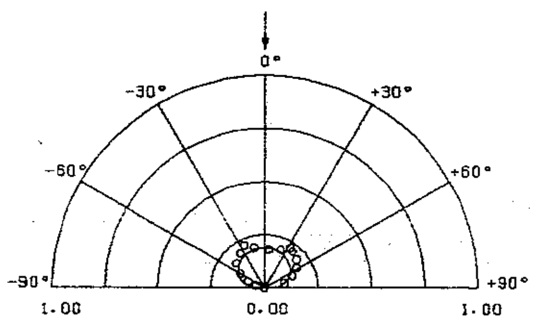
60 1 14

HG ⇒ GE

INCIDENT ANGLE	0 °		ENERGY (EV)	2.50×10^{2}
TARGET	POLY		EPSILON	1.78×10^{-4}
ENVIRONMENT	----------		GAMMA	7.80×10^{-1}
SPUTTERED ATOM (S)	GE		Q	1.40×10^{-1}
			COS^{N} N	4.30×10^{-1}

ION	HG	80	201
TARGET	GE	32	72.5

REFERENCE 60.1



8

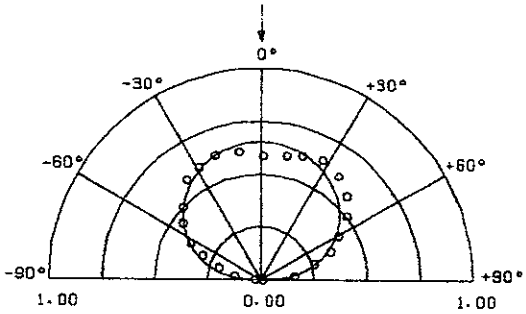
INFORMATION

60 1 15

HG ⇒ GE

INCIDENT ANGLE	0°	ENERGY (EV)	5.00×10^{2}
TARGET	POLY	EPSILON	3.56×10^{-4}
ENVIRONMENT	----------	GAMMA	7.80×10^{-1}
SPUTTERED ATOM(S)	GE	Q	9.93×10^{-2}
		COS^{n} N	6.90×10^{-1}

ION	HG	80	201	REFERENCE	60.1
TARGET	GE	32	72.5		



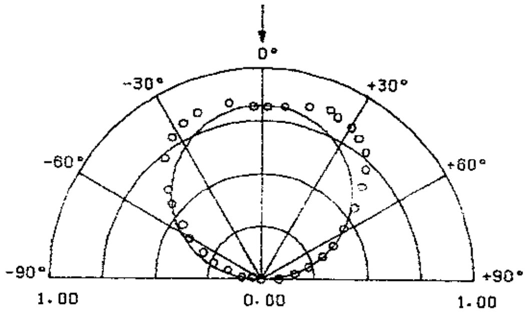
INFORMATION

60 1 18

HG ⇒ GE

INCIDENT ANGLE	0°	ENERGY (EV)	7.50×10^{2}
TARGET	POLY	EPSILON	5.34×10^{-4}
ENVIRONMENT	----------	GAMMA	7.80×10^{-1}
SPUTTERED ATOM(S)	GE	Q	8.11×10^{-2}
		COS^{n} N	9.10×10^{-1}

ION	HG	80	201	REFERENCE	60.1
TARGET	GE	32	72.5		



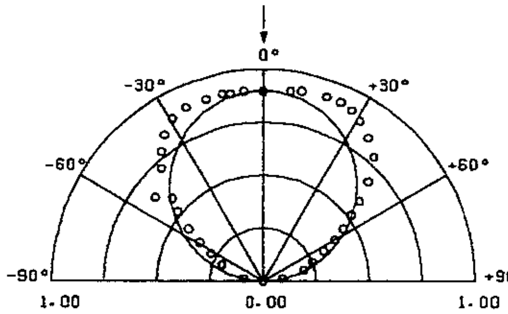
9

INFORMATION

60 1 17

HG ⇒ GE

INCIDENT ANGLE	0 °		ENERGY (EV)	1.00×10^{3}
TARGET	POLY		EPSILON	7.12×10^{-4}
ENVIRONMENT	----------		GAMMA	7.80×10^{-1}
SPUTTERED ATOM (S)	GE		Q	7.02×10^{-2}
			COS^{N} N	1.06
ION	HG 80 201			
TARGET	GE 32 72.5		REFERENCE	60.1

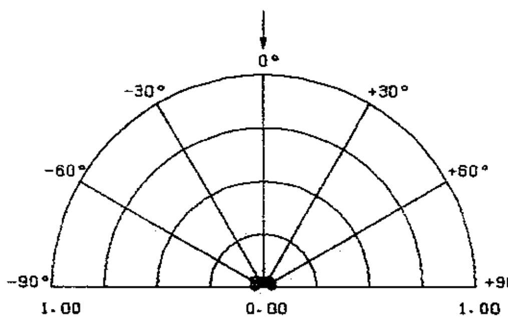


INFORMATION

60 1 18

HG ⇒ MO

INCIDENT ANGLE	0 °		ENERGY (EV)	1.50×10^{2}
TARGET	POLY		EPSILON	9.59×10^{-5}
ENVIRONMENT	----------		GAMMA	8.76×10^{-1}
SPUTTERED ATOM (S)	MO		Q	2.28×10^{-1}
			COS^{N} N	10.0×10^{-3}
ION	HG 80 201			
TARGET	MO 42 95.9		REFERENCE	60.1



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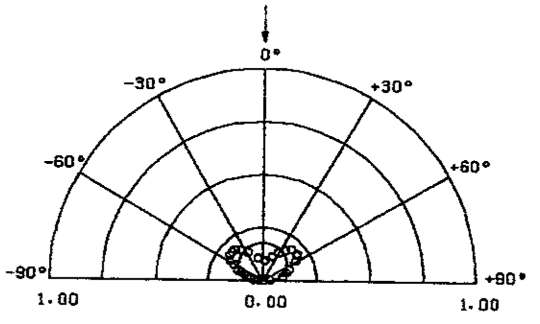
INFORMATION

60 1 10

HG ⇒ MO

INCIDENT ANGLE	0 °	ENERGY (EV)	2.50×10^{2}
TARGET	POLY	EPSILON	1.60×10^{-4}
ENVIRONMENT	----------	GAMMA	8.76×10^{-1}
SPUTTERED ATOM (S)	MO	Q	1.77×10^{-1}
		COS * N	4.70×10^{-1}

ION	HG	80	201	REFERENCE	60 . 1
TARGET	MO	42	95. 9		



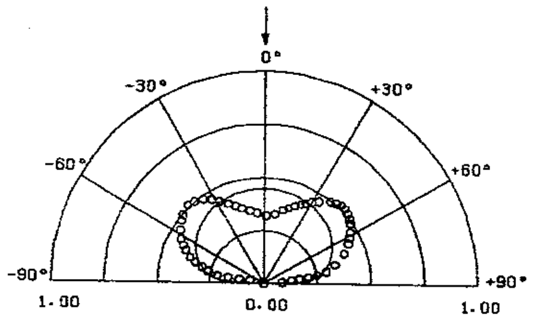
INFORMATION

60 1 20

HG ⇒ MO

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{2}
TARGET	POLY	EPSILON	3.20×10^{-4}
ENVIRONMENT	----------	GAMMA	8.76×10^{-1}
SPUTTERED ATOM (S)	MO	Q	1.25×10^{-1}
		COS * N	2.90×10^{-1}

ION	HG	80	201	REFERENCE	60 . 1
TARGET	MO	42	95. 9		



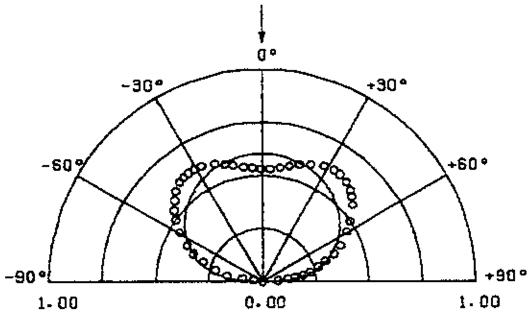
INFORMATION

60 1 21

HG ⇒ MO

INCIDENT ANGLE	0 °	ENERGY (EV)	7.50×10^{2}
TARGET	POLY	EPSILON	4.79×10^{-4}
ENVIRONMENT	----------	GAMMA	8.76×10^{-1}
SPUTTERED ATOM (S)	MO	Q	1.02×10^{-1}
		$\cos^{N}$ N	5.50×10^{-1}

ION	HG	80	201	REFERENCE	60 . 1
TARGET	MO	42	95.9		



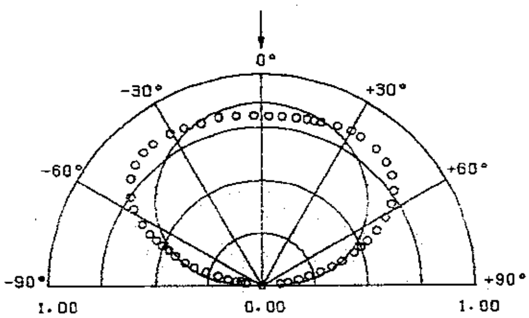
INFORMATION

60 1 22

HG ⇒ MO

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	6.39×10^{-4}
ENVIRONMENT	----------	GAMMA	8.76×10^{-1}
SPUTTERED ATOM (S)	MO	Q	9.83×10^{-2}
		$\cos^{N}$ N	6.40×10^{-1}

ION	HG	80	201	REFERENCE	60 . 1
TARGET	MO	42	95.9		



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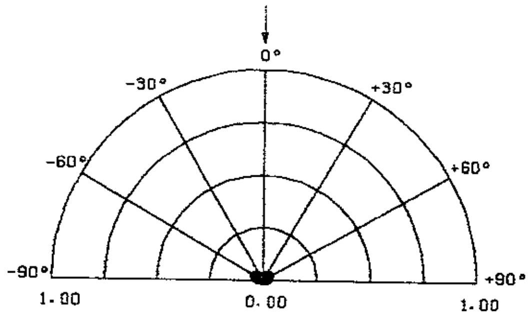
INFORMATION

60 1 29

HG ⇒ FE

INCIDENT ANGLE	0 °	ENERGY (EV)	1.50×10^{2}
TARGET	POLY	EPSILON	1.10×10^{-4}
ENVIRONMENT	----------	GAMMA	6.82×10^{-1}
SPUTTERED ATOM (S)	FE	Q	2.05×10^{-1}
		COS * N	3.00×10^{-2}

ION	HG	80	201	REFERENCE	60 . 1
TARGET	FE	26	55.8		



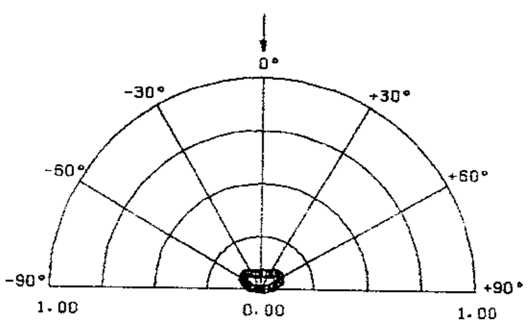
INFORMATION

60 1 24

HG ⇒ FE

INCIDENT ANGLE	0 °	ENERGY (EV)	2.50×10^{2}
TARGET	POLY	EPSILON	1.84×10^{-4}
ENVIRONMENT	----------	GAMMA	6.82×10^{-1}
SPUTTERED ATOM (S)	FE	Q	1.58×10^{-1}
		COS * N	2.20×10^{-1}

ION	HG	80	201	REFERENCE	60 . 1
TARGET	FE	26	55.8		

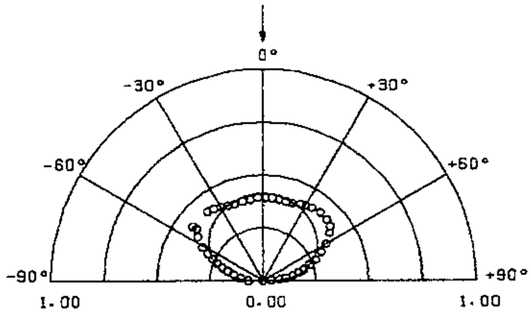


INFORMATION

60 1 25

HG ⇒ FE

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{2}
TARGET	POLY	EPSILON	3.68×10^{-4}
ENVIRONMENT	----------	GAMMA	6.82×10^{-1}
SPUTTERED ATOM (S)	FE	Q	1.12×10^{-1}
		COS^{N} N	4.80×10^{-1}
ION	HG 80 201	REFERENCE	60 - 1
TARGET	FE 26 55.8		

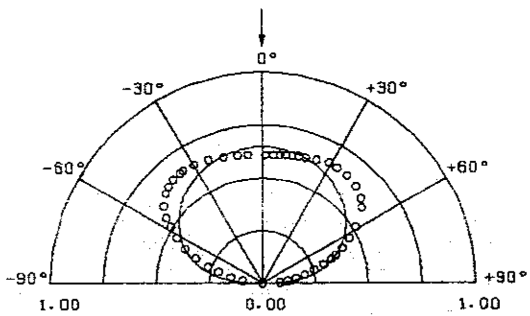


INFORMATION

60 1 26

HG ⇒ FE

INCIDENT ANGLE	0 °	ENERGY (EV)	7.50×10^{2}
TARGET	POLY	EPSILON	5.52×10^{-4}
ENVIRONMENT	----------	GAMMA	6.82×10^{-1}
SPUTTERED ATOM (S)	FE	Q	9.15×10^{-2}
		COS^{N} N	5.40×10^{-1}
ION	HG 80 201	REFERENCE	60 - 1
TARGET	FE 26 55.8		



INFORMATION

60 1 27

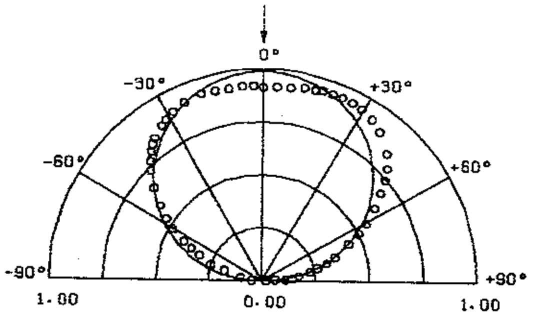
HG ⇒ FE

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	----------
SPUTTERED ATOM (S)	FE

ION	HG	80	201
TARGET	FE	26	55.8

ENERGY (EV)	1.00×10^{3}
EPSILON	7.36×10^{-4}
GAMMA	6.62×10^{-1}
Q	7.92×10^{-2}
COS N	8.90×10^{-1}

REFERENCE 60.1



INFORMATION

69 2 1

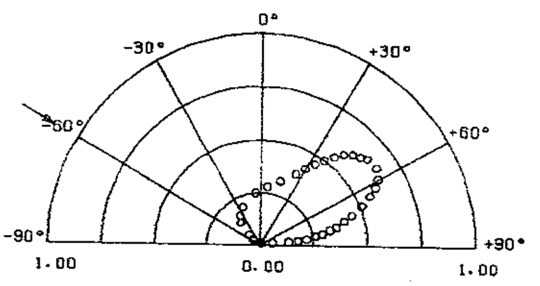
KR ⇒ W

INCIDENT ANGLE	60°
TARGET	POLY
ENVIRONMENT	----------
SPUTTERED ATOM (S)	W

ION	KR	36	83.8
TARGET	W	74	184

ENERGY (EV)	5.00×10^{3}
EPSILON	8.87×10^{-3}
GAMMA	8.60×10^{-1}
Q	4.55×10^{-2}
EJECTION ANGLE EXP.	53.8°
CAL.	34.6°

REFERENCE 69.2

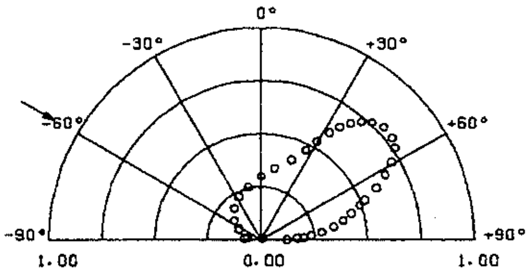


INFORMATION

69 2 2

KR ⇒ W

INCIDENT ANGLE	60°			ENERGY (EV)	1.00×10^{4}
TARGET	POLY			EPSILON	1.77×10^{-2}
ENVIRONMENT	----------			GAMMA	8.60×10^{-1}
SPUTTERED ATOM (S)	W			Q	3.22×10^{-2}
				EJECTION ANGLE EXP.	50.0°
ION	KR	36	83.8	CAL.	33.2°
TARGET	W	74	184		
				REFERENCE	69 . 2

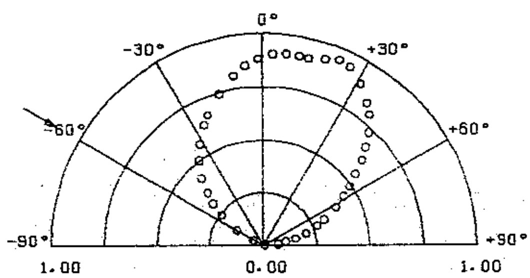


INFORMATION

69 2 3

KR ⇒ W

INCIDENT ANGLE	60°			ENERGY (EV)	1.90×10^{4}
TARGET	POLY			EPSILON	3.37×10^{-2}
ENVIRONMENT	----------			GAMMA	8.60×10^{-1}
SPUTTERED ATOM (S)	W			Q	2.33×10^{-2}
				EJECTION ANGLE EXP.	23.0°
ION	KR	36	83.8	CAL.	32.3°
TARGET	W	74	184		
				REFERENCE	69 . 2



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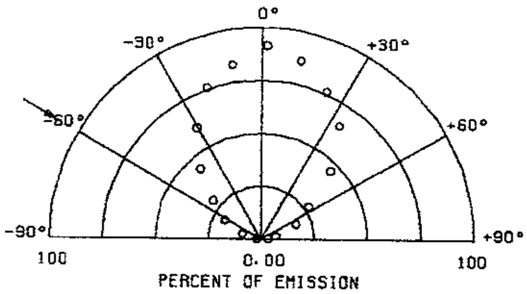
INFORMATION

76 1 1

AR ⇒ CU

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	1.39
ENVIRONMENT	HV	GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU	Q	5.32×10^{-3}
		EJECTION ANGLE EXP.	0.00°
		CAL.	30.5°
ION	AR 18 39.9	REFERENCE	76.1
TARGET	CU 29 63.5		

1.7 MICRO-METER
MAX. EMISSION=88.0



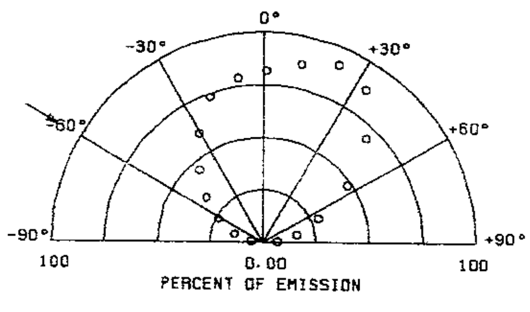
INFORMATION

76 1 2

AR ⇒ CU

INCIDENT ANGLE	60°	ENERGY (EV)	3.00×10^{5}
TARGET	POLY	EPSILON	3.21
ENVIRONMENT	HV	GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU	Q	3.50×10^{-3}
		EJECTION ANGLE EXP.	30.0°
		CAL.	30.3°
ION	AR 18 39.9	REFERENCE	76.1
TARGET	CU 29 63.5		

ERODED SURFACE
11.1 MICRO-METER



INFORMATION

78 1 3

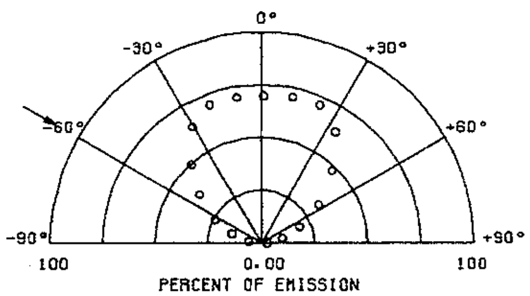
AR ⇒ CU

INCIDENT ANGLE	60°	ENERGY (EV)	3.00×10^{5}
TARGET	POLY	EPSILON	3.21
ENVIRONMENT	HV	GAMMA	9.48×10^{-1}
SPUTTERED ATOM(S)	CU	Q	3.50×10^{-3}
		EJECTION ANGLE EXP.	0.00°
		CAL.	30.3°

ION	AR	18	39.9
TARGET	CU	29	63.5

REFERENCE 76.1

SMOOTH SURFACE
11.1 MICRO-METER



INFORMATION

78 1 4

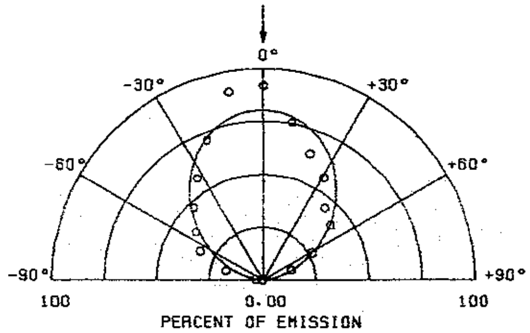
AR ⇒ AU

INCIDENT ANGLE	0°	ENERGY (EV)	3.00×10^{5}
TARGET	POLY	EPSILON	1.28
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM(S)	AU	Q	4.75×10^{-3}
		$\cos^{N}$ N	1.49

ION	AR	18	39.9
TARGET	AU	79	197

REFERENCE 76.1

MAX.EMISSION=57.0
7.3MICRO-METER



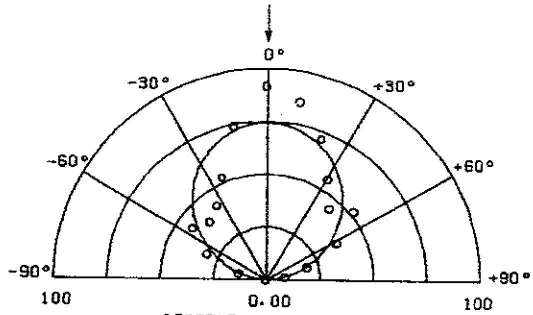
INFORMATION

76 1 5

AR ⇒ AU

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{5}
TARGET	POLY	EPSILON	1.28
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	4.76×10^{-3}
		COS* N	1.17
ION	AR 18 39.9	REFERENCE	76.1
TARGET	AU 79 197		

MAX. EMISSION=63.0
7MICRO-METER



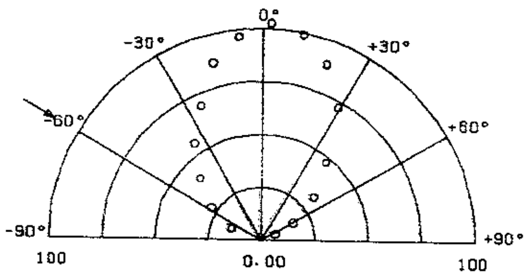
PERCENT OF EMISSION

INFORMATION

76 1 6

AR ⇒ AU

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	5.55×10^{-1}
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	7.23×10^{-3}
		EJECTION ANGLE EXP.	0.00°
		CAL.	30.7°
ION	AR 18 39.9	REFERENCE	76.1
TARGET	AU 79 197		



INFORMATION

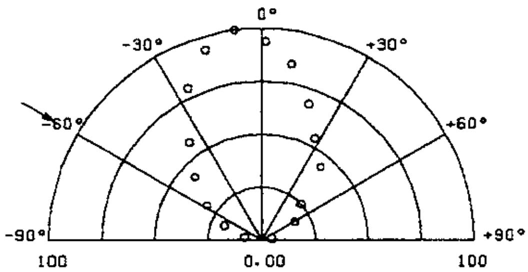
78 : 7

AR ⇒ PT

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	5.63×10^{-1}
ENVIRONMENT	HV	GAMMA	5.64×10^{-1}
SPUTTERED ATOM (S)	PT	Q	8.92×10^{-3}
		EJECTION ANGLE EXP.	0.00°
		CAL.	30.9°

ION	AR	18	39.9
TARGET	PT	78	195

REFERENCE 76.1



INFORMATION

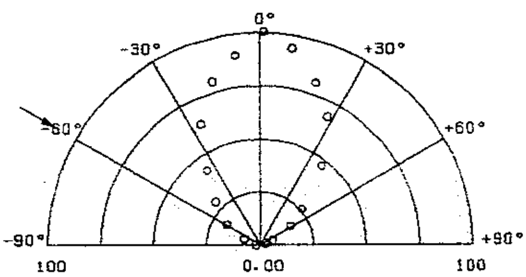
78 : 8

AR ⇒ CU

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	1.39
ENVIRONMENT	HV	GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU	Q	5.32×10^{-2}
		EJECTION ANGLE EXP.	5.00°
		CAL.	30.5°

ION	AR	18	39.9
TARGET	CU	29	63.5

REFERENCE 76.1

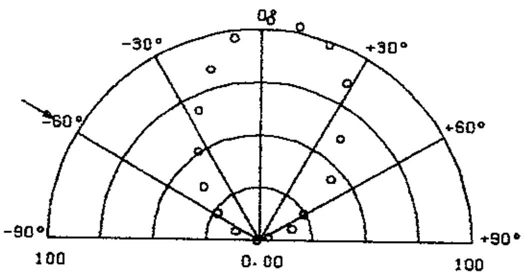


INFORMATION

76 1 8

AR ⇒ FE

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	1.50
ENVIRONMENT	HV	GAMMA	9.72×10^{-1}
SPUTTERED ATOM (S)	FE	Q	5.82×10^{-3}
		EJECTION ANGLE EXP.	5.00°
ION	AR 18 39.9	CAL.	30.6°
TARGET	FE 26 55.8		
		REFERENCE	76.1

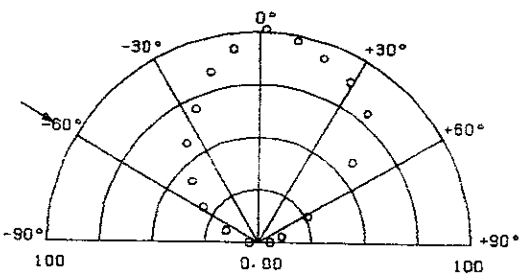


INFORMATION

76 1 10

AR ⇒ TA

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	6.04×10^{-1}
ENVIRONMENT	HV	GAMMA	5.93×10^{-1}
SPUTTERED ATOM (S)	TA	Q	1.03×10^{-2}
		EJECTION ANGLE EXP.	5.00°
ION	AR 18 39.9	CAL.	31.0°
TARGET	TA 73 181		
		REFERENCE	76.1



INFORMATION

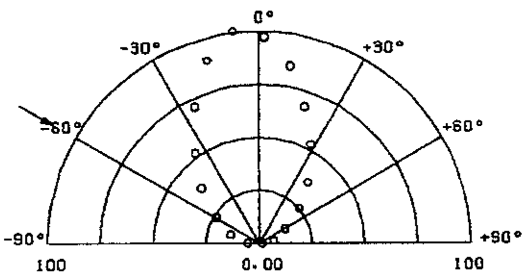
76 1 11

AR ⇒ AU

INCIDENT ANGLE	60°	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	EPSILON	4.27
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	2.61×10^{-3}
		EJECTION ANGLE EXP.	5.00°
		CAL.	30.3°

ION	AR	18	39.9
TARGET	AU	79	197

REFERENCE 76.1



INFORMATION

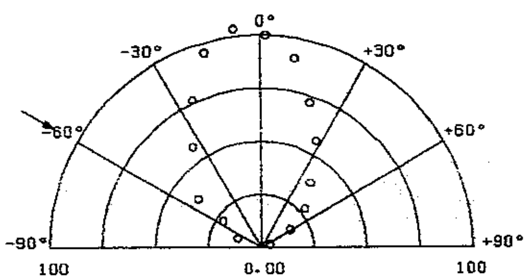
76 1 12

AR ⇒ PT

INCIDENT ANGLE	60°	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	EPSILON	4.33
ENVIRONMENT	HV	GAMMA	5.64×10^{-1}
SPUTTERED ATOM (S)	PT	Q	3.22×10^{-3}
		EJECTION ANGLE EXP.	5.00°
		CAL.	30.3°

ION	AR	18	39.9
TARGET	PT	78	195

REFERENCE 76.1



INFORMATION

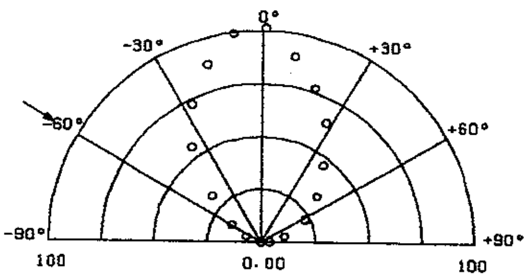
76 1 19

AR ⇒ CU

INCIDENT ANGLE	60°	ENERGY (EV)	1.00×10^{6}
TARGET	POLY	EPSILON	1.07×10^{1}
ENVIRONMENT	HV	GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU	Q	1.92×10^{-3}
		EJECTION ANGLE EXP.	0.00°
		CAL.	30.2°

ION	AR	18	39.9
TARGET	CU	29	63.5

REFERENCE 76.1



INFORMATION

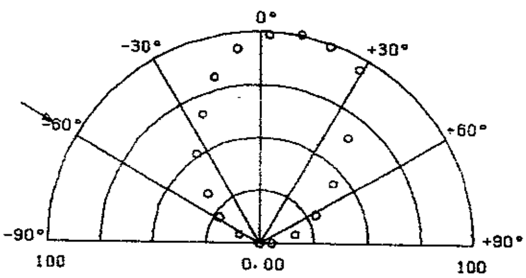
76 1 14

AR ⇒ FE

INCIDENT ANGLE	60°	ENERGY (EV)	1.00×10^{6}
TARGET	POLY	EPSILON	1.16×10^{1}
ENVIRONMENT	HV	GAMMA	9.72×10^{-1}
SPUTTERED ATOM (S)	FE	Q	2.10×10^{-3}
		EJECTION ANGLE EXP.	20.0°
		CAL.	30.2°

ION	AR	18	39.9
TARGET	FE	26	55.8

REFERENCE 76.1



INFORMATION

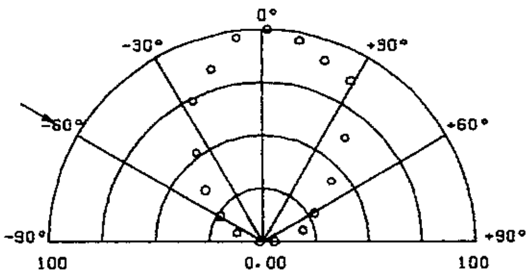
76 I 15

AR ⇒ TA

INCIDENT ANGLE	60°	ENERGY (EV)	1.00×10^{6}
TARGET	POLY	EPSILON	4.64
ENVIRONMENT	HV	GAMMA	5.93×10^{-1}
SPUTTERED ATOM (S)	TA	Q	3.70×10^{-3}
		EJECTION ANGLE EXP.	0.00°
		CAL.	30.4°

ION	AR	18	39.9
TARGET	TA	73	181

REFERENCE 76.1



INFORMATION

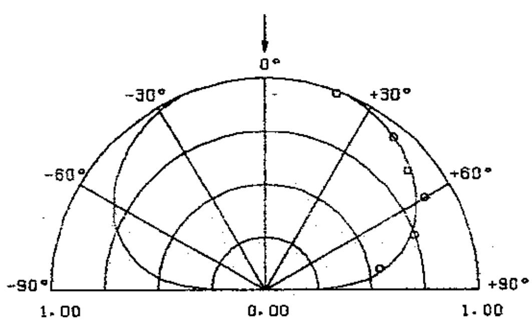
77 1 I

KR ⇒ CU

INCIDENT ANGLE	0°	ENERGY (EV)	5.00×10^{3}
TARGET	POLY	EPSILON	1.68×10^{-2}
ENVIRONMENT	HV	GAMMA	9.81×10^{-1}
SPUTTERED ATOM (S)	CU	Q	2.67×10^{-2}
		COS^{N} N	3.30×10^{-1}

ION	KR	36	83.8
TARGET	CU	29	63.5

REFERENCE 77.1



INFORMATION

77 1 2

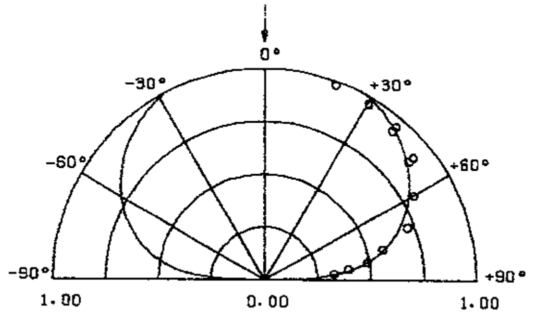
KR ⇒ CU

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	HV
SPUTTERED ATOM (S)	CU

ENERGY (EV)	8.00×10^{3}
EPSILON	2.69×10^{-2}
GAMMA	9.81×10^{-1}
Q	2.11×10^{-2}
COS^{N} N	4.40×10^{-1}

ION	KR	36	83.8
TARGET	CU	29	63.5

REFERENCE 77.1



INFORMATION

77 1 3

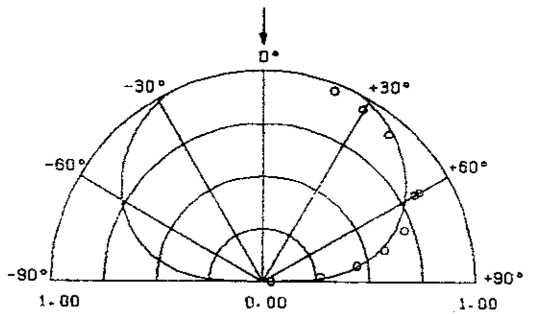
KR ⇒ CU

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	HV
SPUTTERED ATOM (S)	CU

ENERGY (EV)	1.40×10^{4}
EPSILON	4.71×10^{-2}
GAMMA	9.81×10^{-1}
Q	1.59×10^{-2}
COS^{N} N	4.60×10^{-1}

ION	KR	36	83.8
TARGET	CU	29	63.5

REFERENCE 77.1



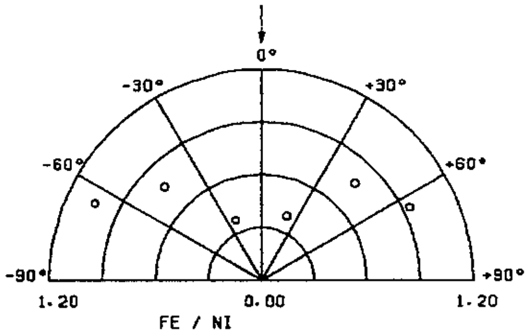
INFORMATION

77 2 1

HG ⇒ FE-NI

INCIDENT ANGLE	0 °	ENERGY (EV)	1.40×10^4
TARGET	POLY	REFERENCE	77.2
ENVIRONMENT	----------		
SPUTTERED ATOM (S)	FE / NI		

ION	HG	80	201
TARGET	FE	26	55.8
	NI	28	58.7



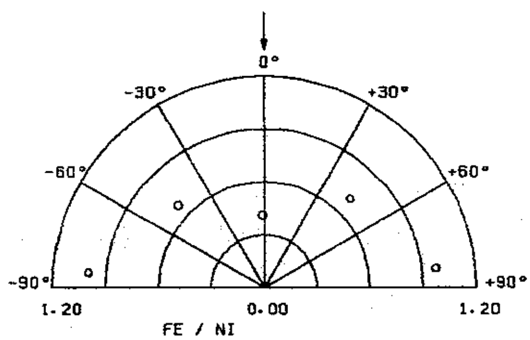
INFORMATION

77 2 2

HG ⇒ FE-NI

INCIDENT ANGLE	0 °	ENERGY (EV)	1.40×10^4
TARGET	POLY	REFERENCE	77.2
ENVIRONMENT	----------		
SPUTTERED ATOM (S)	FE / NI		

ION	HG	80	201
TARGET	FE	26	55.8
	NI	28	58.7



26

INFORMATION

77 2 3

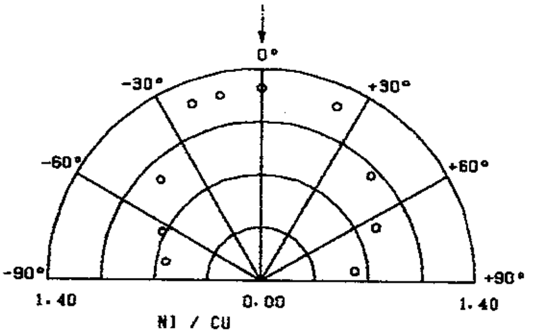
HG ⇒ NI-CU

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	----------
SPUTTERED ATOM (S)	NI / CU

ION	HG	80	201
TARGET	NI	28	58.7
	CU	29	63.5

ENERGY (EV) 1.40 X10^4

REFERENCE 77.2



INFORMATION

77 2 4

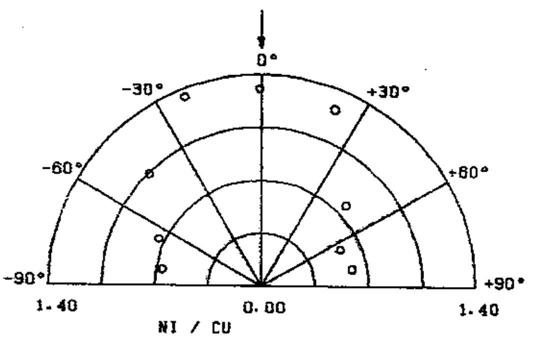
AR ⇒ NI-CU

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	----------
SPUTTERED ATOM (S)	NI / CU

ION	AR	18	39.9
TARGET	NI	28	58.7
	CU	29	63.5

ENERGY (EV) 1.40 X10^4

REFERENCE 77.2



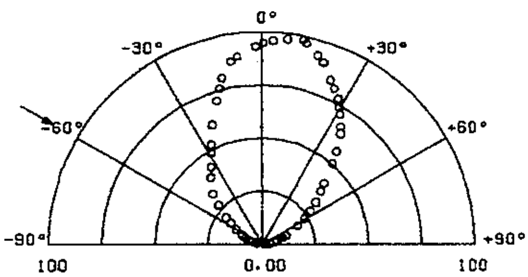
INFORMATION

77 3 1

AR ⇒ PT

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	5.63×10^{-1}
ENVIRONMENT	HV	GAMMA	5.64×10^{-1}
SPUTTERED ATOM (S)	PT	Q	8.92×10^{-3}
		EJECTION ANGLE EXP.	10.08
		CAL.	30.9°
ION	AR 18 39.9	REFERENCE	77.3
TARGET	PT 78 195		

REMOVAL=0.48 MICRO-METER



PERCENT OF EMISSION

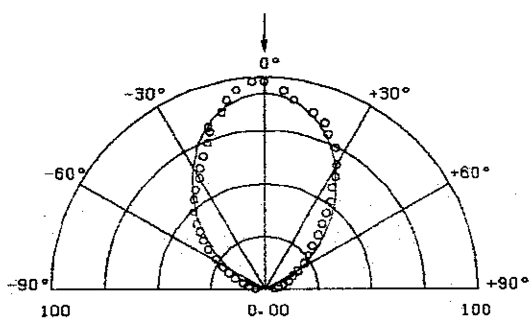
INFORMATION

77 3 2

AR ⇒ PT

INCIDENT ANGLE	0°	ENERGY (EV)	3.00×10^{5}
TARGET	POLY	EPSILON	1.30
ENVIRONMENT	HV	GAMMA	5.64×10^{-1}
SPUTTERED ATOM (S)	PT	Q	5.87×10^{-3}
		$\cos^{N}$ N	2.28
ION	AR 18 39.9	REFERENCE	77.3
TARGET	PT 78 195		

REMOVAL=1.3 MICRO-METER



PERCENT OF EMISSION

INFORMATION

77 3 9

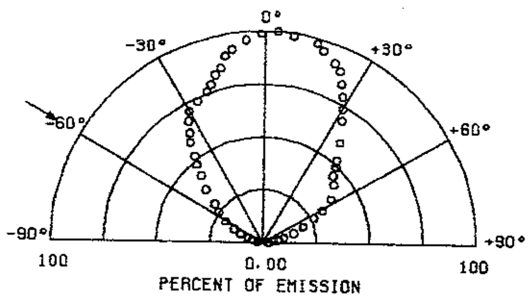
AR ⇒ PT

INCIDENT ANGLE	60°	ENERGY (EV)	3.00×10^{5}
TARGET	POLY	EPSILON	1.30
ENVIRONMENT	HV	GAMMA	5.64×10^{-1}
SPUTTERED ATOM (S)	PT	Q	5.87×10^{-3}
		EJECTION ANGLE EXP.	10.08
		CAL.	30.6°

ION	AR	18	39.9
TARGET	PT	78	195

REFERENCE 77.3

REMOVAL=0.44 MICRO-METER



INFORMATION

77 3 4

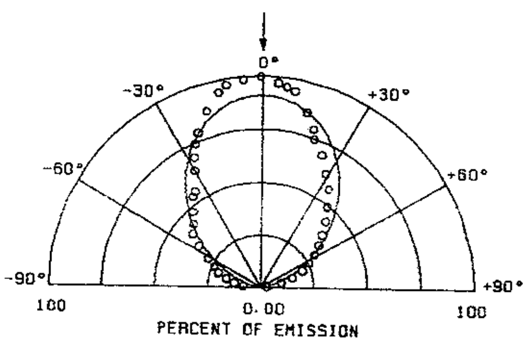
AR ⇒ AU

INCIDENT ANGLE	0 °	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	5.55×10^{-1}
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	7.23×10^{-3}
		COS* N	1.85

ION	AR	18	39.9
TARGET	AU	79	197

REFERENCE 77.3

REMOVAL=0.49 MICRO-METER



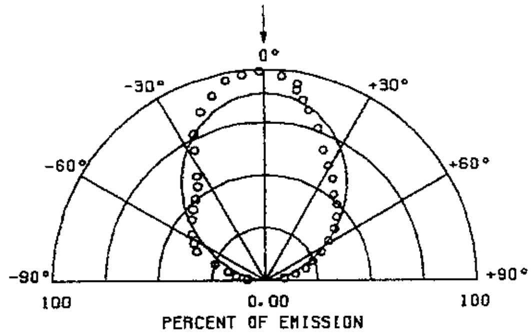
INFORMATION

77 3 5

AR ⇒ AU

INCIDENT ANGLE	0 °	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	5.55×10^{-1}
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	7.23×10^{-3}
		COS^{N} N	1.44
ION	AR 18 39.9	REFERENCE	77.3
TARGET	AU 79 197		

REMOVAL=4.6 MICRO-METER



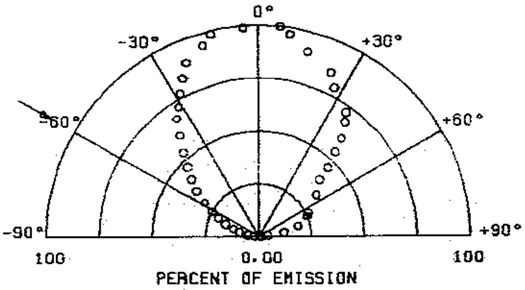
INFORMATION

77 3 6

AR ⇒ AU

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	5.55×10^{-1}
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	7.23×10^{-3}
		EJECTION ANGLE EXP.	0.00°
		CAL.	30.7°
ION	AR 18 39.9	REFERENCE	77.3
TARGET	AU 79 197		

REMOVAL=0.096 MICRO-METER



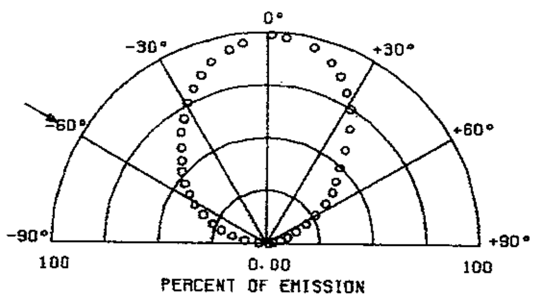
INFORMATION

77 3 7

AR ⇒ AU

INCIDENT ANGLE	60°		ENERGY (EV)	1.30×10^{5}
TARGET	POLY		EPSILON	5.55×10^{-1}
ENVIRONMENT	HV		GAMMA	5.61×10^{-1}
SPUTTERED ATOM(S)	AU		Q	7.23×10^{-3}
			EJECTION ANGLE EXP.	0.00°
			CAL.	30.7°
ION	AR 18	39.9	REFERENCE	77.3
TARGET	AU 79	197		

REMOVAL=2.7 MICRO-METER

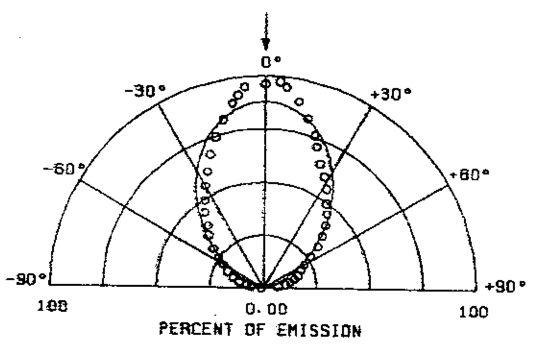


INFORMATION

77 3 8

AR ⇒ AU

INCIDENT ANGLE	0°		ENERGY (EV)	1.00×10^{6}
TARGET	POLY		EPSILON	4.27
ENVIRONMENT	HV		GAMMA	5.61×10^{-1}
SPUTTERED ATOM(S)	AU		Q	2.61×10^{-3}
			COS^{N} N	2.28
ION	AR 18	39.9	REFERENCE	77.3
TARGET	AU 79	197		

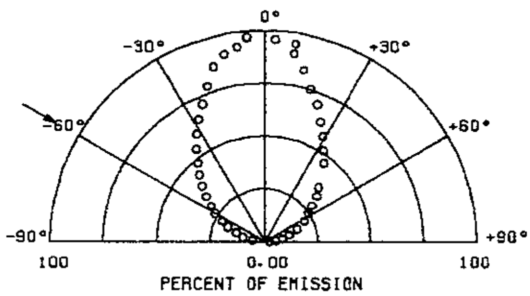


INFORMATION

77 3 9

AR ⇒ AU

INCIDENT ANGLE	60°		ENERGY (EV)	1.00×10^{6}	
TARGET	POLY		EPSILON	4.27	
ENVIRONMENT	HV		GAMMA	5.61×10^{-1}	
SPUTTERED ATOM (S)	AU		Q	2.61×10^{-3}	
			EJECTION ANGLE EXP.	0.00°	
			CAL.	30.3°	
ION	AR	18	39.9		
TARGET	AU	79	197		
			REFERENCE	77.3	

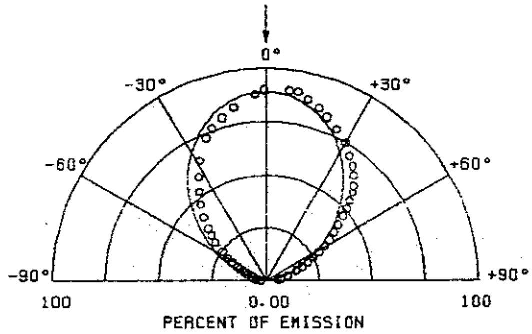


INFORMATION

77 3 10

AR ⇒ CU

INCIDENT ANGLE	0°		ENERGY (EV)	1.30×10^{5}	
TARGET	POLY		EPSILON	1.39	
ENVIRONMENT	HV		GAMMA	9.48×10^{-1}	
SPUTTERED ATOM (S)	CU		Q	5.32×10^{-3}	
			COS^{N} N	1.71	
ION	AR	18	39.9		
TARGET	CU	29	63.5		
			REFERENCE	77.3	

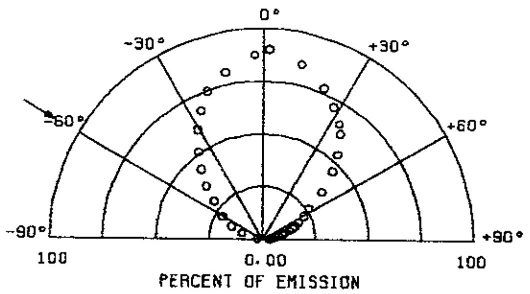


INFORMATION

77 9 11

AR ⇒ CU

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	1.39
ENVIRONMENT	HV	GAMMA	9.48×10^{-1}
SPUTTERED ATOM(S)	CU	Q	5.32×10^{-3}
		EJECTION ANGLE EXP.	0.00°
		CAL.	30.5°
ION	AR 18 39.9	REFERENCE	77.3
TARGET	CU 29 63.5		

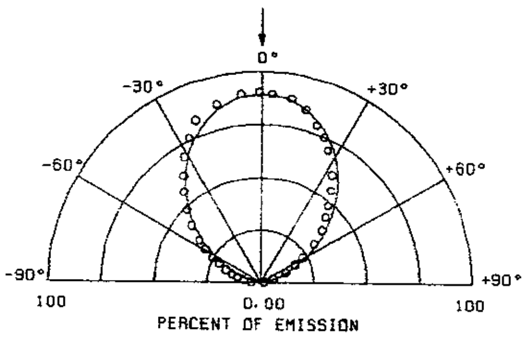


INFORMATION

77 9 12

AR ⇒ CU

INCIDENT ANGLE	0°	ENERGY (EV)	3.00×10^{5}
TARGET	POLY	EPSILON	3.21
ENVIRONMENT	HV	GAMMA	9.48×10^{-1}
SPUTTERED ATOM(S)	CU	Q	3.50×10^{-2}
		COS* N	1.82
ION	AR 18 39.9	REFERENCE	77.3
TARGET	CU 29 63.5		

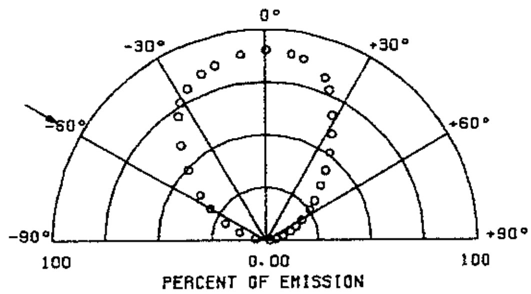


INFORMATION

77 9 19

AR ⇒ CU

INCIDENT ANGLE	60°			ENERGY (EV)	3.00×10^{5}
TARGET	POLY			EPSILON	3.21
ENVIRONMENT	HV			GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU			Q	3.50×10^{-3}
				EJECTION ANGLE EXP.	0.00°
ION	AR	18	39.9	CAL.	30.3°
TARGET	CU	29	63.5		
				REFERENCE	77.3

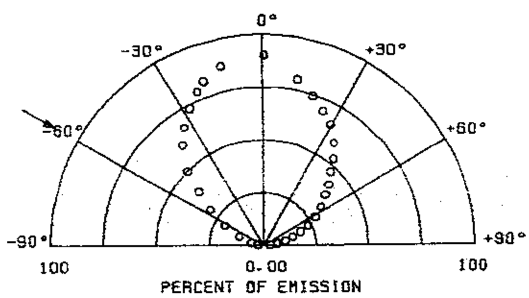


INFORMATION

77 9 14

AR ⇒ CU

INCIDENT ANGLE	60°			ENERGY (EV)	1.00×10^{6}
TARGET	POLY			EPSILON	1.07×10^{1}
ENVIRONMENT	HV			GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU			Q	1.92×10^{-3}
				EJECTION ANGLE EXP.	0.00°
ION	AR	18	39.9	CAL.	30.2°
TARGET	CU	29	63.5		
				REFERENCE	77.3

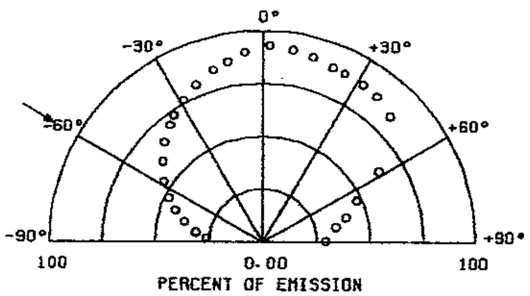


INFORMATION

77 9 15

AR ⇒ TA

INCIDENT ANGLE	60°		ENERGY (EV)	1.30×10^{5}
TARGET	POLY		EPSILON	6.04×10^{-1}
ENVIRONMENT	HV		GAMMA	5.93×10^{-1}
SPUTTERED ATOM (S)	TA		Q	1.03×10^{-2}
			EJECTION ANGLE	
			EXP.	29.0°
			CAL.	31.0°
ION	AR 18	39.9		
TARGET	TA 73	181	REFERENCE	77.3

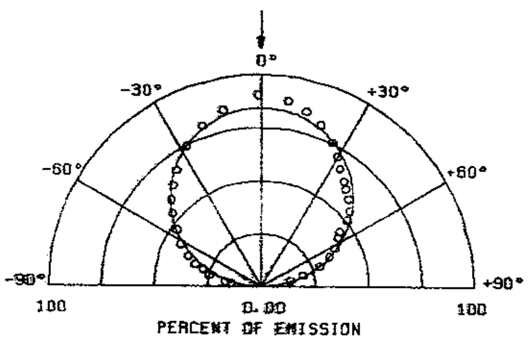


INFORMATION

77 9 16

AR ⇒ TA

INCIDENT ANGLE	0°		ENERGY (EV)	3.00×10^{5}
TARGET	POLY		EPSILON	1.39
ENVIRONMENT	HV		GAMMA	5.93×10^{-1}
SPUTTERED ATOM (S)	TA		Q	6.75×10^{-3}
			COS * N	9.90×10^{-1}
ION	AR 18	39.9		
TARGET	TA 73	181	REFERENCE	77.3

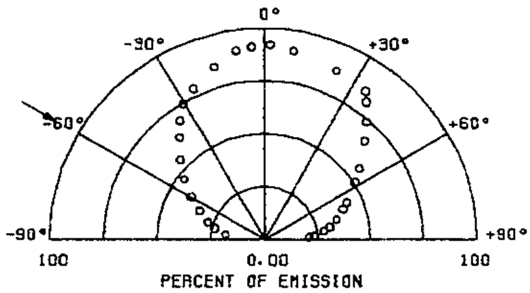


INFORMATION

77 3 17

AR ⇒ TA

INCIDENT ANGLE	60°	ENERGY (EV)	1.00×10^{6}
TARGET	POLY	EPSILON	4.64
ENVIRONMENT	HV	GAMMA	5.93×10^{-1}
SPUTTERED ATOM(S)	TA	Q	3.70×10^{-3}
		EJECTION ANGLE EXP.	0.00°
		CAL.	30.4°
ION	AR 18 39.9		
TARGET	TA 73 181	REFERENCE	77.3



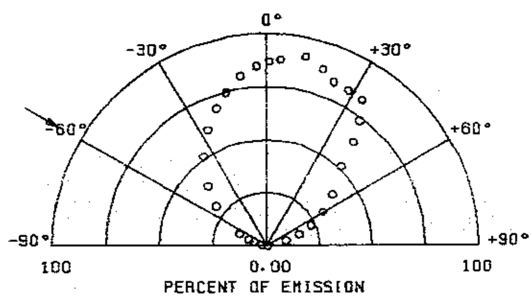
INFORMATION

77 3 18

AR ⇒ FE

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	1.50
ENVIRONMENT	HV	GAMMA	9.72×10^{-1}
SPUTTERED ATOM(S)	FE	Q	5.82×10^{-3}
		EJECTION ANGLE EXP.	20.0°
		CAL.	30.6°
ION	AR 18 39.9		
TARGET	FE 26 55.8	REFERENCE	77.3

0.22 MICRO-METER



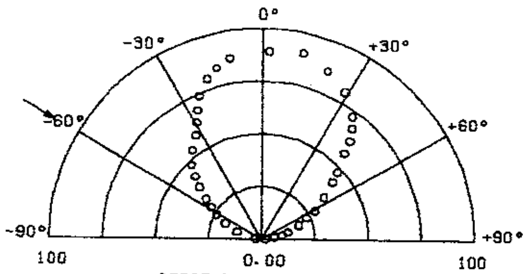
INFORMATION

77 9 19

AR ⇒ FE

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	1.50
ENVIRONMENT	HV	GAMMA	9.72×10^{-1}
SPUTTERED ATOM (S)	FE	Q	5.82×10^{-3}
		EJECTION ANGLE EXP.	0.00°
ION	AR 18 39.9	CAL.	30.6°
TARGET	FE 26 55.8	REFERENCE	77.3

0.94 MICRO-METER



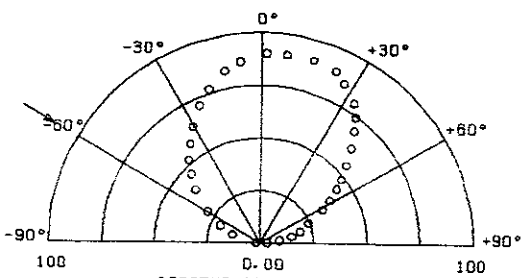
INFORMATION

77 9 20

AR ⇒ FE

INCIDENT ANGLE	60°	ENERGY (EV)	1.30×10^{5}
TARGET	POLY	EPSILON	1.50
ENVIRONMENT	HV	GAMMA	9.72×10^{-1}
SPUTTERED ATOM (S)	FE	Q	5.82×10^{-3}
		EJECTION ANGLE EXP.	0.00°
ION	AR 18 39.9	CAL.	30.6°
TARGET	FE 26 55.8	REFERENCE	77.3

2.00 MICRO-METER



INFORMATION

77 9 21

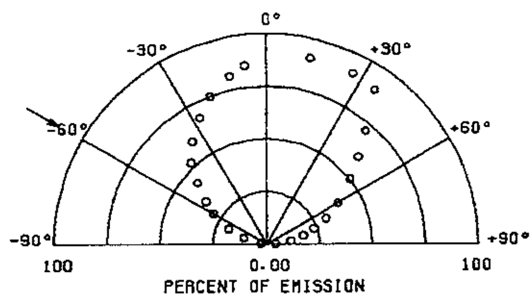
AR ⇒ FE

INCIDENT ANGLE	60°	ENERGY (EV)	1.00×10^{6}
TARGET	POLY	EPSILON	1.16×10^{1}
ENVIRONMENT	HV	GAMMA	9.72×10^{-1}
SPUTTERED ATOM (S)	FE	Q	2.10×10^{-3}
		EJECTION ANGLE EXP.	20.0°
		CAL.	30.2°

ION	AR	18	39.9
TARGET	FE	26	55.8

REFERENCE 77.3

1.10 MICRO-METER



INFORMATION

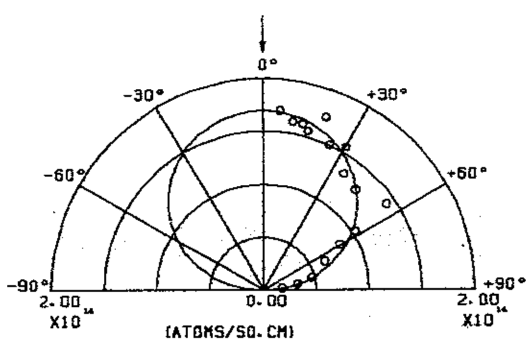
78 5 1

HE ⇒ MO

INCIDENT ANGLE	0°	ENERGY (EV)	6.50×10^{4}
TARGET	POLY	EPSILON	7.38
ENVIRONMENT	UHV	GAMMA	1.54×10^{-1}
SPUTTERED ATOM (S)	MO	Q	2.61×10^{-2}
		COS^{N} N	8.80×10^{-1}

ION	HE	2	4.00
TARGET	MO	42	95.9

REFERENCE 78.5

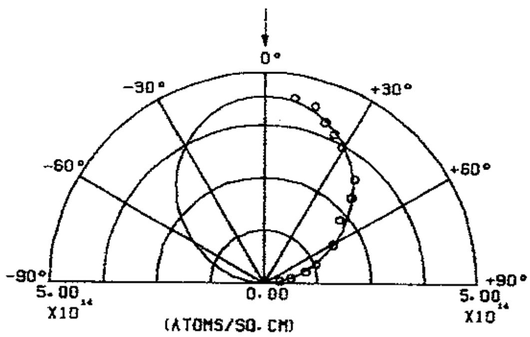


INFORMATION

78 5 2

HE ⇒ AG

INCIDENT ANGLE	0 °		ENERGY (EV)	4.00×10^{4}	
TARGET	POLY		EPSILON	3.94	
ENVIRONMENT	UHV		GAMMA	1.38×10^{-1}	
SPUTTERED ATOM (S)	AG		Q	2.31×10^{-2}	
			COS^{n} N	1.22	
ION	HE	2	4.00		
TARGET	AG	47	108		
			REFERENCE	78.5	

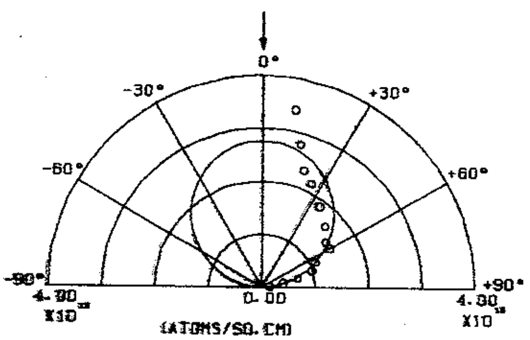


INFORMATION

78 5 3

AR ⇒ MO

INCIDENT ANGLE	0 °		ENERGY (EV)	4.00×10^{4}	
TARGET	POLY		EPSILON	3.15×10^{-1}	
ENVIRONMENT	UHV		GAMMA	8.30×10^{-1}	
SPUTTERED ATOM (S)	MO		Q	1.43×10^{-2}	
			COS^{n} N	1.08	
ION	AR	18	39.9		
TARGET	MO	42	95.9		
			REFERENCE	78.5	

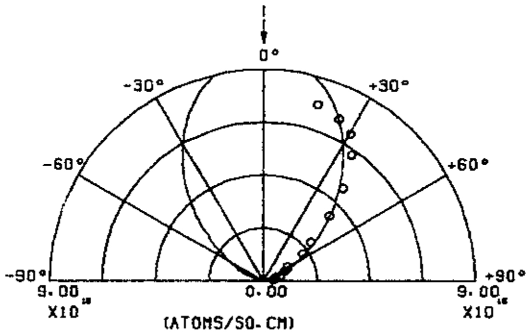


INFORMATION

79 S 4

AR ⇒ AG

INCIDENT ANGLE	0 °		ENERGY (EV)	2.00×10^{4}
TARGET	POLY		EPSILON	1.42×10^{-1}
ENVIRONMENT	UHV		GAMMA	7.89×10^{-1}
SPUTTERED ATOM (S)	AG		Q	1.37×10^{-2}
			COS ^{N} N	2.56
ION	AR 18	39.9	REFERENCE	78.5
TARGET	AG 47	108		



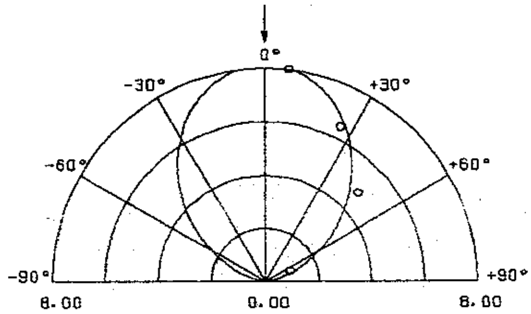
INFORMATION

79 1 1

H3 ⇒ 304 S. S.

INCIDENT ANGLE	0 °		ENERGY (EV)	0.00
TARGET	POLY		EPSILON	0.00
ENVIRONMENT	UHV		GAMMA	6.97×10^{-2}
SPUTTERED ATOM (S)	CR		Q	0.00
			COS ^{N} N	1.81
ION	H 1	1.01	REFERENCE	79.1
TARGET	FE 26 CR 24	55.8 52.0		

ENERGY RANGE 5–10KEV
TARGET: STAINLESS STEEL



SPUTTERD CR SIGNAL
(ARB. UNITS)

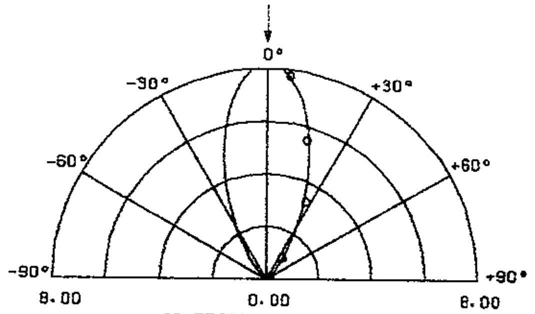
INFORMATION

79 1 2

H3 ⇒ 304 S. S.

INCIDENT ANGLE	0 °		ENERGY (EV)	0. 00
TARGET	POLY		EPSILON	0. 00
ENVIRONMENT	UHV		GAMMA	6. 97 X10^{-2}
SPUTTERED ATOM (S)	CR		Q	0. 00
			COS^{N} N	8. 97
ION	H 1	1. 01	REFERENCE	79 . 1
TARGET	FE 26 CR 24	55. 8 52. 0		

ENERGY RANGE 5-10KEV
TARGET: STAINLESS STEAL



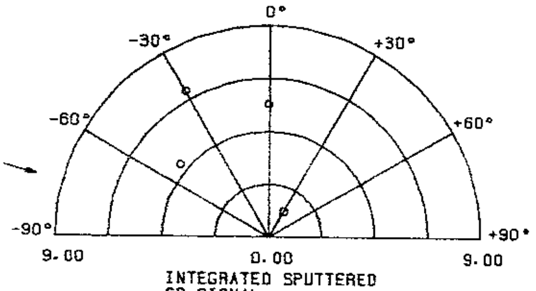
INFORMATION

79 1 3

H3 ⇒ 304 S. S.

INCIDENT ANGLE	75°		ENERGY (EV)	0. 00
TARGET	POLY		EPSILON	0. 00
ENVIRONMENT	UHV		GAMMA	6. 97 X10^{-2}
SPUTTERED ATOM (S)	CR		Q	0. 00
			EJECTION ANGLE EXP.	30. 0°
			CAL.	0. 00°
ION	H 1	1. 01	REFERENCE	79 . 1
TARGET	FE 26 CR 24	55. 8 52. 0		

ENERGY RANGE 5-10KEV
TARGET: STAINLESS STEEL



INFORMATION

79 1 4

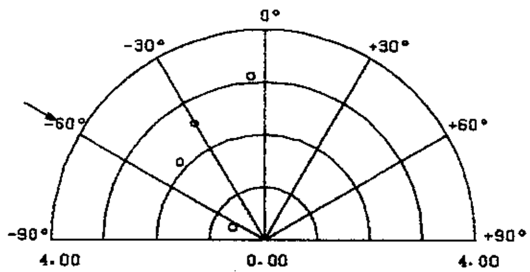
H3 ⇒ 304 S.S.

INCIDENT ANGLE	60°	ENERGY (EV)	0.00
TARGET	POLY	EPSILON	0.00
ENVIRONMENT	UHV	GAMMA	6.97×10^{-2}
SPUTTERED ATOM (S)	CR	Q	0.00
		EJECTION ANGLE EXP.	4.81°
		CAL.	0.00°

ION	H	1	1.01
TARGET	FE	26	55.8
	CR	24	52.0

REFERENCE 79.1

ENERGY RANGE 5-10KEV
TARGET: STAINLESS STEEL



INTEGRATED SPUTTERED
CR SIGNAL
(ARB. UNITS)

INFORMATION

79 1 5

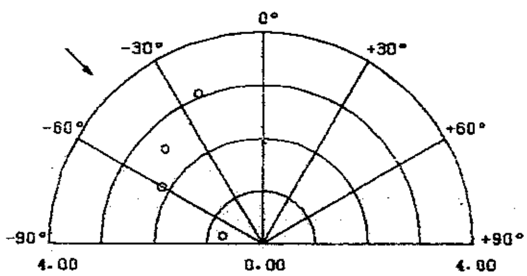
H3 ⇒ 304 S.S.

INCIDENT ANGLE	45°	ENERGY (EV)	0.00
TARGET	POLY	EPSILON	0.00
ENVIRONMENT	UHV	GAMMA	6.97×10^{-2}
SPUTTERED ATOM (S)	CR	Q	0.00
		EJECTION ANGLE EXP.	22.6°
		CAL.	0.00°

ION	H	1	1.01
TARGET	FE	26	55.8
	CR	24	52.0

REFERENCE 79.1

ENERGY RANGE 5-10KEV
TARGET: STAINLESS STEEL



INTEGRATED SPUTTERED
CR SIGNAL
(ARB. UNITS)

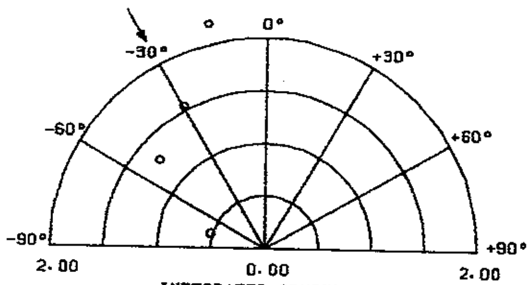
INFORMATION

79 1 6

H3 ⇒ 304 S. S.

INCIDENT ANGLE	30°		ENERGY (EV)	0.00
TARGET	POLY		EPSILON	0.00
ENVIRONMENT	UHV		GAMMA	6.97×10^{-2}
SPUTTERED ATOM (S)	CR		Q	0.00
			EJECTION ANGLE EXP.	14.5°
			CAL.	0.00°
ION	H 1	1.01	REFERENCE	79.1
TARGET	FE 26	55.8		
	CR 24	52.0		

ENERGY RANGE 5-10KEV
TARGET: STAINLESS STEEL

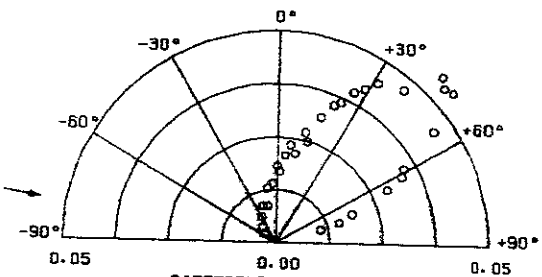


INFORMATION

79 2 1

H3 ⇒ NI

INCIDENT ANGLE	80°		ENERGY (EV)	1.00×10^{3}
TARGET	POLY		EPSILON	4.03×10^{-1}
ENVIRONMENT	UHV		GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI		Q	2.59×10^{-1}
			EJECTION ANGLE EXP.	45.0°
			CAL.	33.1°
ION	H 1	1.01	REFERENCE	79.2
TARGET	NI 28	58.7		



INFORMATION

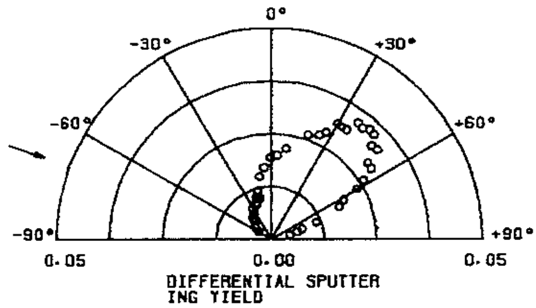
78 2 2

H3 ⇒ NI

INCIDENT ANGLE	70°	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	4.03×10^{-1}
ENVIRONMENT	UHV	GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI	Q	2.59×10^{-1}
		EJECTION ANGLE EXP.	43.0°
		CAL.	45.9°

ION	H	1	1.01
TARGET	NI	28	58.7

REFERENCE 79.2



INFORMATION

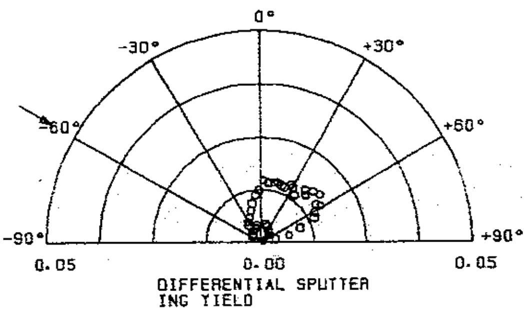
78 2 3

H3 ⇒ CR

INCIDENT ANGLE	60°	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	4.92×10^{-1}
ENVIRONMENT	UHV	GAMMA	7.46×10^{-2}
SPUTTERED ATOM (S)	CR	Q	2.34×10^{-1}
		EJECTION ANGLE EXP.	49.0°
		CAL.	57.5°

ION	H	1	1.01
TARGET	CR	24	52.0

REFERENCE 79.2



INFORMATION

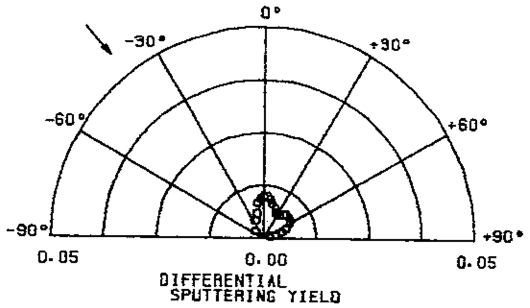
79 2 4

H3 ⇒ NI

INCIDENT ANGLE	40°	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	4.03×10^{-1}
ENVIRONMENT	UHV	GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI	Q	2.59×10^{-1}
		EJECTION ANGLE EXP.	50.0°
		CAL.	90.0°

ION	H	1	1.01
TARGET	NI	28	58.7

REFERENCE 79.2



INFORMATION

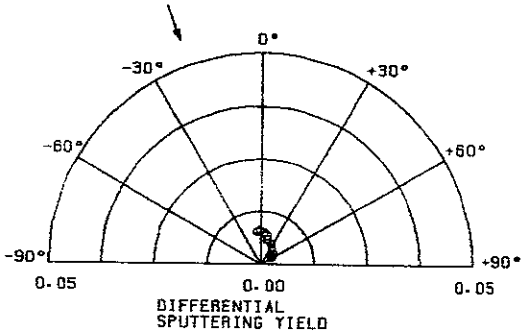
79 2 5

H3 ⇒ NI

INCIDENT ANGLE	20°	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	4.03×10^{-1}
ENVIRONMENT	UHV	GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI	Q	2.59×10^{-1}
		EJECTION ANGLE EXP.	50.0°
		CAL.	90.0°

ION	H	1	1.01
TARGET	NI	28	58.7

REFERENCE 79.2



INFORMATION

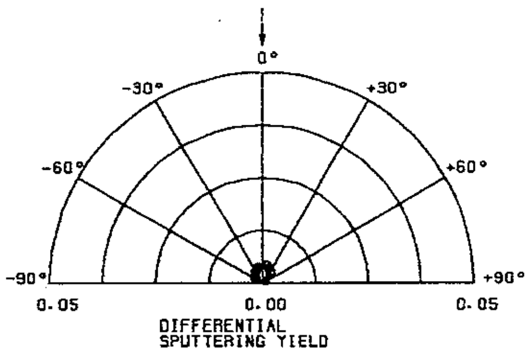
79 2 6

H3 ⇒ NI

INCIDENT ANGLE	0°		ENERGY (EV)	1.00×10^{3}
TARGET	POLY		EPSILON	4.03×10^{-1}
ENVIRONMENT	UHV		GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI		Q	2.59×10^{-1}
			COS^{N} N	2.09

ION	H	1	1.01
TARGET	NI	28	58.7

REFERENCE 79.2



INFORMATION

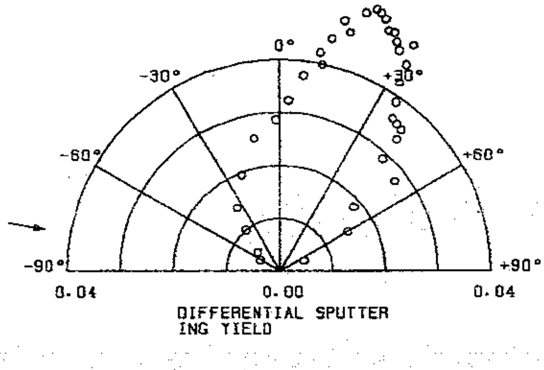
79 2 7

H2 ⇒ NI

INCIDENT ANGLE	80°		ENERGY (EV)	4.00×10^{3}
TARGET	POLY		EPSILON	1.61
ENVIRONMENT	UHV		GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI		Q	1.29×10^{-1}
			EJECTION ANGLE EXP.	21.0°
			CAL.	21.2°

ION	H	1	1.01
TARGET	NI	28	58.7

REFERENCE 79.2

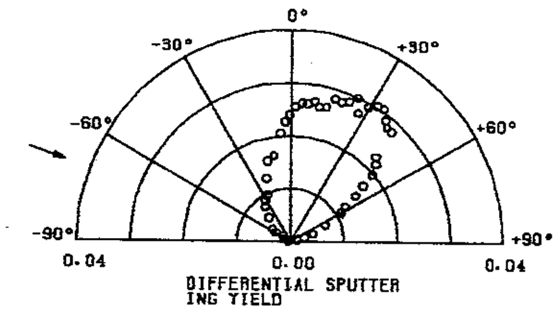


INFORMATION

79 2 8

H2 ⇒ NI

INCIDENT ANGLE	70°		ENERGY (EV)	4.00×10^{3}	
TARGET	POLY		EPSILON	1.61	
ENVIRONMENT	UHV		GAMMA	6.64×10^{-2}	
SPUTTERED ATOM (S)	NI		Q	1.29×10^{-1}	
			EJECTION ANGLE EXP.	33.7°	
			CAL.	32.1°	
ION	H	1	1.01		
TARGET	NI	28	58.7		
			REFERENCE	79.2	

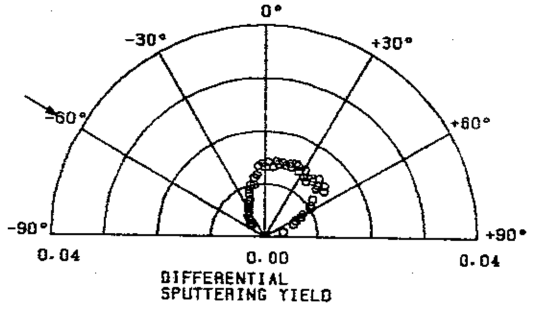


INFORMATION

79 2 9

H2 ⇒ NI

INCIDENT ANGLE	60°		ENERGY (EV)	4.00×10^{3}	
TARGET	POLY		EPSILON	1.61	
ENVIRONMENT	UHV		GAMMA	6.64×10^{-2}	
SPUTTERED ATOM (S)	NI		Q	1.29×10^{-1}	
			EJECTION ANGLE EXP.	42.0°	
			CAL.	43.7°	
ION	H	1	1.01		
TARGET	NI	28	58.7		
			REFERENCE	79.2	

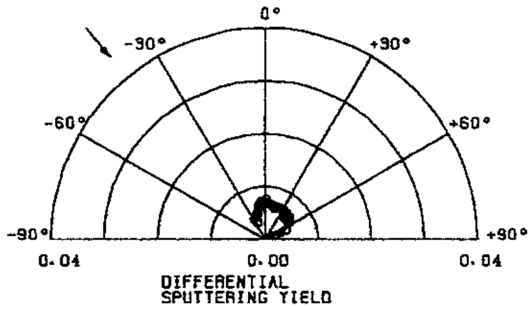


INFORMATION

78 2 10

$H_2 \Rightarrow$ NI

INCIDENT ANGLE	40°	ENERGY (EV)	4.00×10^{3}
TARGET	POLY	EPSILON	1.61
ENVIRONMENT	UHV	GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI	Q	1.29×10^{-1}
		EJECTION ANGLE EXP.	50.0°
ION	H 1 1.01	CAL.	73.3°
TARGET	NI 28 58.7	REFERENCE	79.2

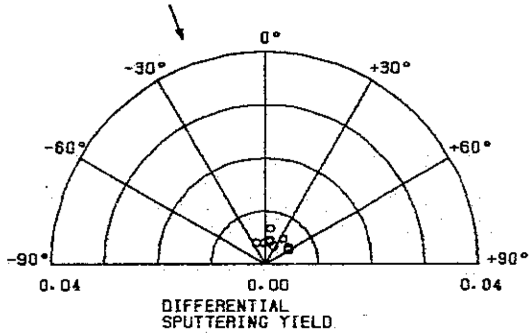


INFORMATION

79 2 11

$H_2 \Rightarrow$ NI

INCIDENT ANGLE	20°	ENERGY (EV)	4.00×10^{3}
TARGET	POLY	EPSILON	1.61
ENVIRONMENT	UHV	GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI	Q	1.29×10^{-1}
		EJECTION ANGLE EXP.	50.0°
ION	H 1 1.01	CAL.	90.0°
TARGET	NI 28 58.7	REFERENCE	79.2



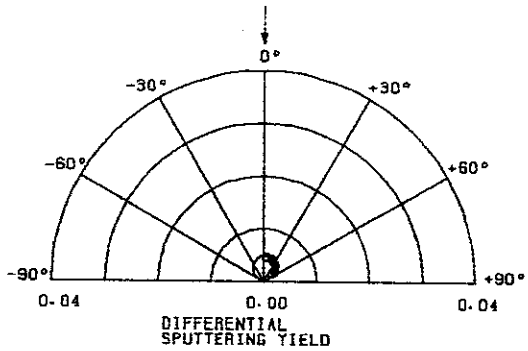
48

INFORMATION

79 2 12

H2 ⇒ NI

INCIDENT ANGLE	0 °			ENERGY (EV)	4.00×10^{3}
TARGET	POLY			EPSILON	1.61
ENVIRONMENT	UHV			GAMMA	6.64×10^{-2}
SPUTTERED ATOM(S)	NI			Q	1.29×10^{-1}
				COS^{N} N	1.63
ION	H	1	1.01	REFERENCE	79.2
TARGET	NI	28	58.7		

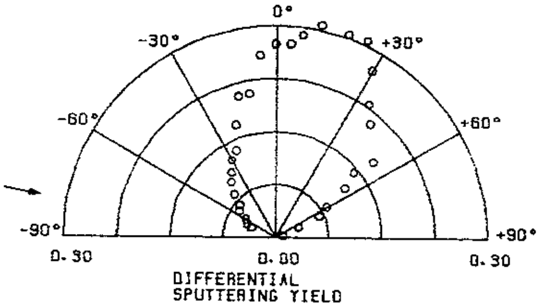


INFORMATION

79 2 19

HE ⇒ NI

INCIDENT ANGLE	80°			ENERGY (EV)	4.00×10^{3}
TARGET	POLY			EPSILON	7.47×10^{-1}
ENVIRONMENT	UHV			GAMMA	2.39×10^{-1}
SPUTTERED ATOM(S)	NI			Q	6.81×10^{-2}
				EJECTION ANGLE EXP.	15.0°
				CAL.	15.9°
ION	HE	2	4.00	REFERENCE	79.2
TARGET	NI	28	58.7		



INFORMATION

79 2 14

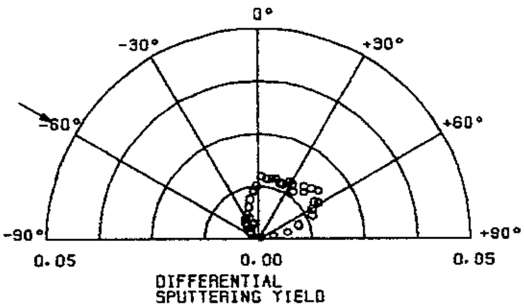
H3 ⇒ NI

INCIDENT ANGLE	60°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	NI

ION	H	1	1.01
TARGET	NI	28	58.7

ENERGY (EV)	1.30×10^{3}
EPSILON	5.24×10^{-1}
GAMMA	6.64×10^{-2}
Q	2.27×10^{-1}
EJECTION ANGLE EXP.	50.0°
CAL.	56.4°

REFERENCE 79.2



INFORMATION

79 2 15

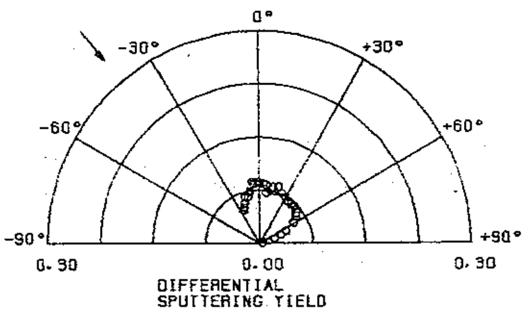
HE ⇒ NI

INCIDENT ANGLE	40°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	NI

ION	HE	2	4.00
TARGET	NI	28	58.7

ENERGY (EV)	4.00×10^{3}
EPSILON	7.47×10^{-1}
GAMMA	2.39×10^{-1}
Q	6.81×10^{-2}
EJECTION ANGLE EXP.	55.0°
CAL.	60.2°

REFERENCE 79.2



INFORMATION

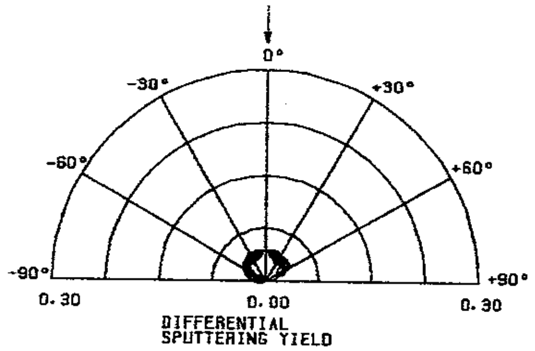
79 2 16

HE ⇒ NI

INCIDENT ANGLE	0°	ENERGY (EV)	4.00 X10^{3}
TARGET	POLY	EPSILON	7.47 X10^{-1}
ENVIRONMENT	UHV	GAMMA	2.39 X10^{-1}
SPUTTERED ATOM (S)	NI	Q	6.81 X10^{-2}
		COS^{n} N	7.20 X10^{-1}

ION	HE	2	4.00
TARGET	NI	28	58.7

REFERENCE 79.2



INFORMATION

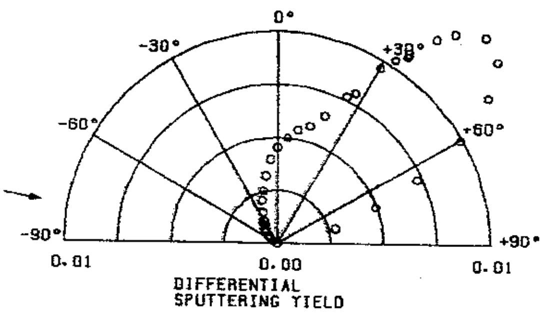
79 2 17

H2 ⇒ W

INCIDENT ANGLE	80°	ENERGY (EV)	4.00 X10^{3}
TARGET	POLY	EPSILON	4.58 X10^{-1}
ENVIRONMENT	UHV	GAMMA	2.17 X10^{-3}
SPUTTERED ATOM (S)	W	Q	3.20 X10^{-1}
		EJECTION ANGLE EXP.	45.0°
		CAL.	39.4°

ION	H	1	1.01
TARGET	W	74	184

REFERENCE 79.2



INFORMATION

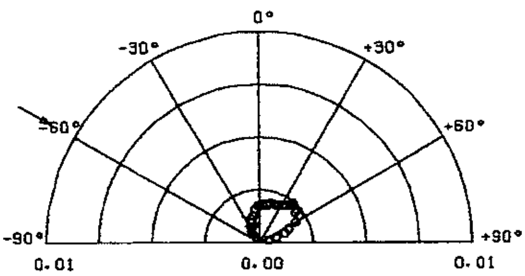
79 2 18

H2 ⇒ W

INCIDENT ANGLE	60°	ENERGY (EV)	4.00×10^{3}
TARGET	POLY	EPSILON	4.58×10^{-1}
ENVIRONMENT	UHV	GAMMA	2.17×10^{-2}
SPUTTERED ATOM (S)	W	Q	3.20×10^{-1}
		EJECTION ANGLE EXP.	45.0°
		CAL.	75.3°

ION	H	1	1.01
TARGET	W	74	184

REFERENCE 79.2



DIFFERENTIAL SPUTTERING YIELD

INFORMATION

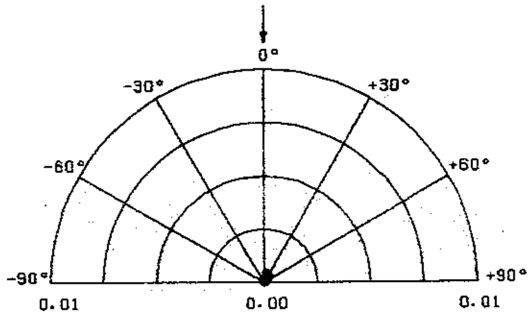
79 2 18

H2 ⇒ W

INCIDENT ANGLE	0°	ENERGY (EV)	4.00×10^{3}
TARGET	POLY	EPSILON	4.58×10^{-1}
ENVIRONMENT	UHV	GAMMA	2.17×10^{-2}
SPUTTERED ATOM (S)	W	Q	3.20×10^{-1}
		$\cos^{N}$ N	7.30×10^{-1}

ION	H	1	1.01
TARGET	W	74	184

REFERENCE 79.2



DIFFERENTIAL SPUTTERING YIELD

INFORMATION

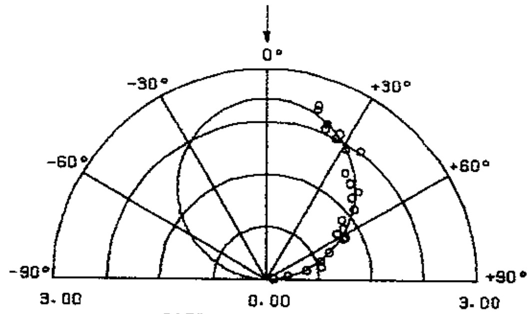
79 2 20

$H_2 \Rightarrow$ TA-C

INCIDENT ANGLE	0 °	ENERGY (EV)	4.00×10^{3}
TARGET	POLY	EPSILON	4.66×10^{-1}
ENVIRONMENT	UHV	GAMMA	2.20×10^{-2}
SPUTTERED ATOM (S)	TA	Q	3.03×10^{-1}
		COS * N	1.05

ION	H	1	1.01	REFERENCE	79.2
TARGET	TA	73	181		
	C	6	12.0		

NORMALIZED
TA



DIFFERENTIAL
SPUTTERING YIELD
(ARB. UNITS)

INFORMATION

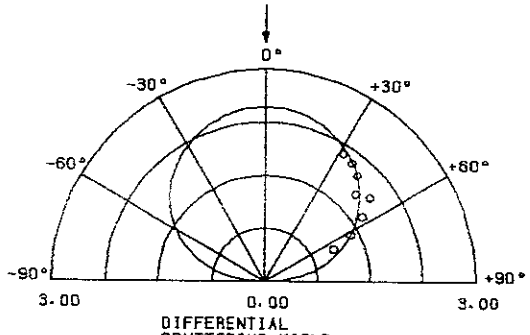
79 2 21

$H_2 \Rightarrow$ TA-C

INCIDENT ANGLE	0 °	ENERGY (EV)	4.00×10^{3}
TARGET	POLY	EPSILON	1.09×10^{1}
ENVIRONMENT	UHV	GAMMA	2.20×10^{-2}
SPUTTERED ATOM (S)	C	Q	8.03×10^{-2}
		COS * N	7.70×10^{-1}

ION	H	1	1.01	REFERENCE	79.2
TARGET	TA	73	181		
	C	6	12.0		

NORMALIZED
C



DIFFERENTIAL
SPUTTERING YIELD
(ARB. UNITS)

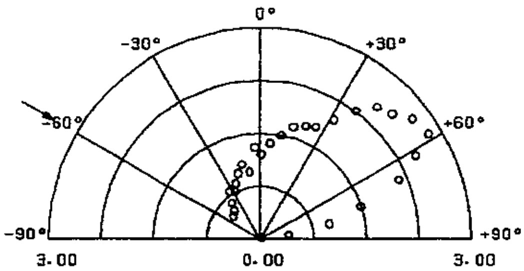
INFORMATION

79 2 22

H2 ⇒ TA-C

INCIDENT ANGLE	60°	ENERGY (EV)	4.00×10^{3}
TARGET	POLY	EPSILON	4.66×10^{-1}
ENVIRONMENT	UHV	GAMMA	2.20×10^{-2}
SPUTTERED ATOM (S)	TA	Q	3.03×10^{-1}
		EJECTION ANGLE EXP.	58.0°
		CAL.	70.5°
ION	H 1 1.01	REFERENCE	79.2
TARGET	TA 73 181 C 6 12.0		

NORMALIZED
TA



DIFFERENTIAL
SPUTTERING YIELD
(ARB. UNITS)

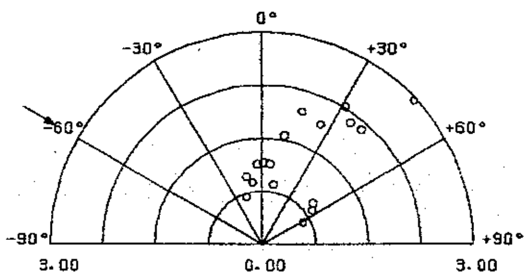
INFORMATION

79 2 23

H2 ⇒ TA-C

INCIDENT ANGLE	60°	ENERGY (EV)	4.00×10^{3}
TARGET	POLY	EPSILON	1.09×10^{1}
ENVIRONMENT	UHV	GAMMA	2.20×10^{-2}
SPUTTERED ATOM (S)	C	Q	8.83×10^{-2}
		EJECTION ANGLE EXP.	46.6°
		CAL.	38.3°
ION	H 1 1.01	REFERENCE	79.2
TARGET	TA 73 181 C 6 12.0		

NORMALIZED
C



DIFFERENTIAL
SPUTTERING YIELD
(ARB. UNITS)

INFORMATION

79 2 24

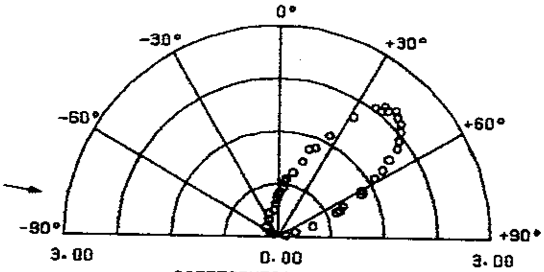
H2 ⇒ TA-C

INCIDENT ANGLE	80°		ENERGY (EV)	4.00×10^{3}	
TARGET	POLY		EPSILON	4.66×10^{-1}	
ENVIRONMENT	UHV		GAMMA	2.20×10^{-2}	
SPUTTERED ATOM(S)	TA		Q	3.03×10^{-1}	
			EJECTION ANGLE		
			EXP.	42.4°	
			CAL.	37.6°	

ION	H	1	1.01
TARGET	TA	73	181
	C	6	12.0

REFERENCE 79.2

NORMALIZED
TA



DIFFERENTIAL
SPUTTERING YIELD
(ARB. UNITS)

INFORMATION

79 2 25

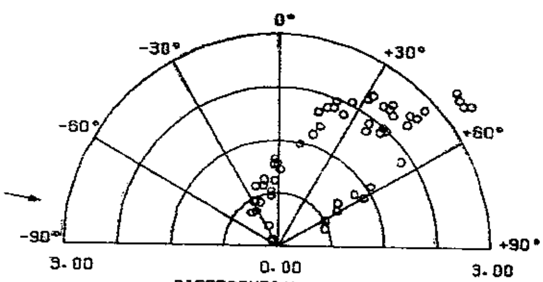
H2 ⇒ TA-C

INCIDENT ANGLE	80°	ENERGY (EV)	4.00×10^{3}
TARGET	POLY	EPSILON	1.09×10^{1}
ENVIRONMENT	UHV	GAMMA	2.20×10^{-2}
SPUTTERED ATOM(S)	C	Q	8.03×10^{-2}
		EJECTION ANGLE	
		EXP.	53.7°
		CAL.	16.9°

ION	H	1	1.01
TARGET	TA	73	181
	C	6	12.0

REFERENCE 79.2

NORMALIZED
C



DIFFERENTIAL
SPUTTERING YIELD
(ARB. UNITS)

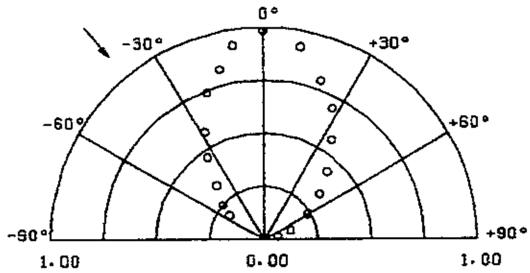
INFORMATION

79 8 1

NEARKR ⇒ AG

INCIDENT ANGLE	40°		ENERGY (EV)	1.00×10^4
TARGET	POLY		REFERENCE	79 . 8
ENVIRONMENT	UHV			
SPUTTERED ATOM (S)	AG			

ION	KR	36	83.8
	NE	10	20.2
TARGET	AG	47	108



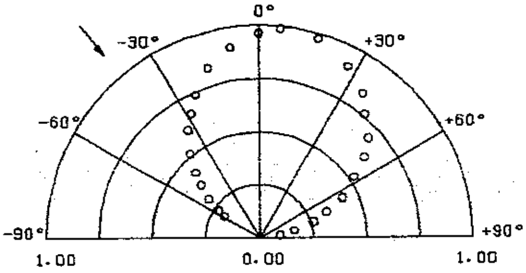
INFORMATION

79 8 2

NEARKR ⇒ NB

INCIDENT ANGLE	40°		ENERGY (EV)	1.00×10^4
TARGET	POLY		REFERENCE	79 . 8
ENVIRONMENT	UHV			
SPUTTERED ATOM (S)	NB			

ION	KR	36	83.8
	NE	10	20.2
TARGET	NB	41	92.9



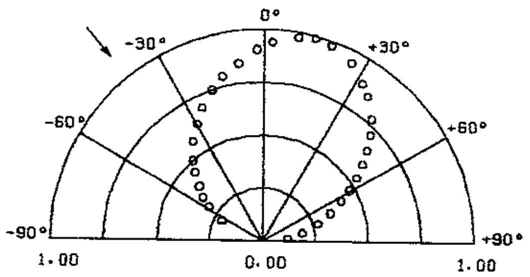
INFORMATION

79 8 9

NEARKR ⇒ AL

INCIDENT ANGLE	40°	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	REFERENCE	79.8
ENVIRONMENT	UHV		
SPUTTERED ATOM(S)	AL		

ION	KR	36	83.8
	NE	10	20.2
TARGET	AL	13	27.0



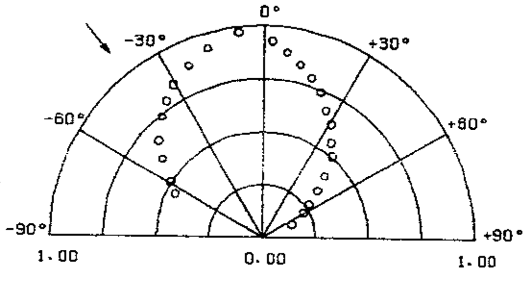
INFORMATION

79 8 4

NEARKR ⇒ PB

INCIDENT ANGLE	40°	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	REFERENCE	79.8
ENVIRONMENT	UHV		
SPUTTERED ATOM(S)	PB		

ION	KR	36	83.8
	NE	10	20.2
TARGET	PB	82	207



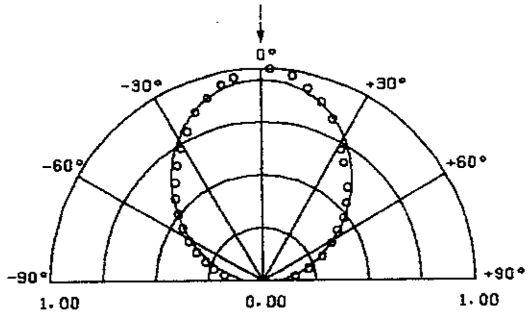
INFORMATION

79 8 5

NEARKR ⇒ AG

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	AG
ENERGY (EV)	1.00×10^4
REFERENCE	79 . 8

ION	KR	36	83.8
	NE	10	20.2
TARGET	AG	47	108



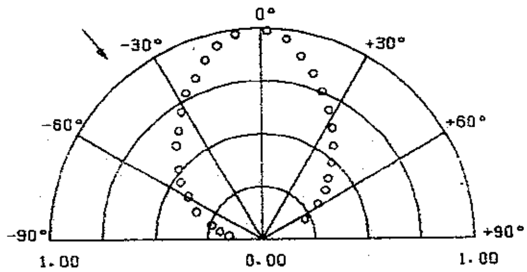
INFORMATION

79 8 6

NEARKR ⇒ AG

INCIDENT ANGLE	40°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	AG
ENERGY (EV)	1.00×10^4
REFERENCE	79 . 8

ION	KR	36	83.8
	NE	10	20.2
TARGET	AG	47	108



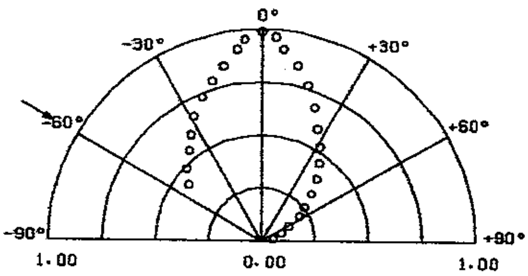
INFORMATION

79 8 7

NEARKR ⇒ AG

INCIDENT ANGLE	60°	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	REFERENCE	79.8
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	AG		

ION	KR	36	83.8
	NE	10	20.2
TARGET	AG	47	108



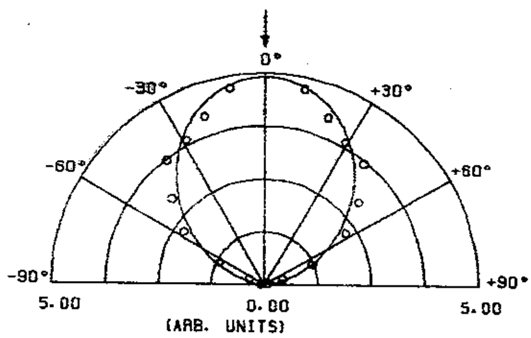
INFORMATION

80 1 1

AR ⇒ SI

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	EPSILON	5.07×10^{-2}
ENVIRONMENT	UHV	GAMMA	9.70×10^{-1}
SPUTTERED ATOM (S)	SI	Q	3.99×10^{-2}
		COS* N	1.54
		REFERENCE	80.1

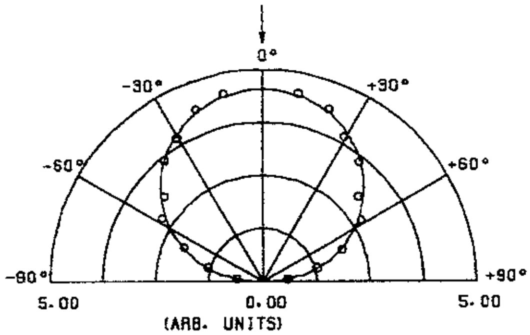
ION	AR	18	39.9
TARGET	SI	14	28.1



INFORMATION

80 1 2
AR ⇒ SI

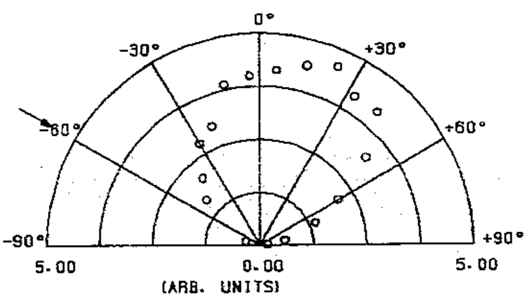
INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	EPSILON	1.69×10^{-1}
ENVIRONMENT	UHV	GAMMA	9.70×10^{-1}
SPUTTERED ATOM (S)	SI	Q	2.19×10^{-2}
		COS^{N} N	8.70×10^{-1}
ION	AR 18 39.9	REFERENCE	80.1
TARGET	SI 14 28.1		



INFORMATION

80 1 3
AR ⇒ SI

INCIDENT ANGLE	60°	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	EPSILON	5.07×10^{-2}
ENVIRONMENT	UHV	GAMMA	9.70×10^{-1}
SPUTTERED ATOM (S)	SI	Q	3.99×10^{-2}
		EJECTION ANGLE EXP.	20.0°
		CAL.	34.0°
ION	AR 18 39.9	REFERENCE	80.1
TARGET	SI 14 28.1		



60

INFORMATION

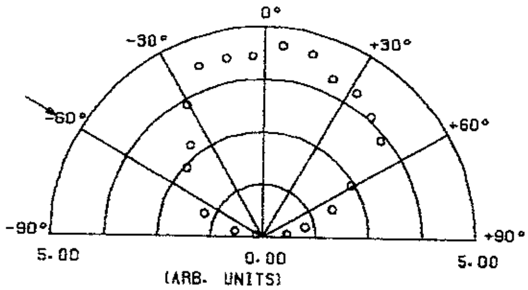
80 1 4

AR ⇒ SI

INCIDENT ANGLE	60°		ENERGY (EV)	1.00×10^{4}
TARGET	POLY		EPSILON	1.69×10^{-1}
ENVIRONMENT	UHV		GAMMA	9.70×10^{-1}
SPUTTERED ATOM (S)	SI		Q	2.19×10^{-2}
			EJECTION ANGLE EXP.	15.0°
			CAL.	32.2°

ION	AR	18	39.9
TARGET	SI	14	28.1

REFERENCE 80.1



INFORMATION

81 1 1

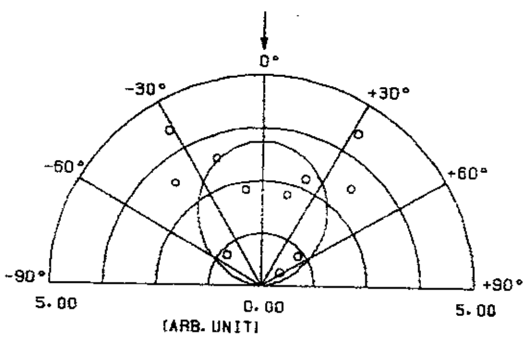
AR ⇒ AU

INCIDENT ANGLE	0°		ENERGY (EV)	1.00×10^{3}
TARGET	POLY		EPSILON	4.27×10^{-3}
ENVIRONMENT	HV		GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU		Q	8.24×10^{-2}
			COS* N	1.36

ION	AR	18	39.9
TARGET	AU	79	197

REFERENCE 81.1

TEXTURE



INFORMATION

81 1 2

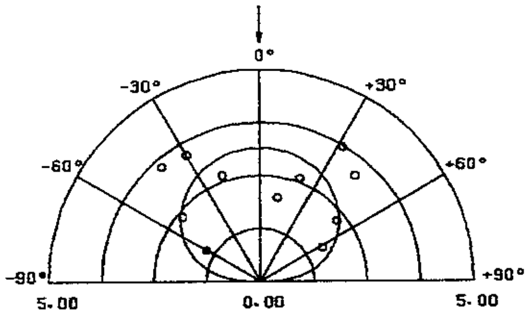
AR ⇒ AL

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	1.80×10^{-2}
ENVIRONMENT	HV	GAMMA	9.62×10^{-1}
SPUTTERED ATOM (S)	AL	Q	5.93×10^{-2}
		$\cos^{N}$ N	6.00×10^{-1}

ION	AR	18	39.9
TARGET	AL	13	27.0

REFERENCE 81.1

TEXTURE



INFORMATION

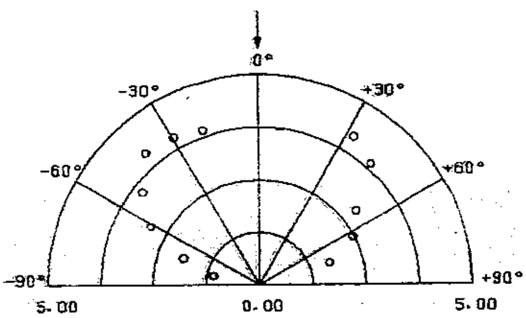
81 1 3

AR ⇒ NI-FE

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY		
ENVIRONMENT	HV	REFERENCE	81.1
SPUTTERED ATOM (S)	NI, FE		

ION	AR	18	39.9
TARGET	NI	28	58.7
	FE	26	55.8

TEXTURE



INFORMATION

81 1 4

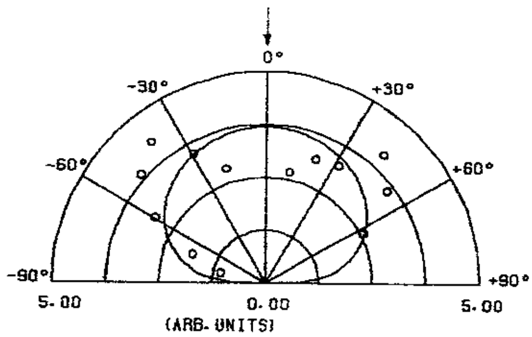
AR ⇒ AL

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	1.80×10^{-2}
ENVIRONMENT	HV	GAMMA	9.62×10^{-1}
SPUTTERED ATOM (S)	AL	Q	5.93×10^{-2}
		COS * N	4.40×10^{-1}

ION	AR	18	39.9
TARGET	AL	13	27.0

REFERENCE 81 . 1

TEXTURE



INFORMATION

81 1 5

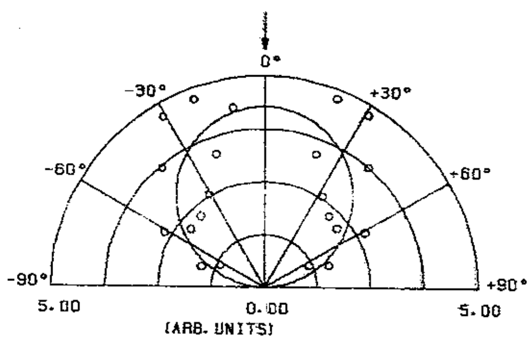
AR ⇒ AU

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	4.27×10^{-3}
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	8.24×10^{-2}
		COS * N	1.08

ION	AR	18	39.9
TARGET	AU	79	197

REFERENCE 81 . 1

TEXTURE



INFORMATION

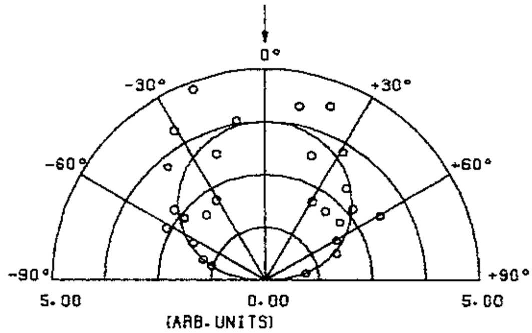
81 1 6

AR ⇒ PT

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	4.33×10^{-3}
ENVIRONMENT	HV	GAMMA	5.64×10^{-1}
SPUTTERED ATOM (S)	PT	Q	1.02×10^{-1}
		COS^{N} N	7.90×10^{-1}

ION	AR	18	39.9	REFERENCE	81.1
TARGET	PT	78	195		

TEXTURE



INFORMATION

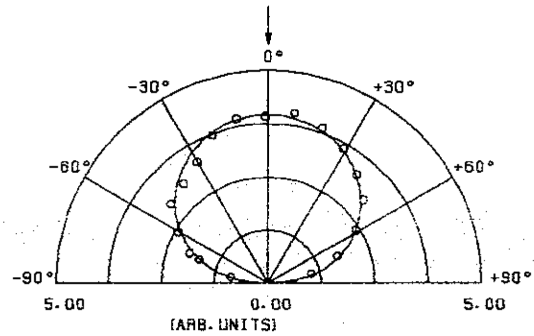
81 1 7

AR ⇒ PT

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	4.33×10^{-3}
ENVIRONMENT	HV	GAMMA	5.64×10^{-1}
SPUTTERED ATOM (S)	PT	Q	1.02×10^{-1}
		COS^{N} N	7.60×10^{-1}

ION	AR	18	39.9	REFERENCE	81.1
TARGET	PT	78	195		

TEXTURE



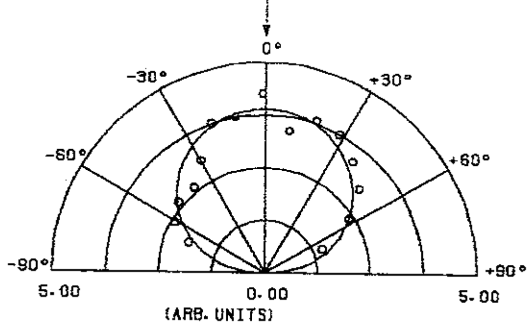
INFORMATION

81 1 8

AR ⇒ TA

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	4.64×10^{-3}
ENVIRONMENT	HV	GAMMA	5.93×10^{-1}
SPUTTERED ATOM (S)	TA	Q	1.17×10^{-1}
		COS* N	8.10×10^{-1}
ION	AR 18 39.9	REFERENCE	81.1
TARGET	TA 73 181		

TEXTURE



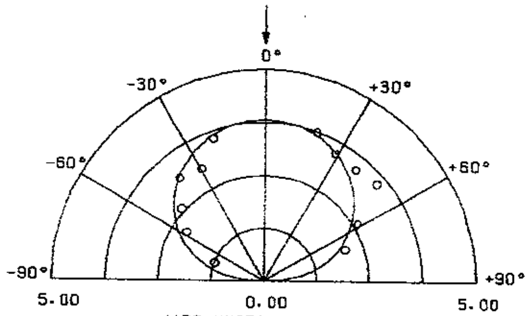
INFORMATION

81 1 9

AR ⇒ SI

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	1.69×10^{-2}
ENVIRONMENT	HV	GAMMA	9.70×10^{-1}
SPUTTERED ATOM (S)	SI	Q	6.92×10^{-2}
		COS* N	7.20×10^{-1}
ION	AR 18 39.9	REFERENCE	81.1
TARGET	SI 14 28.1		

TEXTURE



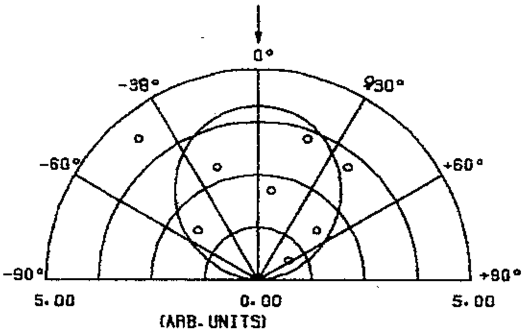
INFORMATION

81 1 10

AR ⇒ AU

INCIDENT ANGLE	0 °			ENERGY (EV)	5.00×10^{2}
TARGET	POLY			EPSILON	2.14×10^{-2}
ENVIRONMENT	HV			GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU			Q	1.17×10^{-1}
				COS^{N} N	1.19
ION	AR	18	39.9	REFERENCE	81.1
TARGET	AU	79	197		

TEXTURE



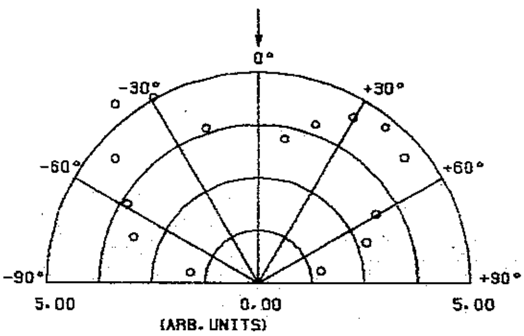
INFORMATION

81 1 12

AR ⇒ NI-FE

INCIDENT ANGLE	0 °			ENERGY (EV)	5.00×10^{2}
TARGET	POLY			REFERENCE	81.1
ENVIRONMENT	HV				
SPUTTERED ATOM (S)	NI.FE				
ION	AR	18	39.9		
TARGET	NI	28	58.7		
	FE	26	55.8		

TEXTURE



INFORMATION

81 1 14

AR ⇒ SI

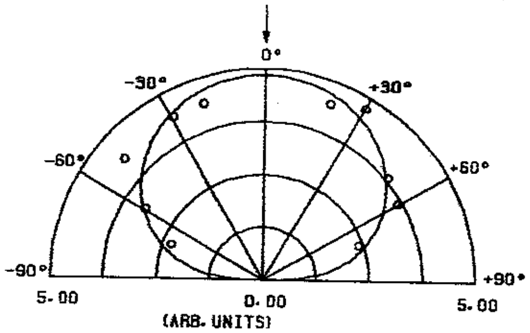
INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	HV
SPUTTERED ATOM(S)	SI

ION	AR	18	39.9
TARGET	SI	14	28.1

ENERGY (EV)	5.00×10^{2}
EPSILON	8.45×10^{-3}
GAMMA	9.70×10^{-1}
Q	9.78×10^{-2}
COS^{N} N	5.80×10^{-1}

REFERENCE 81.1

TEXTURE



INFORMATION

81 1 18

AR ⇒ AU

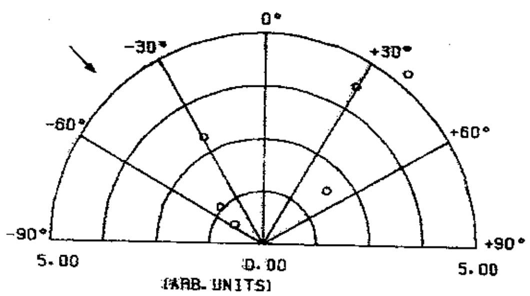
INCIDENT ANGLE	45°
TARGET	POLY
ENVIRONMENT	HV
SPUTTERED ATOM(S)	AU

ION	AR	18	39.9
TARGET	AU	79	197

ENERGY (EV)	1.00×10^{3}
EPSILON	4.27×10^{-3}
GAMMA	5.61×10^{-1}
Q	8.24×10^{-2}
EJECTION ANGLE EXP.	49.0°
CAL.	56.1°

REFERENCE 81.1

TEXTURE



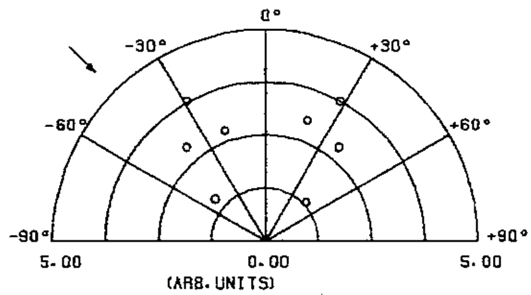
INFORMATION

81 1 17

AR ⇒ AU

INCIDENT ANGLE	45°		ENERGY (EV)	1.00×10^{3}
TARGET	POLY		EPSILON	4.27×10^{-3}
ENVIRONMENT	HV		GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU		Q	8.24×10^{-2}
			EJECTION ANGLE EXP.	46.5°
ION	AR 18	39.9	CAL.	56.1°
TARGET	AU 79	197	REFERENCE	81 - 1

TEXTURE



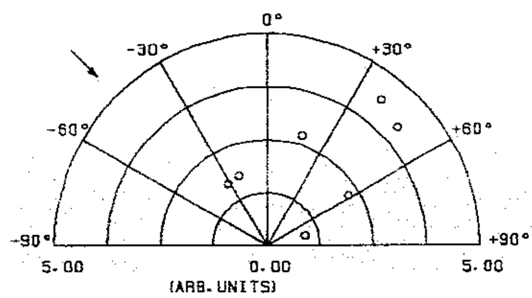
INFORMATION

81 1 18

AR ⇒ AL

INCIDENT ANGLE	45°		ENERGY (EV)	1.00×10^{3}
TARGET	POLY		EPSILON	1.80×10^{-2}
ENVIRONMENT	HV		GAMMA	9.62×10^{-1}
SPUTTERED ATOM (S)	AL		Q	5.93×10^{-2}
			EJECTION ANGLE EXP.	47.8°
ION	AR 18	39.9	CAL.	52.7°
TARGET	AL 13	27.0	REFERENCE	81 - 1

TEXTURE



INFORMATION

81 1 19

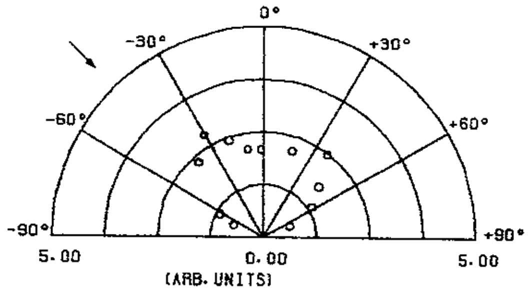
AR ⇒ AL

INCIDENT ANGLE	45°	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	1.80×10^{-2}
ENVIRONMENT	HV	GAMMA	9.62×10^{-1}
SPUTTERED ATOM (S)	AL	Q	5.93×10^{-2}
		EJECTION ANGLE EXP.	47.2°
		CAL.	52.7°

ION	AR	18	39.9
TARGET	AL	13	27.0

REFERENCE 81.1

TEXTURE



INFORMATION

81 1 20

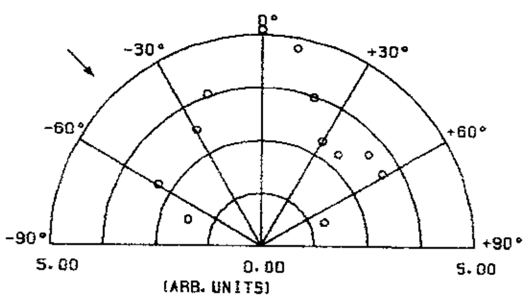
AR ⇒ AU

INCIDENT ANGLE	45°	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	4.27×10^{-3}
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	8.24×10^{-2}
		EJECTION ANGLE EXP.	49.3°
		CAL.	56.1°

ION	AR	18	39.9
TARGET	AU	79	197

REFERENCE 81.1

TEXTURE



INFORMATION

81 1 21

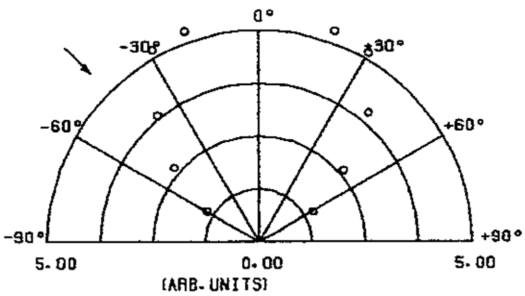
AR ⇒ AU

INCIDENT ANGLE	45°	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	4.27×10^{-3}
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	8.24×10^{-2}
		EJECTION ANGLE EXP.	49.7°
		CAL.	56.1°

ION	AR	18	39.9
TARGET	AU	79	197

REFERENCE 81.1

TEXTURE



INFORMATION

81 1 22

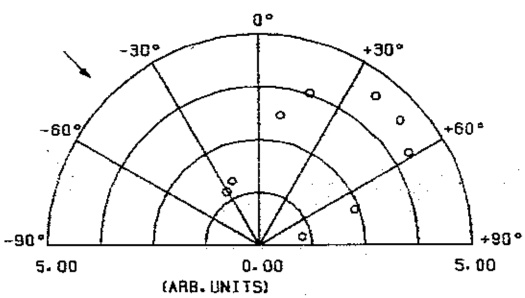
AR ⇒ SI

INCIDENT ANGLE	45°	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	1.69×10^{-2}
ENVIRONMENT	HV	GAMMA	9.70×10^{-1}
SPUTTERED ATOM (S)	SI	Q	6.92×10^{-2}
		EJECTION ANGLE EXP.	48.5°
		CAL.	54.1°

ION	AR	18	39.9
TARGET	SI	14	28.1

REFERENCE 81.1

TEXTURE



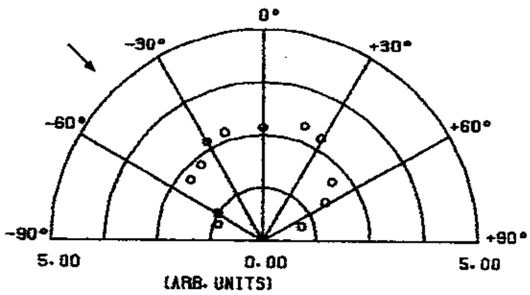
INFORMATION

81 1 29

AR ⇒ SI

INCIDENT ANGLE	45°		ENERGY (EV)	1.00×10^{3}
TARGET	POLY		EPSILON	1.69×10^{-2}
ENVIRONMENT	HV		GAMMA	9.70×10^{-1}
SPUTTERED ATOM(S)	SI		Q	6.92×10^{-2}
			EJECTION ANGLE EXP.	49.0°
ION	AR 18	39.9	CAL.	54.1°
TARGET	SI 14	28.1	REFERENCE	81.1

TEXTURE

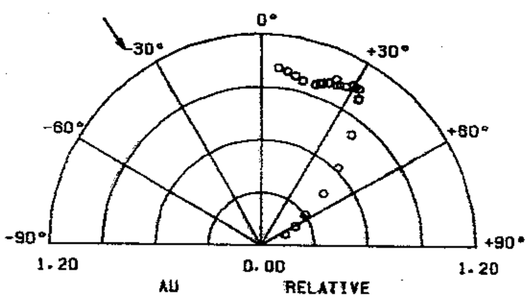


INFORMATION

81 2 1

AR ⇒ AG-AU

INCIDENT ANGLE	35°		ENERGY (EV)	8.00×10^{4}
TARGET	POLY		EPSILON	3.42×10^{-1}
ENVIRONMENT	UHV		GAMMA	7.89×10^{-1}
SPUTTERED ATOM(S)	AU		Q	9.22×10^{-3}
			EJECTION ANGLE EXP.	55.1°
ION	AR 18	39.9	CAL.	56.4°
TARGET	AG 47 AU 79	108 197	REFERENCE	81.2

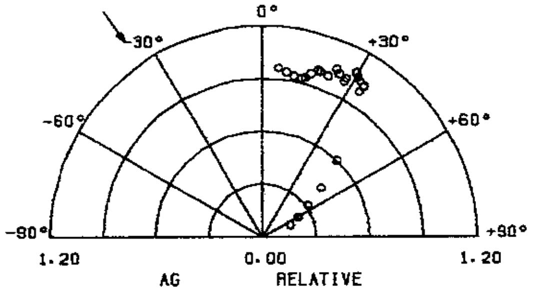


INFORMATION

81 2 2

AR ⇒ AG–AU

INCIDENT ANGLE	35°			ENERGY (EV)	8.00×10^{4}
TARGET	POLY			EPSILON	5.68×10^{-1}
ENVIRONMENT	UHV			GAMMA	7.89×10^{-1}
SPUTTERED ATOM (S)	AG			Q	6.84×10^{-3}
				EJECTION ANGLE EXP.	55.2°
ION	AR	18	39.9	CAL.	56.0°
TARGET	AG	47	108		
	AU	79	197	REFERENCE	81.2

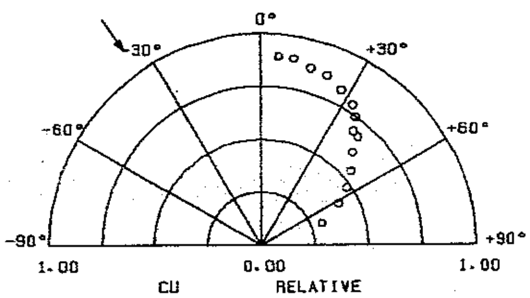


INFORMATION

81 2 3

AR ⇒ CU–PT

INCIDENT ANGLE	35°			ENERGY (EV)	2.00×10^{4}
TARGET	POLY			EPSILON	2.14×10^{-1}
ENVIRONMENT	UHV			GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU			Q	1.36×10^{-2}
				EJECTION ANGLE EXP.	56.1°
ION	AR	18	39.9	CAL.	57.1°
TARGET	CU	29	63.5		
	PT	78	195	REFERENCE	81.2



INFORMATION

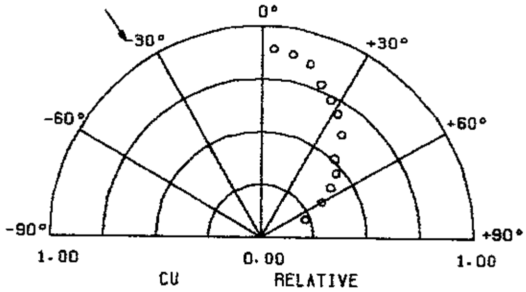
81 2 4

AR ⇒ CU-PT

INCIDENT ANGLE	35°		ENERGY (EV)	8.00×10^{4}
TARGET	POLY		EPSILON	8.56×10^{-1}
ENVIRONMENT	UHV		GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU		Q	6.78×10^{-3}
			EJECTION ANGLE EXP.	60.0°
			CAL.	56.0°

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

REFERENCE 81 . 2



INFORMATION

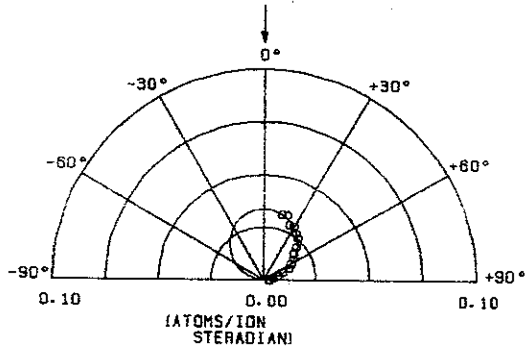
81 3 1

H ⇒ NI

INCIDENT ANGLE	0 °		ENERGY (EV)	4.50×10^{2}
TARGET	POLY		EPSILON	1.82×10^{-1}
ENVIRONMENT	UHV		GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI		Q	3.85×10^{-1}
			COS^{N} N	1.15

ION	H	1	1.01
TARGET	NI	28	58.7

REFERENCE 81 . 3

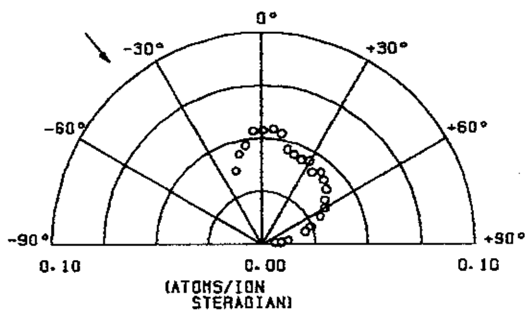


INFORMATION

81 3 2

H ⇒ NI

INCIDENT ANGLE	40°		ENERGY (EV)	4.50×10^{2}
TARGET	POLY		EPSILON	1.82×10^{-1}
ENVIRONMENT	UHV		GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI		Q	3.85×10^{-1}
			EJECTION ANGLE EXP.	45.9°
			CAL.	90.0°
ION	H 1	1.01	REFERENCE	81 . 3
TARGET	NI 28	58.7		

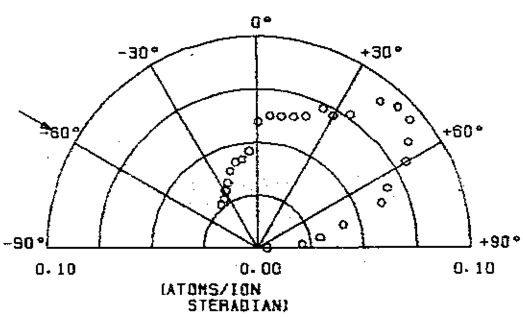


INFORMATION

81 3 3

H ⇒ NI

INCIDENT ANGLE	60°		ENERGY (EV)	4.50×10^{2}
TARGET	POLY		EPSILON	1.82×10^{-1}
ENVIRONMENT	UHV		GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI		Q	3.85×10^{-1}
			EJECTION ANGLE EXP.	45.0°
			CAL.	90.0°
ION	H 1	1.01	REFERENCE	81 . 3
TARGET	NI 28	58.7		



INFORMATION

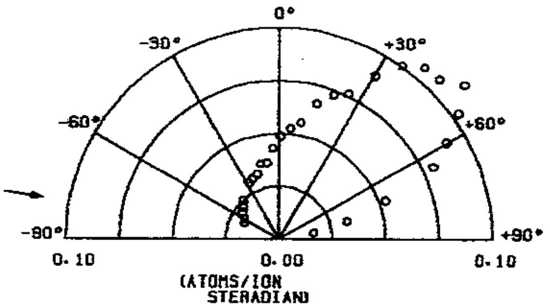
81 9 4

H ⇒ NI

INCIDENT ANGLE	80°	ENERGY (EV)	4.50×10^{2}
TARGET	POLY	EPSILON	1.82×10^{-1}
ENVIRONMENT	UHV	GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI	Q	3.85×10^{-1}
		EJECTION ANGLE EXP.	49.3°
		CAL.	46.6°

ION	H	1	1.01
TARGET	NI	28	58.7

REFERENCE 81.3



INFORMATION

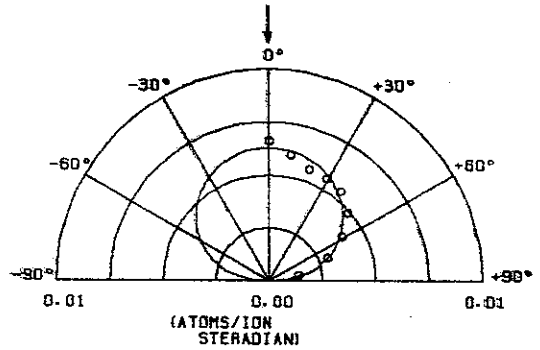
81 3 5

H ⇒ NI

INCIDENT ANGLE	0°	ENERGY (EV)	4.50×10^{2}
TARGET	POLY	EPSILON	1.82×10^{-1}
ENVIRONMENT	UHV	GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI	Q	3.85×10^{-1}
		$\cos^{N}$ N	7.50×10^{-1}

ION	H	1	1.01
TARGET	NI	28	58.7

REFERENCE 81.3



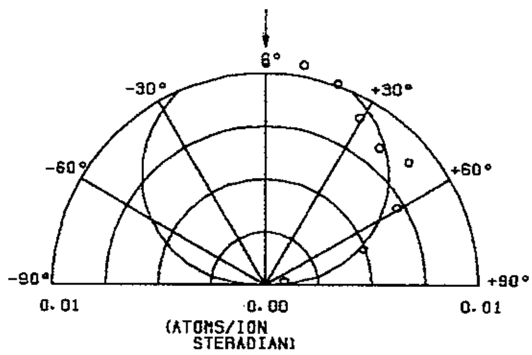
INFORMATION

81 9 6

H ⇒ NI

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	4.03×10^{-1}
ENVIRONMENT	UHV	GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI	Q	2.59×10^{-1}
		COS^{N} N	8.10×10^{-1}

ION	H	1	1.01	REFERENCE	81.3
TARGET	NI	28	58.7		



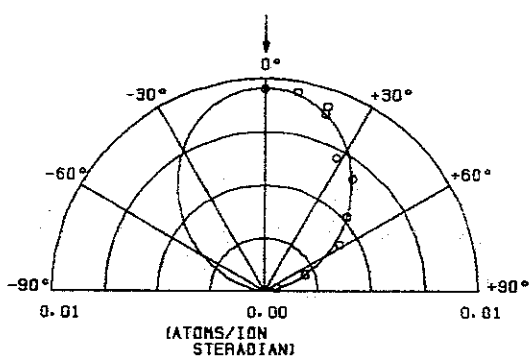
INFORMATION

81 3 7

H ⇒ NI

INCIDENT ANGLE	0 °	ENERGY (EV)	4.00×10^{3}
TARGET	POLY	EPSILON	1.61
ENVIRONMENT	UHV	GAMMA	6.64×10^{-2}
SPUTTERED ATOM (S)	NI	Q	1.29×10^{-1}
		COS^{N} N	1.54

ION	H	1	1.01	REFERENCE	81.3
TARGET	NI	28	58.7		



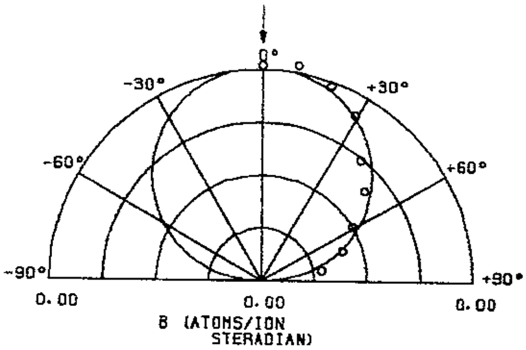
INFORMATION

81 3 8

D ⇒ NB-B2

INCIDENT ANGLE	0 °	ENERGY (EV)	4.00×10^{2}
TARGET	POLY	EPSILON	1.25
ENVIRONMENT	UHV	GAMMA	8.25×10^{-2}
SPUTTERED ATOM (S)	B	Q	1.65×10^{-1}
		COS^{N} N	9.20×10^{-1}

ION	H	1	2.00	REFERENCE	81.3
TARGET	NB	41	92.9		
	B	5	10.8		



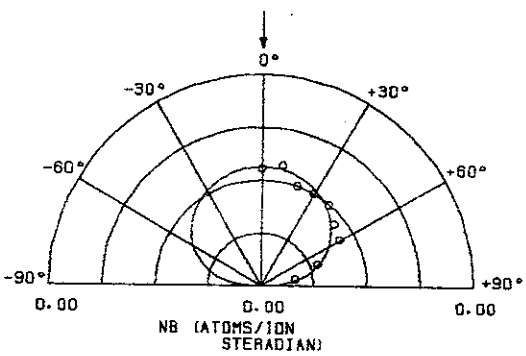
INFORMATION

81 3 9

D ⇒ NB-B2

INCIDENT ANGLE	0 °	ENERGY (EV)	4.00×10^{2}
TARGET	POLY	EPSILON	9.77×10^{-2}
ENVIRONMENT	UHV	GAMMA	8.25×10^{-2}
SPUTTERED ATOM (S)	NB	Q	4.79×10^{-1}
		COS^{N} N	6.10×10^{-1}

ION	H	1	2.00	REFERENCE	81.3
TARGET	NB	41	92.9		
	B	5	10.8		



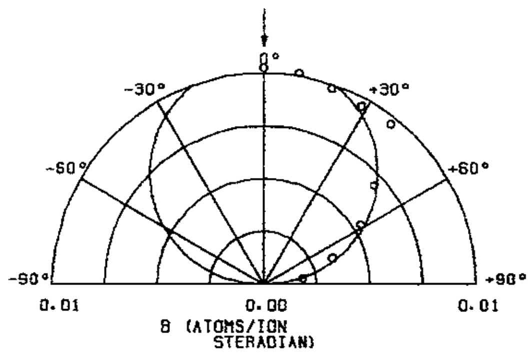
INFORMATION

81 3 10

D ⇒ NB-B2

INCIDENT ANGLE	0 °	ENERGY (EV)	2.00×10^{3}
TARGET	POLY	EPSILON	6.26
ENVIRONMENT	UHV	GAMMA	8.25×10^{-2}
SPUTTERED ATOM (S)	B	Q	7.40×10^{-2}
		COS^{N} N	9.70×10^{-1}

ION	H	1	2.00	REFERENCE	81.3
TARGET	NB B	41 5	92.9 10.8		



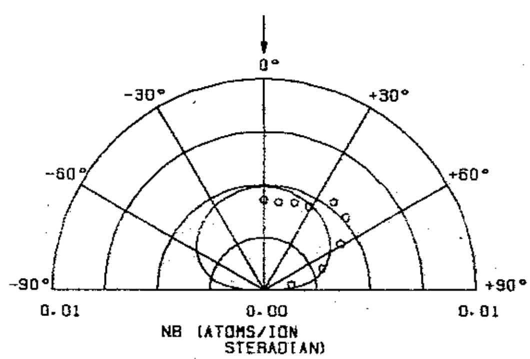
INFORMATION

81 3 11

D ⇒ NB-B2

INCIDENT ANGLE	0 °	ENERGY (EV)	2.00×10^{3}
TARGET	POLY	EPSILON	4.89×10^{-1}
ENVIRONMENT	UHV	GAMMA	8.25×10^{-2}
SPUTTERED ATOM (S)	NB	Q	2.14×10^{-1}
		COS^{N} N	4.40×10^{-1}

ION	H	1	2.00	REFERENCE	81.3
TARGET	NB B	41 5	92.9 10.8		



78

INFORMATION

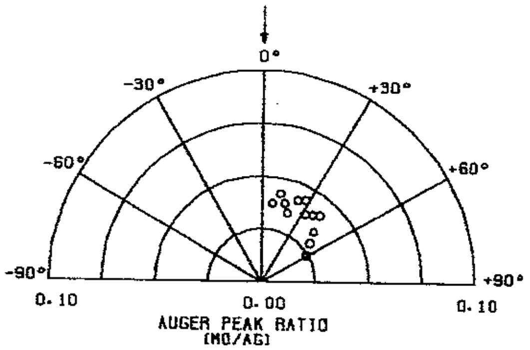
81 10 1

HE ⇒ MO-AG

INCIDENT ANGLE	0 °
TARGET	ALLOY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	MO / AG

ION	HE	2	4.00
TARGET	MO	42	95.9
	AG	47	108

ENERGY (EV)	2.00×10^{3}
REFERENCE	81.10



INFORMATION

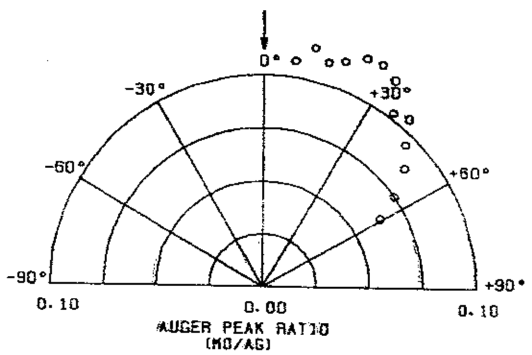
81 10 2

HE ⇒ MO-AG

INCIDENT ANGLE	0 °
TARGET	ALLOY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	MO / AG

ION	HE	2	4.00
TARGET	MO	42	95.9
	AG	47	108

ENERGY (EV)	2.00×10^{3}
REFERENCE	81.10

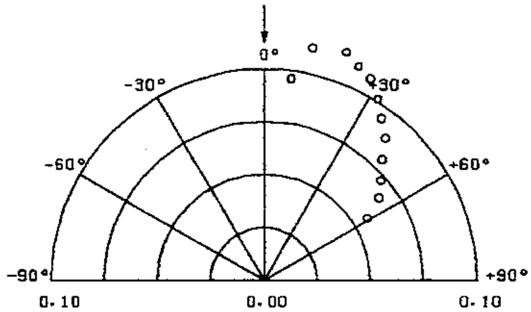


INFORMATION

81 10 9

HE ⇒ MO-AG

INCIDENT ANGLE	0 °		ENERGY (EV)	2.00×10^{3}
TARGET	ALLOY		REFERENCE	81 - 10
ENVIRONMENT	UHV			
SPUTTERED ATOM (S)	MO / AG			
ION	HE	2	4.00	
TARGET	MO	42	95.9	
	AG	47	108	



AUGER PEAK RATIO (MO/AG)

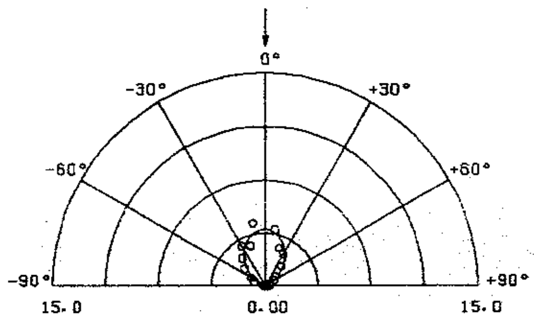
INFORMATION

81 12 1

AR ⇒ AU

INCIDENT ANGLE	0 °		ENERGY (EV)	5.00×10^{4}
TARGET	POLY		EPSILON	2.14×10^{-1}
ENVIRONMENT	HV		GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU		Q	1.17×10^{-2}
			COS^{N} N	2.27
ION	AR	18	39.9	
TARGET	AU	79	197	REFERENCE 81 - 12

TEMP. 300C



WEIGHT OF SPUTTERED ATOMS (A. U.)

INFORMATION

81 12 2

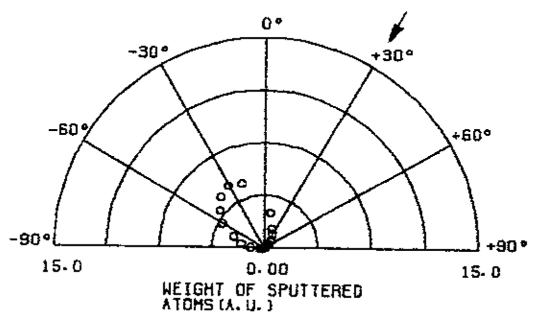
AR ⇒ AU

INCIDENT ANGLE	30°	ENERGY (EV)	5.00×10^{3}
TARGET	POLY	EPSILON	2.14×10^{-2}
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	3.69×10^{-2}
		EJECTION ANGLE EXP.	70.8°
		CAL.	67.1°

ION	AR	18	39.9
TARGET	AU	79	197

REFERENCE 81 . 12

TEMP. 300C



INFORMATION

81 12 3

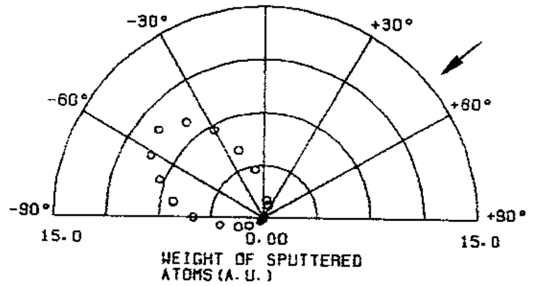
AR ⇒ AU

INCIDENT ANGLE	52°	ENERGY (EV)	5.00×10^{4}
TARGET	POLY	EPSILON	2.14×10^{-1}
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	1.17×10^{-2}
		EJECTION ANGLE EXP.	49.5°
		CAL.	39.3°

ION	AR	18	39.9
TARGET	AU	79	197

REFERENCE 81 . 12

TEMP. 300C



INFORMATION

81 12 4

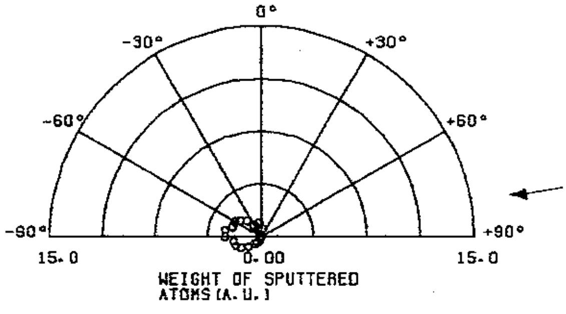
AR ⇒ AU

INCIDENT ANGLE	80°	ENERGY (EV)	5.00×10^{4}
TARGET	POLY	EPSILON	2.14×10^{-1}
ENVIRONMENT	HV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	1.17×10^{-2}
		EJECTION ANGLE EXP.	60.6°
		CAL.	11.0°

ION	AR	18	39.9
TARGET	AU	79	197

REFERENCE 81.12

TEMP. 300C



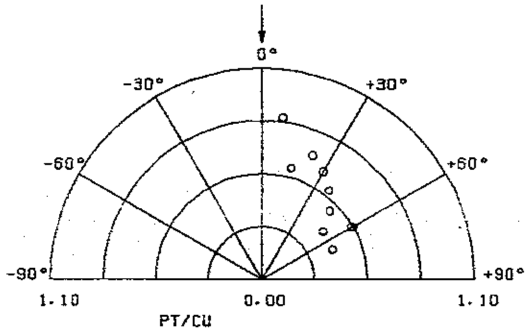
INFORMATION

82 1 1

AR ⇒ CU-PT

INCIDENT ANGLE	0°	ENERGY (EV)	5.00×10^{4}
TARGET	POLY	REFERENCE	82.1
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195



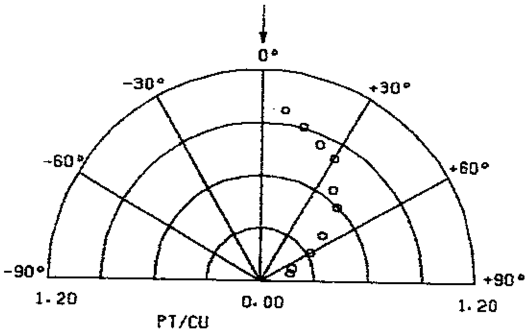
INFORMATION

82 1 2

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{4}
TARGET	POLY	REFERENCE	82.1
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	NI / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	NI	28	58.7



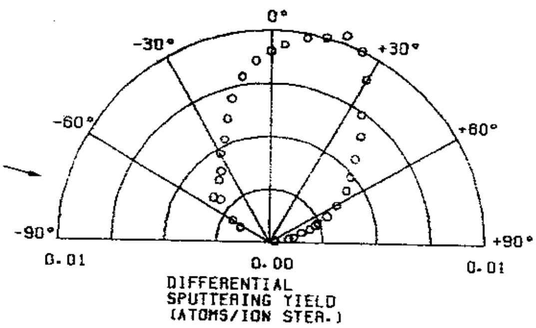
INFORMATION

82 2 1

D ⇒ MO

INCIDENT ANGLE	75°	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	EPSILON	2.37×10^{1}
ENVIRONMENT	UHV	GAMMA	8.00×10^{-2}
SPUTTERED ATOM (S)	MO	Q	2.92×10^{-2}
		EJECTION ANGLE EXP.	20.0°
		EJECTION ANGLE CAL.	17.6°
		REFERENCE	82.2

ION	H	1	2.00
TARGET	MO	42	95.9

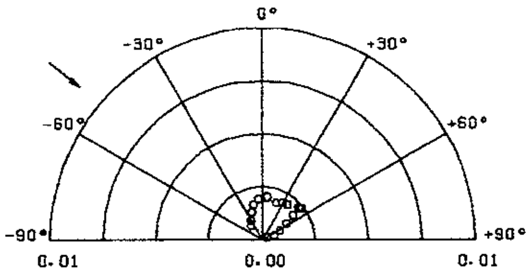


INFORMATION

82 2 2

D ⇒ MO

INCIDENT ANGLE	50°	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	EPSILON	2.37×10^{1}
ENVIRONMENT	UHV	GAMMA	8.00×10^{-2}
SPUTTERED ATOM (S)	MO	Q	2.92×10^{-2}
		EJECTION ANGLE	
		EXP.	50.0°
		CAL.	43.3°
ION	H 1 2.00	REFERENCE	82.2
TARGET	MO 42 95.9		



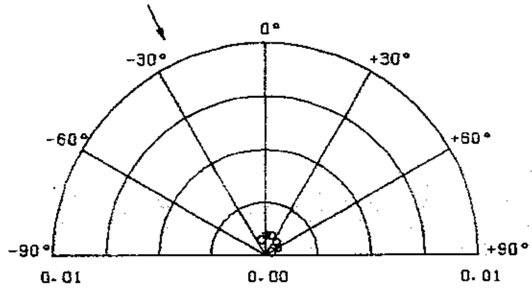
DIFFERENTIAL SPUTTERING YIELD (ATOMS/ION STER.)

INFORMATION

82 2 3

D ⇒ MO

INCIDENT ANGLE	25°	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	EPSILON	2.37×10^{1}
ENVIRONMENT	UHV	GAMMA	8.00×10^{-2}
SPUTTERED ATOM (S)	MO	Q	2.92×10^{-2}
		EJECTION ANGLE	
		EXP.	50.0°
		CAL.	71.8°
ION	H 1 2.00	REFERENCE	82.2
TARGET	MO 42 95.9		



DIFFERENTIAL SPUTTERING YIELD (ATOMS/ION STER.)

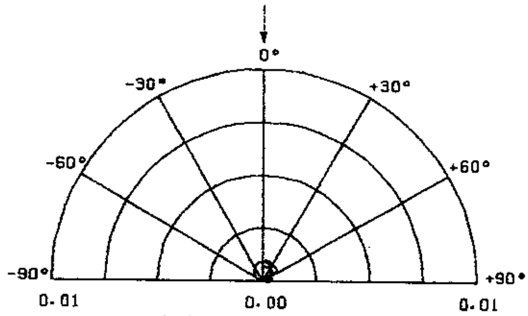
INFORMATION

82 2 4

D ⇒ MO

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	MO
ION	H 1 2.00
TARGET	MO 42 95.9

ENERGY (EV)	1.00×10^{5}
EPSILON	2.37×10^{1}
GAMMA	8.00×10^{-2}
Q	2.92×10^{-2}
COS* N	1.29
REFERENCE	82.2



DIFFERENTIAL
SPUTTERING YIELD
(ATOMS/ION STER.)

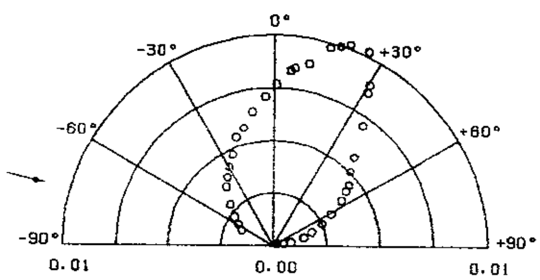
INFORMATION

82 2 5

D ⇒ MO

INCIDENT ANGLE	75°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	MO
ION	H 1 2.00
TARGET	MO 42 95.9

ENERGY (EV)	5.00×10^{4}
EPSILON	1.18×10^{1}
GAMMA	8.00×10^{-2}
Q	4.13×10^{-2}
EJECTION ANGLE EXP.	25.0°
CAL.	18.7°
REFERENCE	82.2



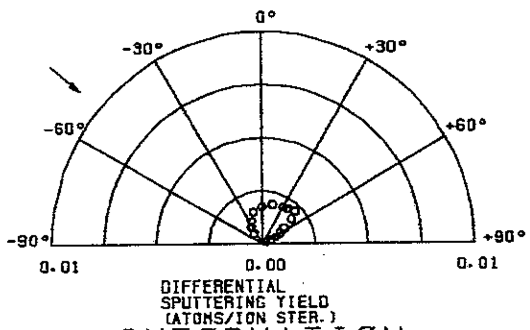
DIFFERENTIAL
SPUTTERING YIELD
(ATOMS/ION STER.)

INFORMATION

82 2 6

D ⇒ MO

INCIDENT ANGLE	50°			ENERGY (EV)	5.00×10^{4}
TARGET	POLY			EPSILON	1.18×10^{1}
ENVIRONMENT	UHV			GAMMA	8.00×10^{-2}
SPUTTERED ATOM (S)	MO			Q	4.13×10^{-2}
				EJECTION ANGLE EXP.	45.0°
				CAL.	44.8°
ION	H	1	2.00		
TARGET	MO	42	95.9	REFERENCE	82.2

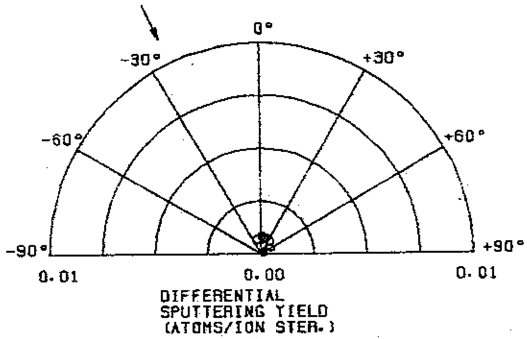


INFORMATION

82 2 7

D ⇒ MO

INCIDENT ANGLE	25°			ENERGY (EV)	5.00×10^{4}
TARGET	POLY			EPSILON	1.18×10^{1}
ENVIRONMENT	UHV			GAMMA	8.00×10^{-2}
SPUTTERED ATOM (S)	MO			Q	4.13×10^{-2}
				EJECTION ANGLE EXP.	45.0°
				CAL.	75.5°
ION	H	1	2.00		
TARGET	MO	42	95.9	REFERENCE	82.2

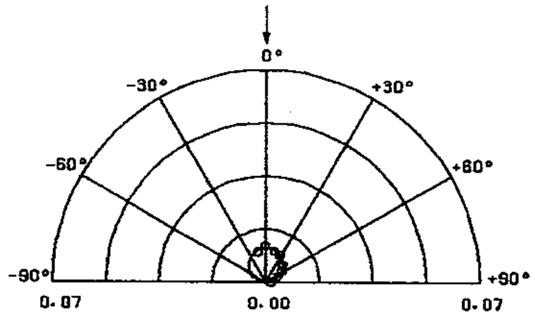


INFORMATION

82 2 8

HE ⇒ MO

INCIDENT ANGLE	0 °		ENERGY (EV)	1.00×10^{5}	
TARGET	POLY		EPSILON	1.14×10^{1}	
ENVIRONMENT	UHV		GAMMA	1.54×10^{-1}	
SPUTTERED ATOM(S)	MO		Q	2.11×10^{-2}	
			COS* N	1.11	
ION	HE	2	4.00		
TARGET	MO	42	95.9	REFERENCE	82.2



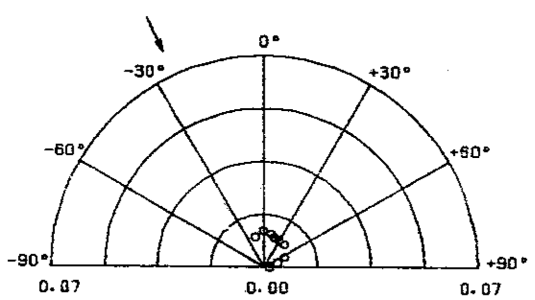
DIFFERENTIAL
SPUTTERING YIELD
(ATOMS/ION STER.)

INFORMATION

82 2 9

HE ⇒ MO

INCIDENT ANGLE	25°		ENERGY (EV)	1.00×10^{5}	
TARGET	POLY		EPSILON	1.14×10^{1}	
ENVIRONMENT	UHV		GAMMA	1.54×10^{-1}	
SPUTTERED ATOM(S)	MO		Q	2.11×10^{-2}	
			EJECTION ANGLE EXP.	60.0°	
			CAL.	69.7°	
ION	HE	2	4.00		
TARGET	MO	42	95.9	REFERENCE	82.2



DIFFERENTIAL
SUPTTERING YIELD
(ATOMS/ION STER.)

INFORMATION

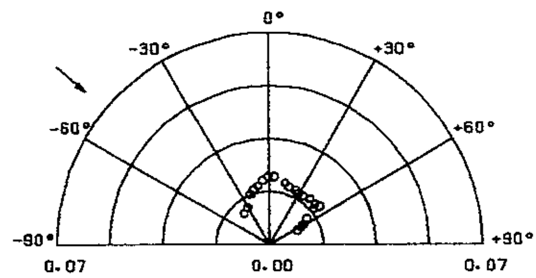
82 2 10

HE ⇒ MO

INCIDENT ANGLE	50°	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	EPSILON	1.14×10^{1}
ENVIRONMENT	UHV	GAMMA	1.54×10^{-1}
SPUTTERED ATOM (S)	MO	Q	2.11×10^{-2}
		EJECTION ANGLE EXP.	50.0°
		CAL.	42.4°

ION	HE	2	4.00
TARGET	MO	42	95.9

REFERENCE 82.2



DIFFERENTIAL SPUTTERING YIELD (ATOMS/ION STER.)

INFORMATION

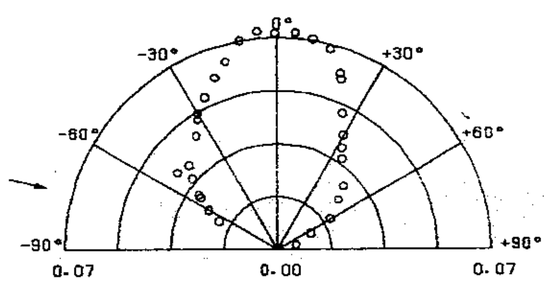
82 2 11

HE ⇒ MO

INCIDENT ANGLE	75°	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	EPSILON	1.14×10^{1}
ENVIRONMENT	UHV	GAMMA	1.54×10^{-1}
SPUTTERED ATOM (S)	MO	Q	2.11×10^{-2}
		EJECTION ANGLE EXP.	5.00°
		CAL.	16.9°

ION	HE	2	4.00
TARGET	MO	42	95.9

REFERENCE 82.2



DIFFERENTIAL SPUTTERING YIELD (ATOMS/ION STER.)

INFORMATION

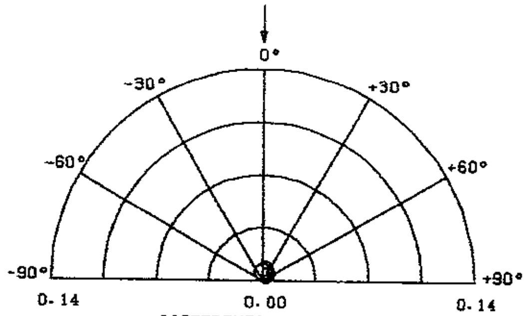
82 2 12

HE ⇒ MO

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{4}
TARGET	POLY	EPSILON	5.68
ENVIRONMENT	UHV	GAMMA	1.54×10^{-1}
SPUTTERED ATOM (S)	MO	Q	2.98×10^{-2}
		COS^{N} N	1.11

ION	HE	2	4.00
TARGET	MO	42	95.9

REFERENCE 82.2



DIFFERENTIAL SPUTTERING YIELD (ATOMS/ION STER.)

INFORMATION

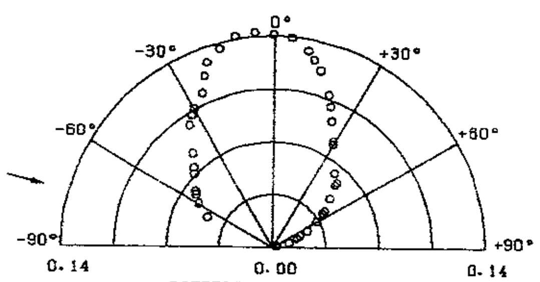
82 2 13

HE ⇒ MO

INCIDENT ANGLE	75°	ENERGY (EV)	5.00×10^{4}
TARGET	POLY	EPSILON	5.68
ENVIRONMENT	UHV	GAMMA	1.54×10^{-1}
SPUTTERED ATOM (S)	MO	Q	2.98×10^{-2}
		EJECTION ANGLE EXP.	0.00°
		CAL.	17.6°

ION	HE	2	4.00
TARGET	MO	42	95.9

REFERENCE 82.2



DIFFERENTIAL SPUTTERING YIELD (ATOMS/IONS STER.)

INFORMATION

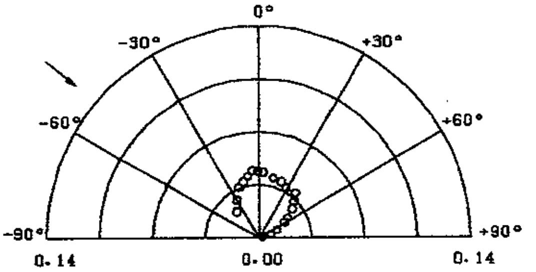
82 2 14

HE ⇒ MO

INCIDENT ANGLE	50°	ENERGY (EV)	5.00 X10^{4}
TARGET	POLY	EPSILON	5.68
ENVIRONMENT	UHV	GAMMA	1.54 X10^{-1}
SPUTTERED ATOM(S)	MO	Q	2.98 X10^{-2}
		EJECTION ANGLE EXP.	40.0°
		CAL.	43.4°

ION	HE	2	4.00
TARGET	MO	42	95.9

REFERENCE 82.2



INFORMATION

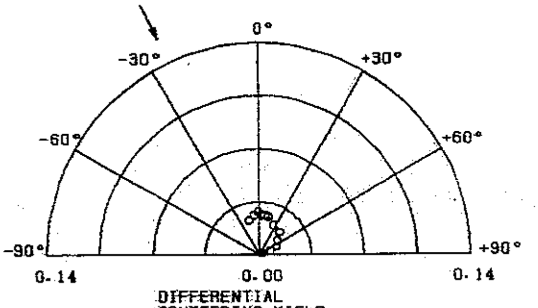
82 2 15

HE ⇒ MO

INCIDENT ANGLE	25°	ENERGY (EV)	5.00 X10^{4}
TARGET	POLY	EPSILON	5.68
ENVIRONMENT	UHV	GAMMA	1.54 X10^{-1}
SPUTTERED ATOM(S)	MO	Q	2.98 X10^{-2}
		EJECTION ANGLE EXP.	40.0°
		CAL.	72.0°

ION	HE	2	4.00
TARGET	MO	42	95.9

REFERENCE 82.2

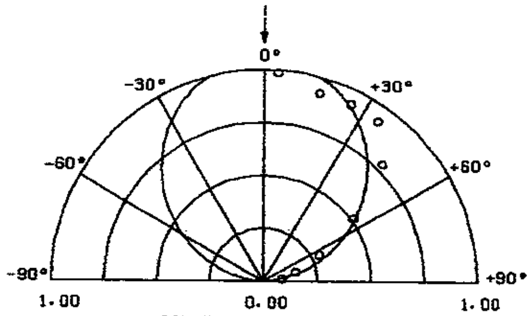


INFORMATION

82 3 1

CU ⇒ CU

INCIDENT ANGLE	0 °		ENERGY (EV)	6.00 X10^{4}
TARGET	POLY		EPSILON	3.02 X10^{-1}
ENVIRONMENT	UHV		GAMMA	10.00X10^{-1}
SPUTTERED ATOM (S)	CU		Q	7.63 X10^{-3}
			COS* N	1.26
ION	CU 29	63.5	REFERENCE	82.3
TARGET	CU 29	63.5		

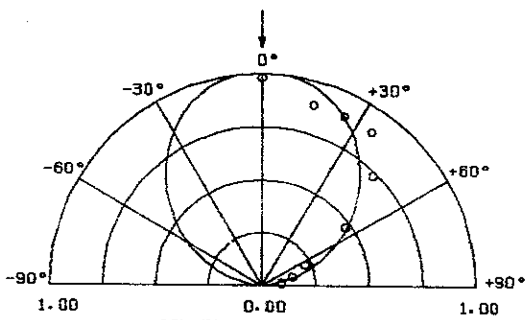


INFORMATION

82 3 2

CU ⇒ CU

INCIDENT ANGLE	0 °		ENERGY (EV)	9.00 X10^{4}
TARGET	POLY		EPSILON	4.52 X10^{-1}
ENVIRONMENT	UHV		GAMMA	10.00X10^{-1}
SPUTTERED ATOM (S)	CU		Q	6.23 X10^{-3}
			COS* N	1.35
ION	CU 29	63.5	REFERENCE	82.3
TARGET	CU 29	63.5		

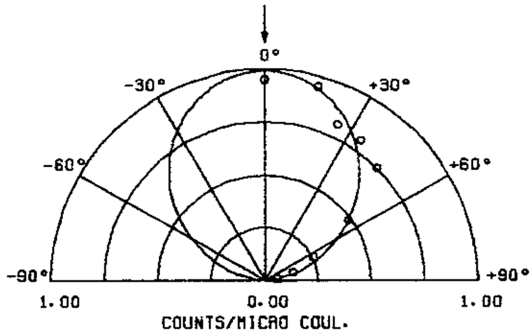


INFORMATION

82 9 3

CU ⇒ CU

INCIDENT ANGLE	0 °			ENERGY (EV)	1.20×10^{5}
TARGET	POLY			EPSILON	6.03×10^{-1}
ENVIRONMENT	UHV			GAMMA	10.00×10^{-1}
SPUTTERED ATOM (S)	CU			Q	5.39×10^{-3}
				COS^{N} N	1.33
ION	CU	29	63.5	REFERENCE	82.3
TARGET	CU	29	63.5		

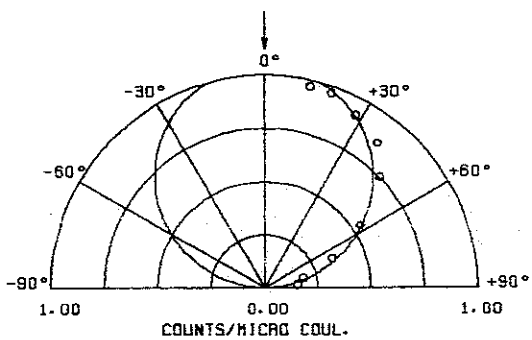


INFORMATION

82 3 4

NI ⇒ NI

INCIDENT ANGLE	0 °			ENERGY (EV)	6.00×10^{4}
TARGET	POLY			EPSILON	3.27×10^{-1}
ENVIRONMENT	UHV			GAMMA	10.00×10^{-1}
SPUTTERED ATOM (S)	NI			Q	8.60×10^{-3}
				COS^{N} N	1.05
ION	NI	28	58.7	REFERENCE	82.3
TARGET	NI	28	58.7		



INFORMATION

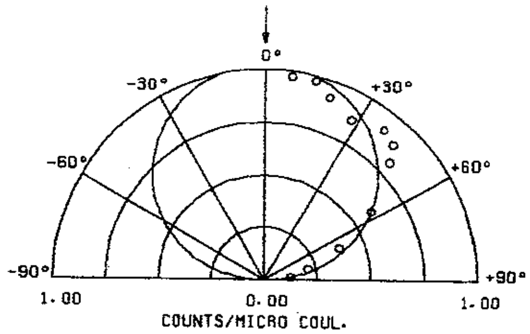
82 3 5

NI ⇒ NI

INCIDENT ANGLE	0 °	ENERGY (EV)	9.00×10^{4}
TARGET	POLY	EPSILON	4.91×10^{-1}
ENVIRONMENT	UHV	GAMMA	10.00×10^{-1}
SPUTTERED ATOM (S)	NI	Q	7.02×10^{-3}
		COS* N	9.00×10^{-1}

ION	NI	28	58.7
TARGET	NI	28	58.7

REFERENCE 82.3



INFORMATION

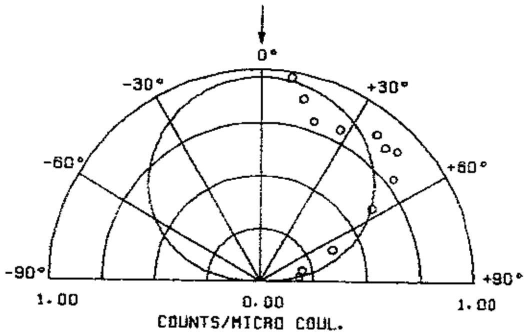
82 3 8

NI ⇒ NI

INCIDENT ANGLE	0 °	ENERGY (EV)	1.20×10^{5}
TARGET	POLY	EPSILON	6.55×10^{-1}
ENVIRONMENT	UHV	GAMMA	10.00×10^{-1}
SPUTTERED ATOM (S)	NI	Q	6.08×10^{-3}
		COS* N	7.50×10^{-1}

ION	NI	28	58.7
TARGET	NI	28	58.7

REFERENCE 82.3



INFORMATION

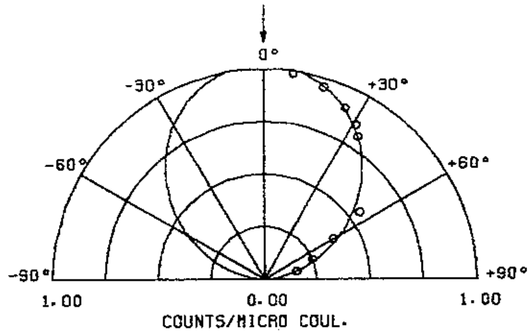
82 3 7

CU ⇒ CU

INCIDENT ANGLE	0 °	ENERGY (EV)	9.00×10^{4}
TARGET	POLY	EPSILON	4.52×10^{-1}
ENVIRONMENT	UHV	GAMMA	10.00×10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.23×10^{-3}
		COS^{N} N	1.30

ION	CU	29	63.5	REFERENCE	82 . 3
TARGET	CU	29	63.5		

(RBS) FOIL II
FLUENCE = 12E+17 CU/SQ. CENTI-M



INFORMATION

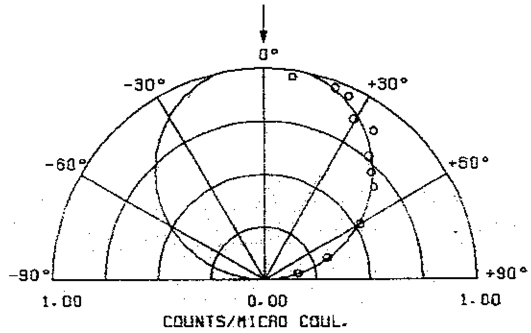
82 3 8

CU ⇒ CU

INCIDENT ANGLE	0 °	ENERGY (EV)	9.00×10^{4}
TARGET	POLY	EPSILON	4.52×10^{-1}
ENVIRONMENT	UHV	GAMMA	10.00×10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.23×10^{-3}
		COS^{N} N	1.00

ION	CU	29	63.5	REFERENCE	82 . 3
TARGET	CU	29	63.5		

(RBS) FOIL III
FLUEBCE = 5.2E+17 CU/SQ. CENTI-M



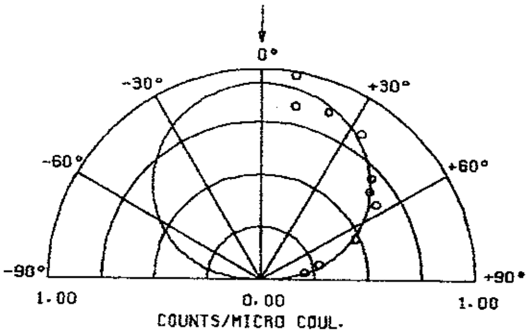
INFORMATION

82 3 9

CU ⇒ CU

INCIDENT ANGLE	0 °			ENERGY (EV)	9.00×10^{4}
TARGET	POLY			EPSILON	4.52×10^{-1}
ENVIRONMENT	UHV			GAMMA	10.00×10^{-1}
SPUTTERED ATOM(S)	CU			Q	6.23×10^{-3}
				COS^{N} N	7.70×10^{-1}
ION	CU	29	63.5		
TARGET	CU	29	63.5	REFERENCE	82.3

(RBS) FOIL V
FLUENCE = 1.3E+17 CU/SQ.CENTI-M



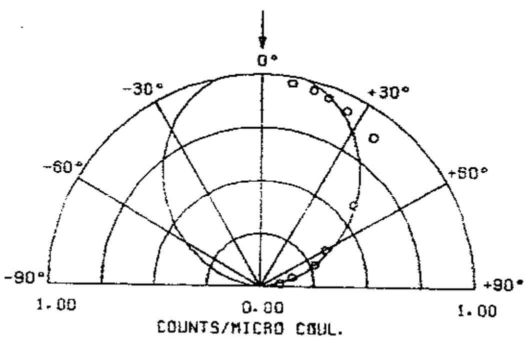
INFORMATION

82 3 10

CU ⇒ CU

INCIDENT ANGLE	0 °			ENERGY (EV)	9.00×10^{4}
TARGET	POLY			EPSILON	4.52×10^{-1}
ENVIRONMENT	UHV			GAMMA	10.00×10^{-1}
SPUTTERED ATOM(S)	CU			Q	6.23×10^{-3}
				COS^{N} N	1.35
ION	CU	29	63.5		
TARGET	CU	29	63.5	REFERENCE	82.3

(PIXE) FOIL II
FLUENCE = 12E+17 CU/SQ.CENTI-M



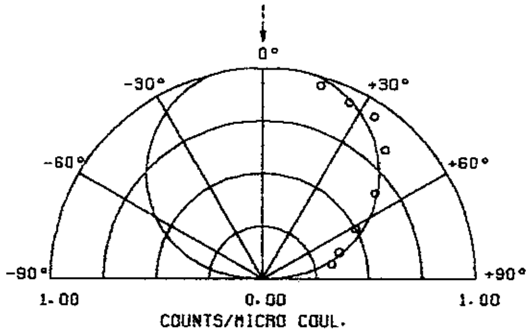
INFORMATION

82 3 11

CU ⇒ CU

INCIDENT ANGLE	0 °	ENERGY (EV)	9.00 X10^{4}
TARGET	POLY	EPSILON	4.52 X10^{-1}
ENVIRONMENT	UHV	GAMMA	10.00 X10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.23 X10^{-3}
		$\cos^{N}$ N	8.20 X10^{-1}
ION	CU 29 63.5	REFERENCE	82.3
TARGET	CU 29 63.5		

(PIXE) FOIL III
FLUENCE = 5.2E+17 CU/SQ.CENTI-M



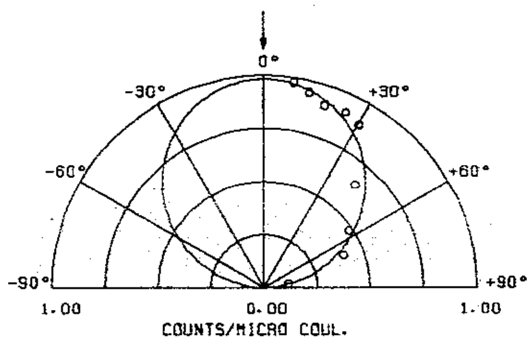
INFORMATION

82 3 12

CU ⇒ CU

INCIDENT ANGLE	0 °	ENERGY (EV)	9.00 X10^{4}
TARGET	POLY	EPSILON	4.52 X10^{-1}
ENVIRONMENT	UHV	GAMMA	10.00 X10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.23 X10^{-3}
		$\cos^{N}$ N	1.07
ION	CU 29 63.5	REFERENCE	82.3
TARGET	CU 29 63.5		

(PIXE) FOIL V
FLUENCE = 1.3E+17 CU/SQ.CENTI-M



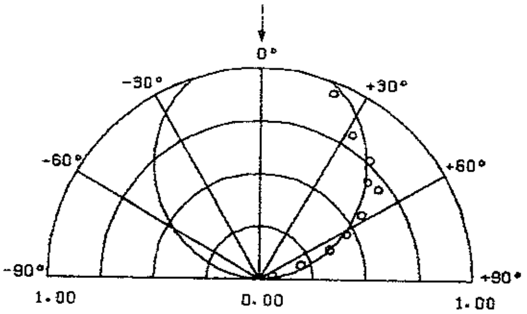
INFORMATION

82 7 1

HE ⇒ V

INCIDENT ANGLE	0 °			ENERGY (EV)	4.00×10^{3}
TARGET	POLY			EPSILON	9.52×10^{-1}
ENVIRONMENT	--. -- EXPOSURE			GAMMA	2.70×10^{-1}
SPUTTERED ATOM (S)	V			Q	7.01×10^{-2}
				COS * N	1.19
ION	HE	2	4.00	REFERENCE	82.7
TARGET	V	23	50.9		

OXYGEN EXPOSED



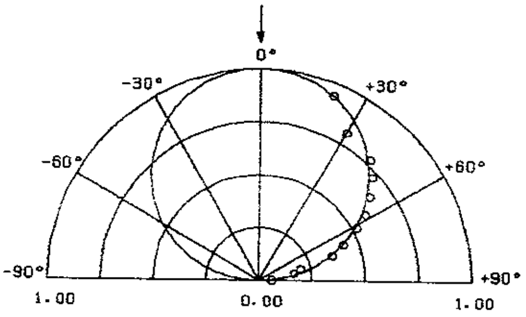
INFORMATION

82 7 2

HE ⇒ V

INCIDENT ANGLE	0 °			ENERGY (EV)	4.00×10^{3}
TARGET	POLY			EPSILON	9.52×10^{-1}
ENVIRONMENT	UHV			GAMMA	2.70×10^{-1}
SPUTTERED ATOM (S)	V			Q	7.01×10^{-2}
				COS * N	9.30×10^{-1}
ION	HE	2	4.00	REFERENCE	82.7
TARGET	V	23	50.9		

CLEAN METAL



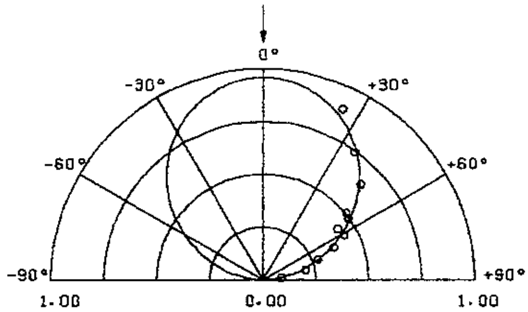
INFORMATION

82 7 3

H ⇒ V

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{2}
TARGET	POLY	EPSILON	2.60×10^{-1}
ENVIRONMENT	UHV	GAMMA	7.61×10^{-2}
SPUTTERED ATOM (S)	V	Q	3.74×10^{-1}
		COS^{N} N	1.17

ION	H	1	1.01	REFERENCE	82.7
TARGET	V	23	50.9		



INFORMATION

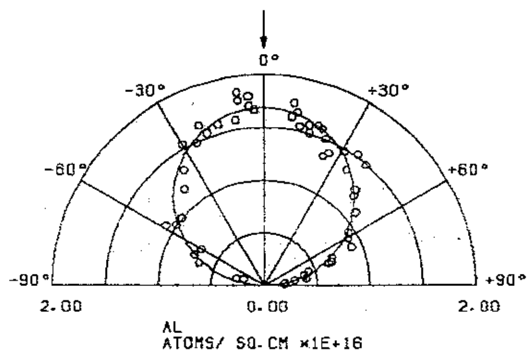
82 11 1

AR ⇒ AL

INCIDENT ANGLE	0 °	ENERGY (EV)	4.00×10^{4}
TARGET	POLY	EPSILON	7.19×10^{-1}
ENVIRONMENT	HV	GAMMA	9.62×10^{-1}
SPUTTERED ATOM (S)	AL	Q	9.38×10^{-3}
		COS^{N} N	9.60×10^{-1}

ION	AR	18	39.9	REFERENCE	82.11
TARGET	AL	13	27.0		
	O	8	16.0		

1-4E-4 PA



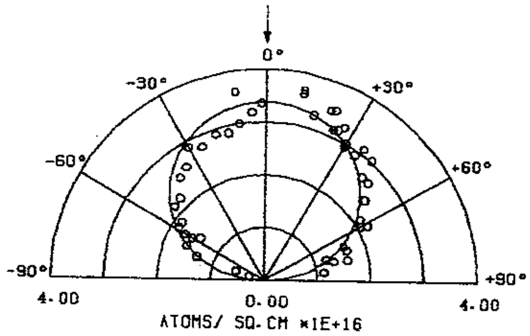
INFORMATION

82 11 2

AR ⇒ AL

INCIDENT ANGLE	0 °		ENERGY (EV)	4.00×10^{4}
TARGET	POLY		EPSILON	8.85×10^{-1}
ENVIRONMENT	HV		GAMMA	9.62×10^{-1}
SPUTTERED ATOM (S)	O		Q	8.92×10^{-3}
			COS* N	8.60×10^{-1}
ION	AR 18	39.9	REFERENCE	82.11
TARGET	AL 13	27.0		
	O 8	16.0		

OXYGEN
1-4E-4 PA.



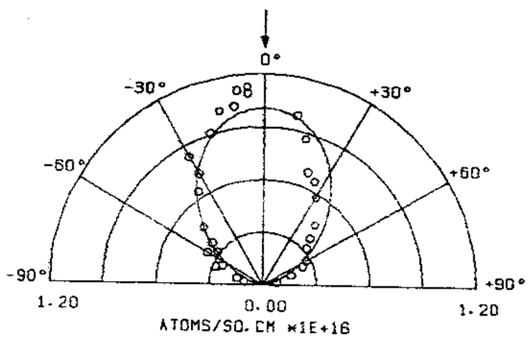
INFORMATION

82 11 3

AR ⇒ AL2-O3

INCIDENT ANGLE	0 °		ENERGY (EV)	4.00×10^{4}
TARGET	POLY		EPSILON	7.19×10^{-1}
ENVIRONMENT	HV		GAMMA	9.62×10^{-1}
SPUTTERED ATOM (S)	AL		Q	9.38×10^{-3}
			COS* N	2.12
ION	AR 18	39.9	REFERENCE	82.11
TARGET	AL 13	27.0		
	O 8	16.0		

AL 1 - 4E-4 PA



INFORMATION

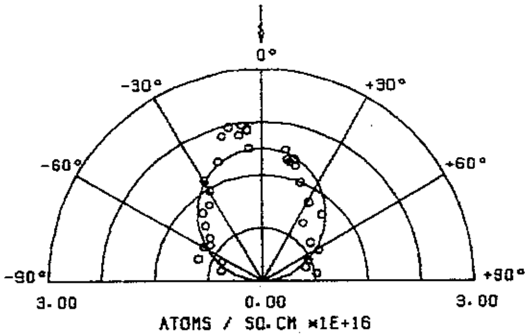
82 11 4

AR ⇒ AL2-03

INCIDENT ANGLE	0 °	ENERGY (EV)	4.00 X10^{4}
TARGET	POLY	EPSILON	8.85 X10^{-1}
ENVIRONMENT	HV	GAMMA	9.62 X10^{-1}
SPUTTERED ATOM (S)	O	Q	8.92 X10^{-3}
		COS * N	1.12

ION	AR	18	39.9	REFERENCE	82.11
TARGET	AL	13	27.0		
	O	8	16.0		

OXYGEN 1 - 4E-4 PA



INFORMATION

83 1 1

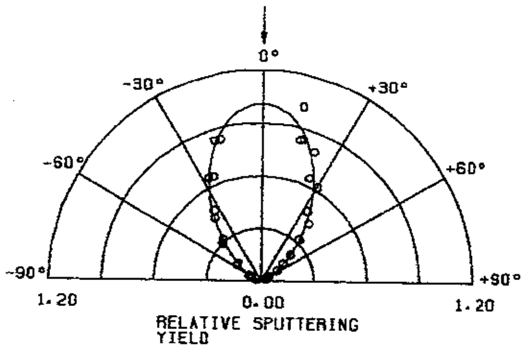
AR ⇒ GA-I

INCIDENT ANGLE	0 °		ENERGY (EV)	1.50×10^{4}
TARGET	POLY		EPSILON	1.53×10^{-1}
ENVIRONMENT	UHV		GAMMA	9.26×10^{-1}
SPUTTERED ATOM (S)	GA		Q	1.42×10^{-2}
			COS^{N} N	3.84

ION	AR	18	39.9
TARGET	GA	31	69.7
	I	53	127

REFERENCE 83.1

GA



INFORMATION

83 1 2

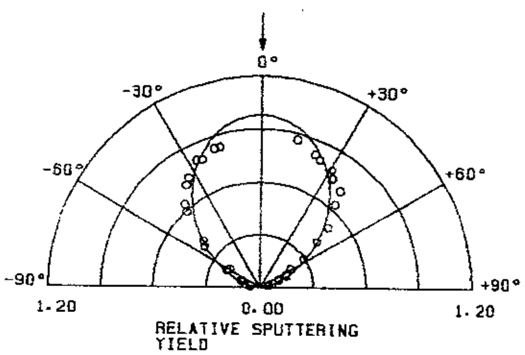
AR ⇒ GA-I

INCIDENT ANGLE	0 °		ENERGY (EV)	1.50×10^{4}
TARGET	POLY		EPSILON	9.59×10^{-2}
ENVIRONMENT	UHV		GAMMA	9.26×10^{-1}
SPUTTERED ATOM (S)	I		Q	1.01×10^{-2}
			COS^{N} N	1.85

ION	AR	18	39.9
TARGET	GA	31	69.7
	I	53	127

REFERENCE 83.1

I



INFORMATION

89 2 1

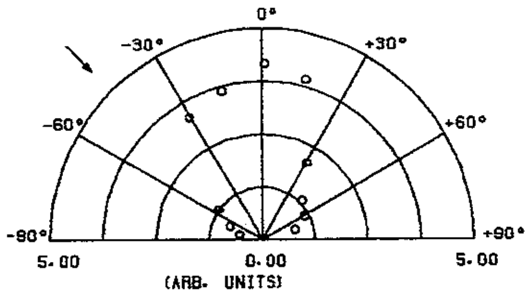
AR ⇒ AU-CU

INCIDENT ANGLE	45°	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	EPSILON	3.21×10^{-2}
ENVIRONMENT	UHV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	CU	Q	3.50×10^{-2}
		EJECTION ANGLE EXP.	45.8°
		CAL.	49.4°

ION	AR	18	39.9
TARGET	AU	79	197
	CU	29	63.5

REFERENCE 83.2

CU 43 AT%



INFORMATION

83 2 2

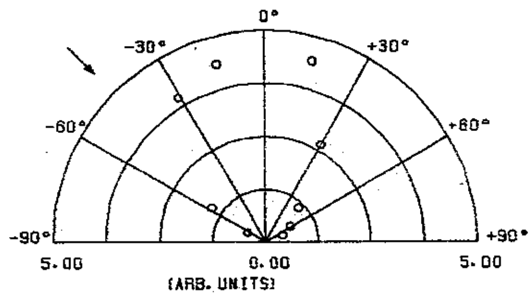
AR ⇒ AU-CU

INCIDENT ANGLE	45°	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	EPSILON	1.28×10^{-2}
ENVIRONMENT	UHV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	4.76×10^{-2}
		EJECTION ANGLE EXP.	57.9°
		CAL.	51.1°

ION	AR	18	39.9
TARGET	AU	79	197
	CU	29	63.5

REFERENCE 83.2

AU 43 AT%



INFORMATION

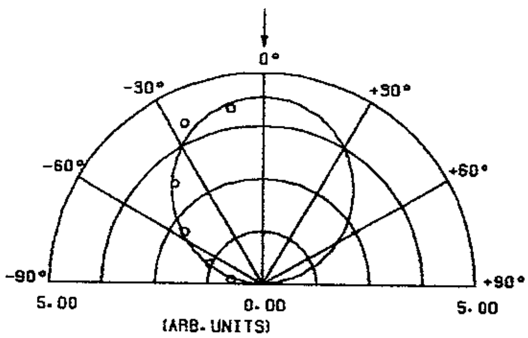
83 2 3

AR ⇒ AU-CU

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	EPSILON	3.21×10^{-2}
ENVIRONMENT	UHV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	CU	Q	3.50×10^{-2}
		COS^{N} N	1.15

ION	AR	18	39.9	REFERENCE	83.2
TARGET	AU	79	197		
	CU	29	63.5		

CU 43 AT%



INFORMATION

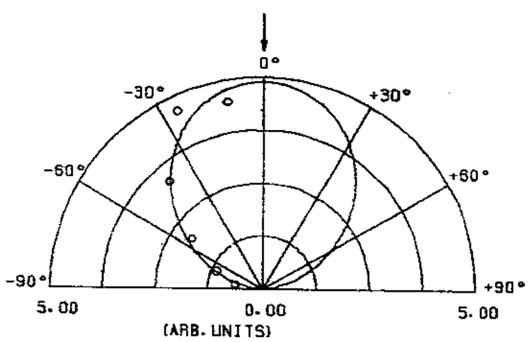
83 2 4

AR ⇒ AU-CU

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	EPSILON	1.28×10^{-2}
ENVIRONMENT	UHV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	4.76×10^{-2}
		COS^{N} N	1.42

ION	AR	18	39.9	REFERENCE	83.2
TARGET	AU	79	197		
	CU	29	63.5		

AU 43 AT%



INFORMATION

89 4 1

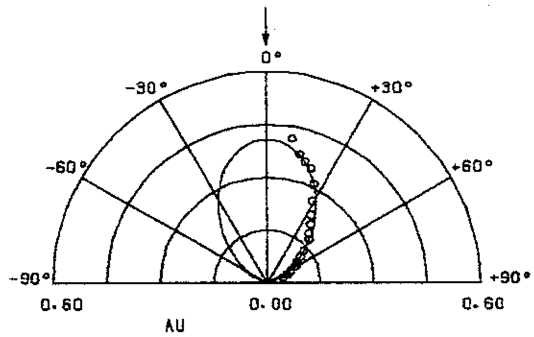
AR ⇒ AG-AU

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	EPSILON	4.27×10^{-1}
ENVIRONMENT	UHV	GAMMA	7.89×10^{-1}
SPUTTERED ATOM (S)	AU	Q	8.24×10^{-3}
		COS * N	2.70

ION	AR	18	39.9
TARGET	AG	47	108
	AU	79	197

REFERENCE 83.4

STRIP 1



INFORMATION

89 4 2

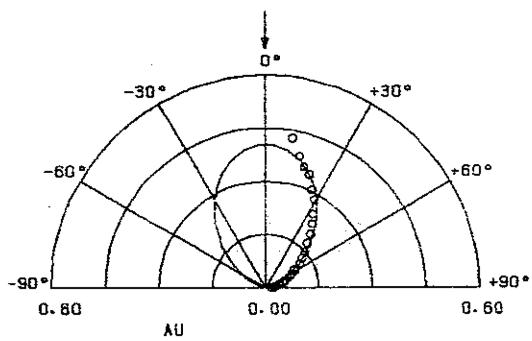
AR ⇒ AG-AU

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	EPSILON	4.27×10^{-1}
ENVIRONMENT	UHV	GAMMA	7.89×10^{-1}
SPUTTERED ATOM (S)	AU	Q	8.24×10^{-3}
		COS * N	2.40

ION	AR	18	39.9
TARGET	AG	47	108
	AU	79	197

REFERENCE 83.4

STRIP 4



INFORMATION

83 4 3

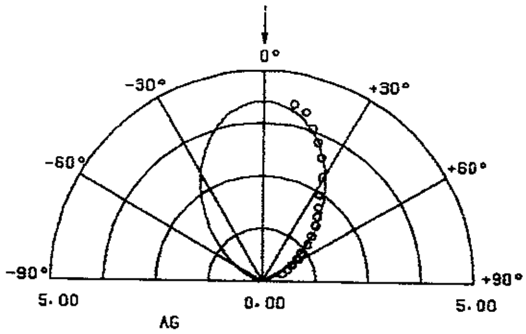
AR ⇒ AG-AU

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00 X10^{5}
TARGET	POLY	EPSILON	7.10 X10^{-1}
ENVIRONMENT	UHV	GAMMA	7.89 X10^{-1}
SPUTTERED ATOM (S)	AG	Q	6.12 X10^{-3}
		COS^{N} N	2.60

ION	AR	18	39.9
TARGET	AG	47	108
	AU	79	197

REFERENCE 83.4

STRIP 1



INFORMATION

83 4 4

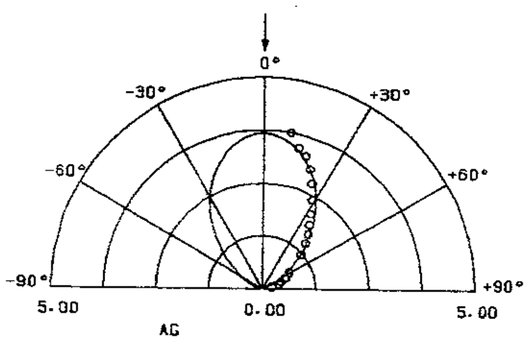
AR ⇒ AG-AU

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00 X10^{5}
TARGET	POLY	EPSILON	7.10 X10^{-1}
ENVIRONMENT	UHV	GAMMA	7.89 X10^{-1}
SPUTTERED ATOM (S)	AG	Q	6.12 X10^{-3}
		COS^{N} N	2.74

ION	AR	18	39.9
TARGET	AG	47	108
	AU	79	197

REFERENCE 83.4

STRIP 3



INFORMATION

89 4 5

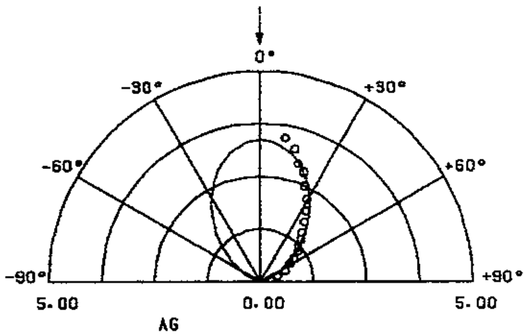
AR ⇒ AG-AU

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	EPSILON	7.10×10^{-1}
ENVIRONMENT	UHV	GAMMA	7.89×10^{-1}
SPUTTERED ATOM(S)	AG	Q	6.12×10^{-3}
		COS^{N} N	2.59

ION	AR	18	39.9
TARGET	AG	47	108
	AU	79	197

REFERENCE 83.4

STRIP 5



INFORMATION

89 4 6

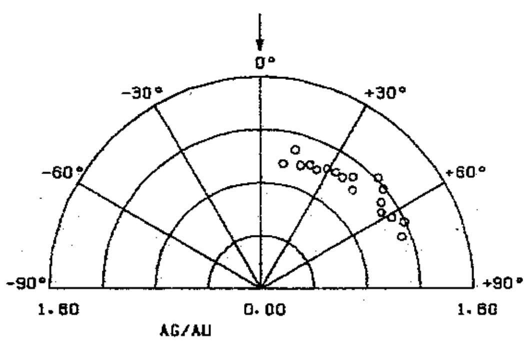
AR ⇒ AU-AG

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{5}
TARGET	POLY		
ENVIRONMENT	UHV		
SPUTTERED ATOM(S)	AG / AU		

ION	AR	18	39.9
TARGET	AU	79	197
	AG	47	108

REFERENCE 83.4

STRIP 1 R=1.26



INFORMATION

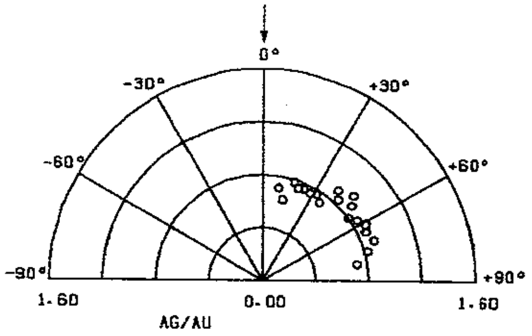
89 4 7

AR ⇒ AU-AG

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^5
TARGET	POLY	REFERENCE	83.4
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	AG / AU		

ION	AR	18	39.9
TARGET	AU	79	197
	AG	47	108

STRIP 2 R=1.1



INFORMATION

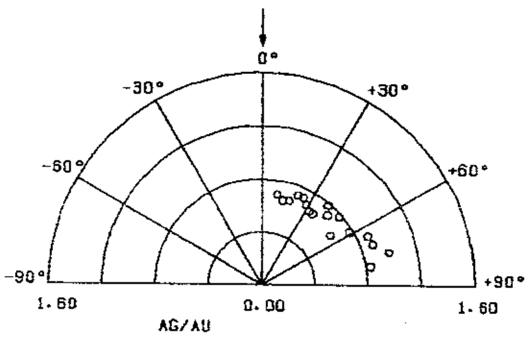
89 4 8

AR ⇒ AU-AG

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^5
TARGET	POLY	REFERENCE	83.4
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	AG / AU		

ION	AR	18	39.9
TARGET	AU	79	197
	AG	47	108

STRIP 3 R=1.05



INFORMATION

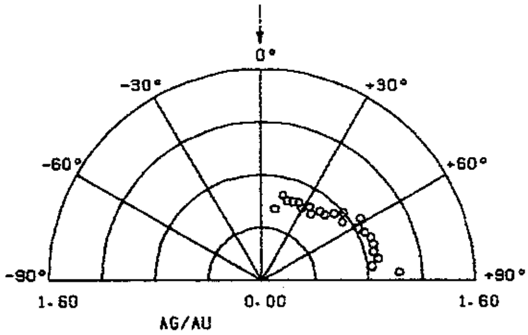
89 4 8

AR ⇒ AU-AG

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	REFERENCE	83.4
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	AG / AU		

ION	AR	18	39.9
TARGET	AU	79	197
	AG	47	108

STRIP 4 R=1.03



INFORMATION

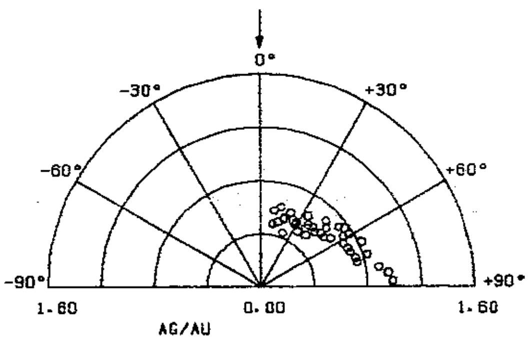
89 4 10

AR ⇒ AU-AG

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	REFERENCE	83.4
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	AG / AU		

ION	AR	18	39.9
TARGET	AU	79	197
	AG	47	108

STRIP 5 R=1.01



INFORMATION

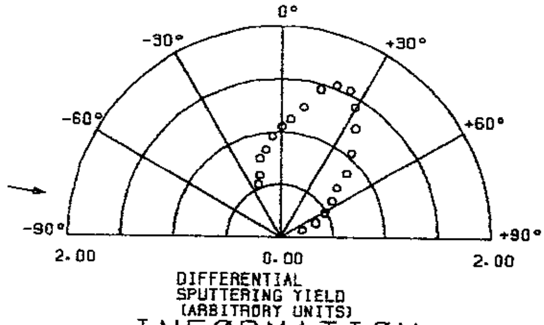
83 5 1

D ⇒ MO

INCIDENT ANGLE	80°	ENERGY (EV)	2.00×10^{3}
TARGET	POLY	EPSILON	4.74×10^{-1}
ENVIRONMENT	UHV	GAMMA	8.00×10^{-2}
SPUTTERED ATOM (S)	MO	Q	2.06×10^{-1}
		EJECTION ANGLE EXP.	25.0°
		CAL.	28.2°

ION	H	1	2.00
TARGET	MO	42	95.9

REFERENCE 83.5



INFORMATION

83 5 2

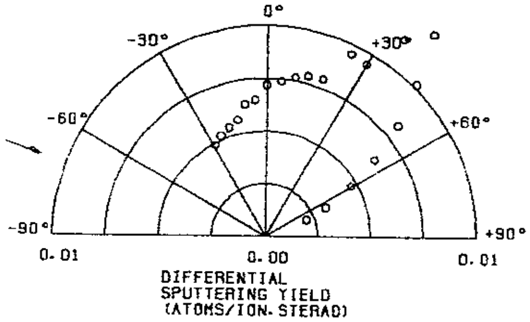
D ⇒ NB-B2

INCIDENT ANGLE	70°	ENERGY (EV)	2.00×10^{3}
TARGET	POLY	EPSILON	6.26
ENVIRONMENT	UHV	GAMMA	8.25×10^{-2}
SPUTTERED ATOM (S)	B	Q	7.40×10^{-2}
		EJECTION ANGLE EXP.	39.8°
		CAL.	26.8°

ION	H	1	2.00
TARGET	NB	41	92.9
	B	5	10.8

REFERENCE 83.5

B DISTRIBUTION



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INFORMATION

89 5 9

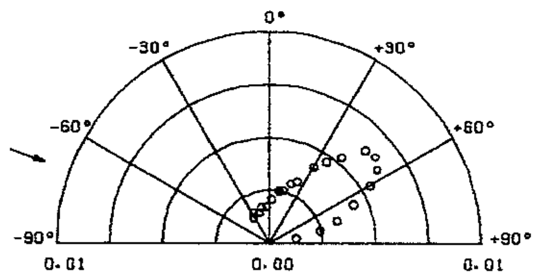
D ⇒ NB-B2

INCIDENT ANGLE	70°	ENERGY (EV)	2.00×10^{3}
TARGET	POLY	EPSILON	4.89×10^{-1}
ENVIRONMENT	UHV	GAMMA	8.25×10^{-2}
SPUTTERED ATOM(S)	NB	Q	2.14×10^{-1}
		EJECTION ANGLE EXP.	50.6°
		CAL.	40.9°

ION	H	1	2.00
TARGET	NB	41	92.9
	B	5	10.8

REFERENCE 83.5

NB DISTRIBUTION



DIFFERENTIAL
SPUTTERING YIELD
(ATOMS/ION. STERAD)

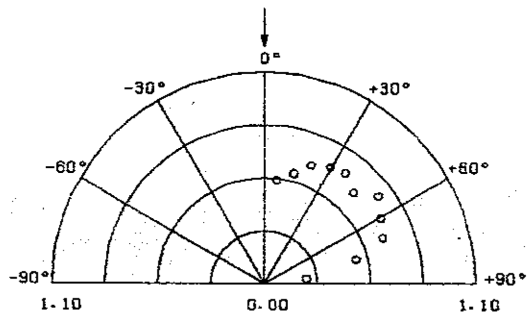
INFORMATION

89 7 1

AR ⇒ CU-PT

INCIDENT ANGLE	0°	ENERGY (EV)	2.00×10^{3}
TARGET	POLY		
ENVIRONMENT	UHV	REFERENCE	83.7
SPUTTERED ATOM(S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195



PT/CU

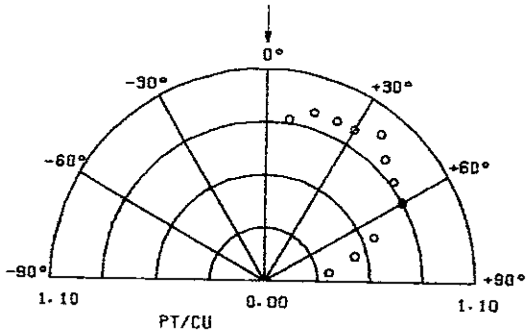
INFORMATION

83 7 2

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	2.00×10^3
TARGET	POLY	REFERENCE	83.7
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195



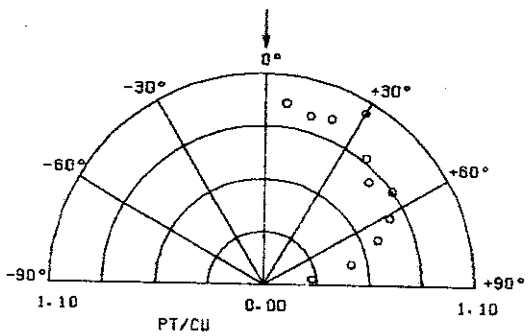
INFORMATION

83 7 3

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	2.00×10^3
TARGET	POLY	REFERENCE	83.7
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195



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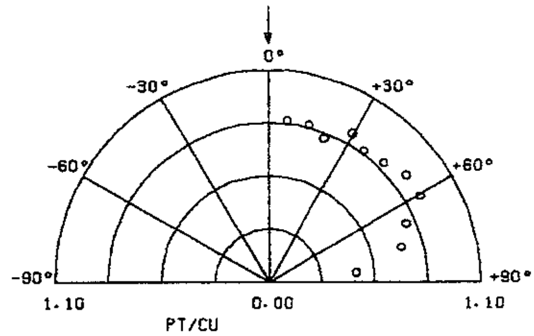
INFORMATION

83 7 4

AR ⇒ CU-PT

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	PT / CU
ENERGY (EV)	2.00×10^3
REFERENCE	83.7

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195



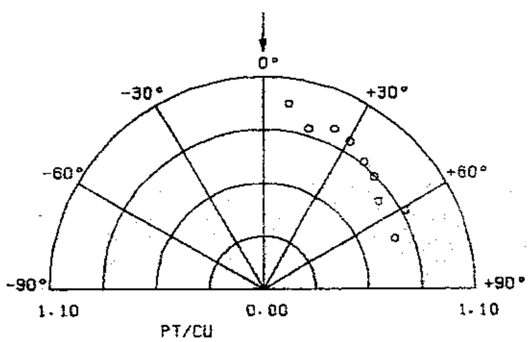
INFORMATION

83 7 5

AR ⇒ CU-PT

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	PT / CU
ENERGY (EV)	2.00×10^3
REFERENCE	83.7

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195



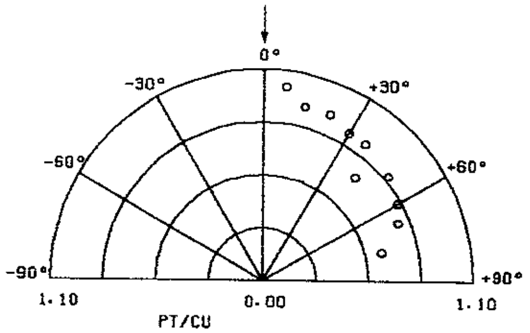
INFORMATION

83 7 6

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	2.00×10^3
TARGET	POLY	REFERENCE	83 . 7
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195



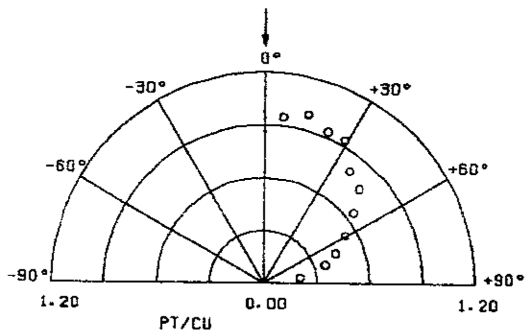
INFORMATION

83 7 7

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	2.00×10^3
TARGET	POLY	REFERENCE	83 . 7
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195



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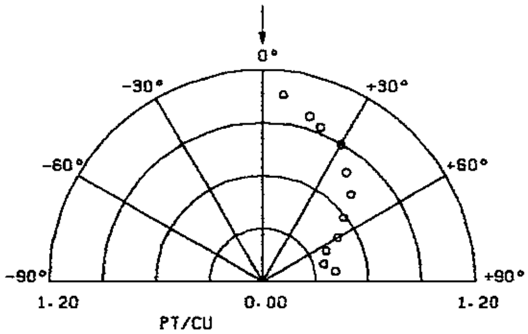
INFORMATION

89 7 8

AR ⇒ CU-PT

INCIDENT ANGLE	0 °		ENERGY (EV)	2.00×10^{3}
TARGET	POLY		REFERENCE	83.7
ENVIRONMENT	UHV			
SPUTTERED ATOM (S)	PT / CU			
ION	AR	18	39.9	
TARGET	CU	29	63.5	
	PT	78	195	

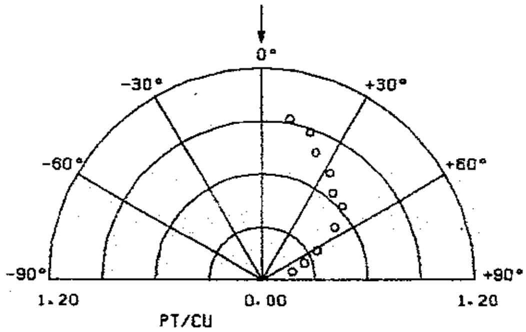


INFORMATION

89 7 9

AR ⇒ CU-PT

INCIDENT ANGLE	0 °		ENERGY (EV)	2.00×10^{3}
TARGET	POLY		REFERENCE	83.7
ENVIRONMENT	UHV			
SPUTTERED ATOM (S)	PT / CU			
ION	AR	18	39.9	
TARGET	CU	29	63.5	
	PT	78	195	



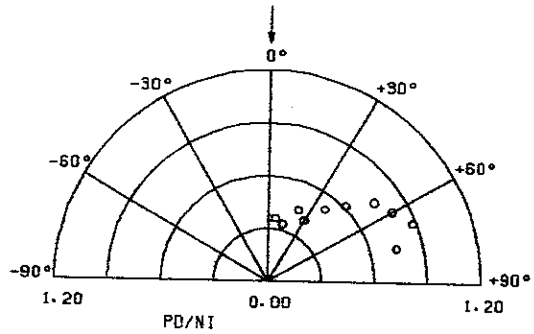
INFORMATION

83 7 10

AR ⇒ NI5-PD

INCIDENT ANGLE	0 °	ENERGY (EV)	2.00×10^3
TARGET	POLY	REFERENCE	83 . 7
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PD / NI		

ION	AR	18	39.9
TARGET	NI	28	58.7
	PD	46	106



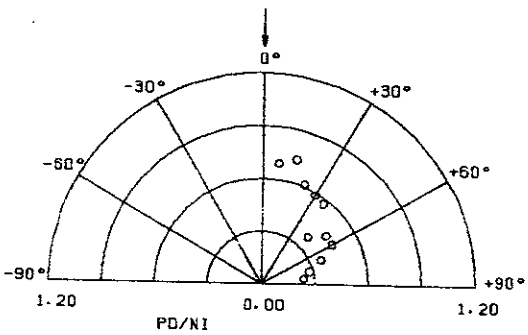
INFORMATION

83 7 11

O ⇒ NI5-PD

INCIDENT ANGLE	0 °	ENERGY (EV)	2.00×10^3
TARGET	POLY	REFERENCE	83 . 7
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PD / NI		

ION	O	8	16.0
TARGET	NI	28	58.7
	PD	46	106



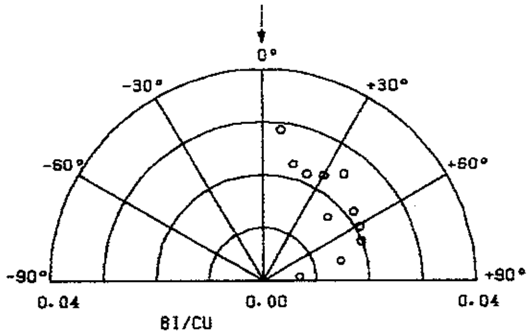
INFORMATION

89 7 12

BI ⇒ CU

INCIDENT ANGLE	0 °		ENERGY (EV)	2.00×10^{3}
TARGET	POLY		REFERENCE	83.7
ENVIRONMENT	UHV			
SPUTTERED ATOM (S)	BI / CU			

ION	BI	83	209
TARGET	CU	29	63.5



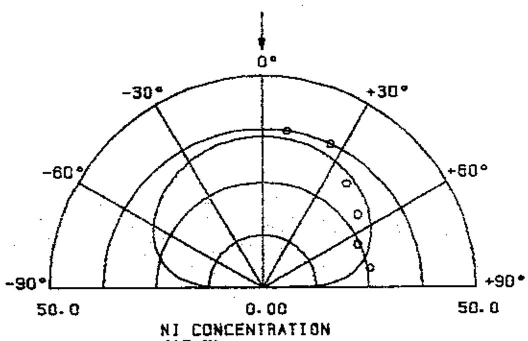
INFORMATION

84 1 1

AR ⇒ NI-CU

INCIDENT ANGLE	0 °		ENERGY (EV)	3.00×10^{3}
TARGET	POLY		EPSILON	3.24×10^{-2}
ENVIRONMENT	UHV		GAMMA	9.64×10^{-1}
SPUTTERED ATOM (S)	NI		Q	3.92×10^{-2}
			COS* N	2.80×10^{-1}
			REFERENCE	84.1

ION	AR	18	39.9
TARGET	NI	28	58.7
	CU	29	63.5



INFORMATION

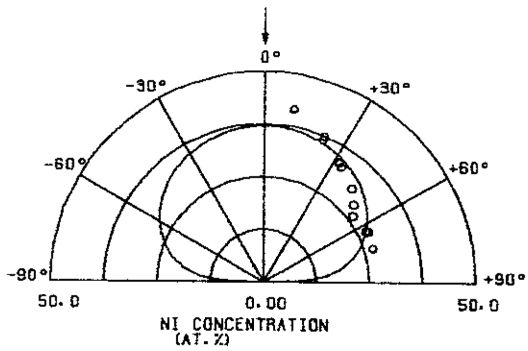
84 1 2

AR ⇒ NI-CU

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	EPSILON	3.24×10^{-2}
ENVIRONMENT	UHV	GAMMA	9.64×10^{-1}
SPUTTERED ATOM (S)	NI	Q	3.92×10^{-2}
		COS^{N} N	3.90×10^{-1}

ION	AR	18	39.9
TARGET	NI	28	58.7
	CU	29	63.5

REFERENCE 84.1



INFORMATION

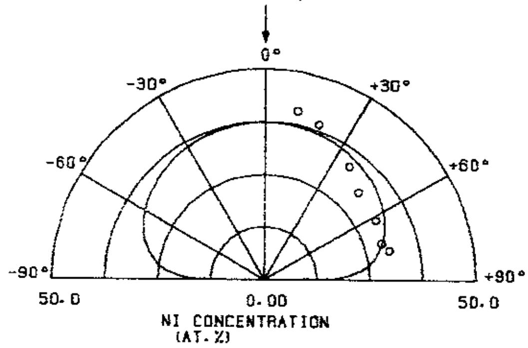
84 1 3

AR ⇒ NI-CU

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	EPSILON	3.24×10^{-2}
ENVIRONMENT	UHV	GAMMA	9.64×10^{-1}
SPUTTERED ATOM (S)	NI	Q	3.92×10^{-2}
		COS^{N} N	2.00×10^{-1}

ION	AR	18	39.9
TARGET	NI	28	58.7
	CU	29	63.5

REFERENCE 84.1



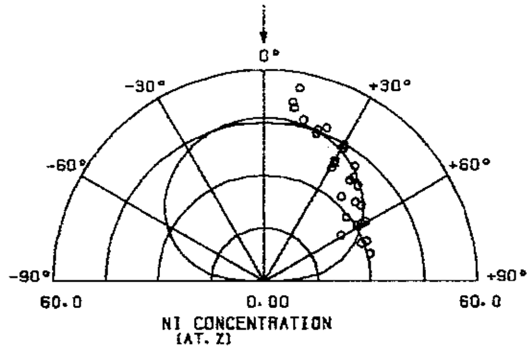
INFORMATION

84 1 4

AR ⇒ NI-CU

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	EPSILON	3.24×10^{-2}
ENVIRONMENT	UHV	GAMMA	9.64×10^{-1}
SPUTTERED ATOM (S)	NI	Q	3.92×10^{-2}
		COS* N	5.60×10^{-1}

ION	AR 18 39.9	REFERENCE	84.1
TARGET	NI 28 58.7 CU 29 63.5		



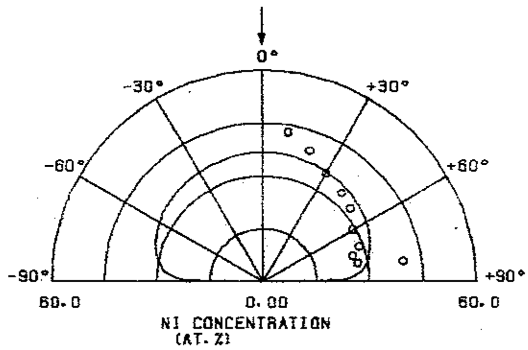
INFORMATION

84 1 5

AR ⇒ NI-CU

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	EPSILON	3.24×10^{-2}
ENVIRONMENT	UHV	GAMMA	9.64×10^{-1}
SPUTTERED ATOM (S)	NI	Q	3.92×10^{-2}
		COS* N	1.20×10^{-1}

ION	AR 18 39.9	REFERENCE	84.1
TARGET	NI 28 58.7 CU 29 63.5		



INFORMATION

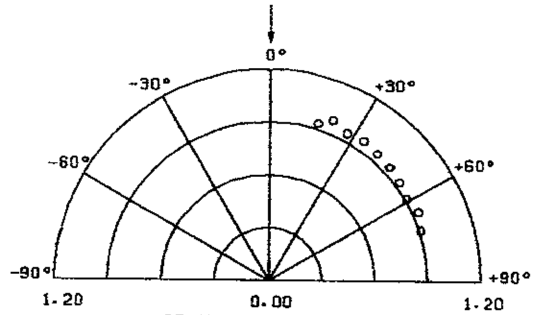
84 2 1

AR ⇒ CU-PT

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	PT / CU
ENERGY (EV)	3.00×10^{3}
REFERENCE	84 . 2

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

-196C



PT/CU NORMALIZED TO TARGET COMPOSITION

INFORMATION

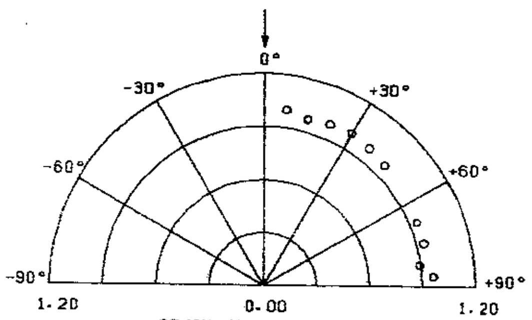
84 2 2

AR ⇒ CU-PT

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	PT / CU
ENERGY (EV)	3.00×10^{3}
REFERENCE	84 . 2

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

200C



PT/CU NORMALIZED TO TARGET COMPOSITION

119

INFORMATION

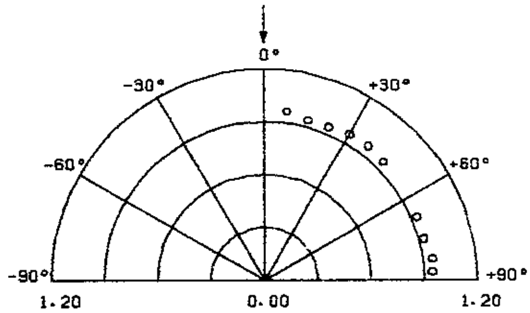
84 2 9

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00 X10^3
TARGET	POLY	REFERENCE	84.2
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

300C



PT/CU NORMALIZIET TO
TARGET COMPOSITION

INFORMATION

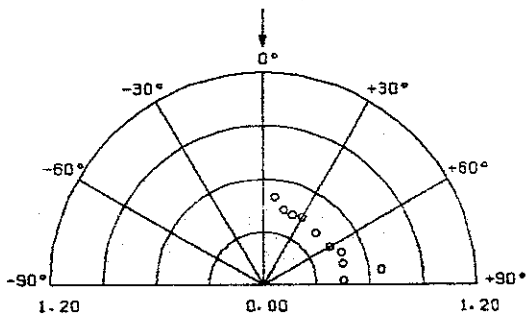
84 2 4

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00 X10^3
TARGET	POLY	REFERENCE	84.2
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

400C



PT/CU NORMALIZED TO
TARGET COMPOSITION

INFORMATION

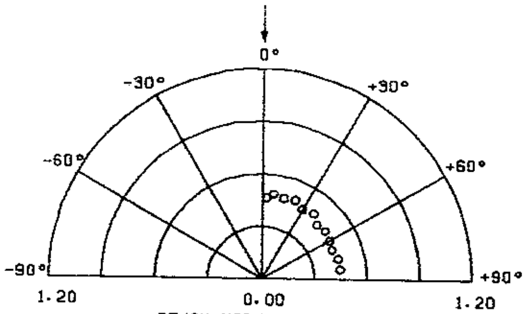
84 2 5

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00 X10^3
TARGET	POLY	REFERENCE	84.2
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

450C



PT/CU NORMALIZED TO
TARGET COMPOSITION

INFORMATION

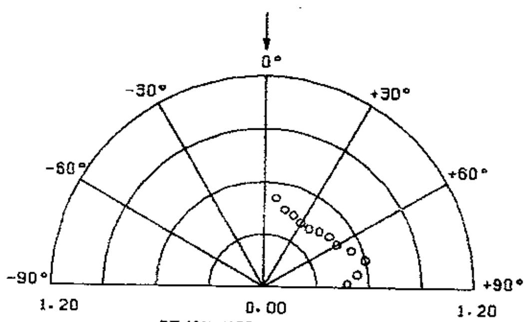
84 2 8

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00 X10^3
TARGET	POLY	REFERENCE	84.2
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

500C



PT/CU NORMALIZED TO
TARGET COMPOSITION

INFORMATION

84 2 7

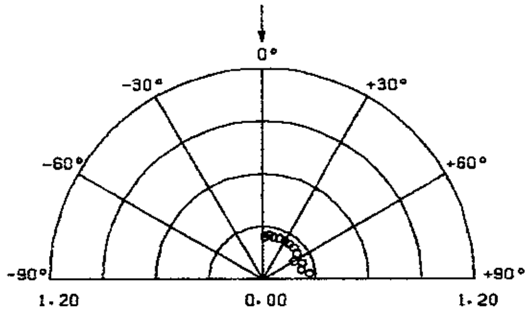
AR ⇒ CU-PT

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	PT / CU

ENERGY (EV)	3.00×10^3
REFERENCE	84.2

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

550C



PT/CU NORMALIZED TO TARGET COMPOSITION

INFORMATION

84 2 8

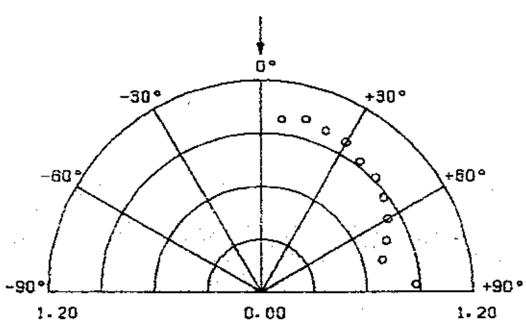
AR ⇒ CU-PT

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	PT / CU

ENERGY (EV)	3.00×10^3
REFERENCE	84.2

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

-196C



PT/CU NORMALIZED TO TARGET COMPOSITION

INFORMATION

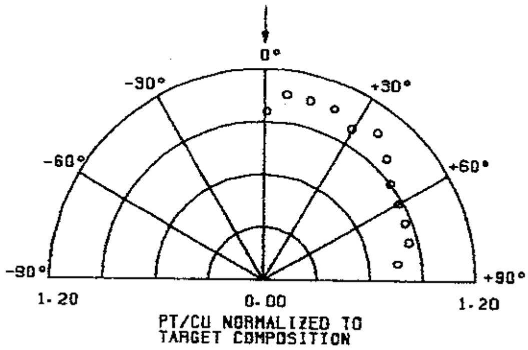
84 2 9

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^3
TARGET	POLY	REFERENCE	84.2
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

200C



INFORMATION

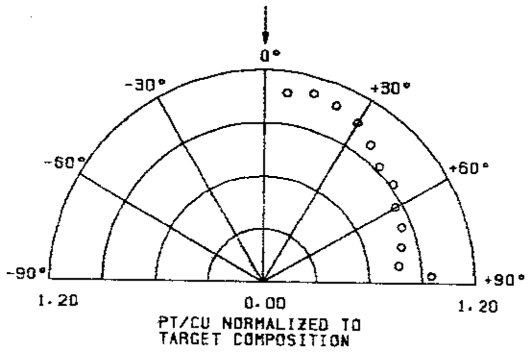
84 2 10

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^3
TARGET	POLY	REFERENCE	84.2
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

300C



INFORMATION

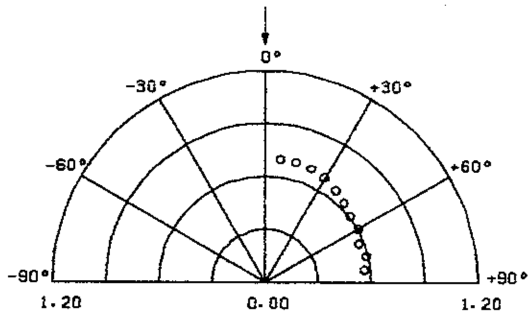
84 2 11

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	REFERENCE	84.2
ENVIRONMENT	UHV		
SPUTTERED ATOM(S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

400C



PT/CU NORMALIZED TO TARGET COMPOSITION

INFORMATION

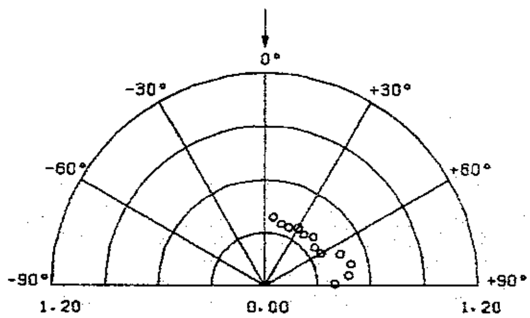
84 2 12

AR ⇒ CU-PT

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{3}
TARGET	POLY	REFERENCE	84.2
ENVIRONMENT	UHV		
SPUTTERED ATOM(S)	PT / CU		

ION	AR	18	39.9
TARGET	CU	29	63.5
	PT	78	195

500C



PT/CU NORMALIZED TO TARGET COMPOSITION

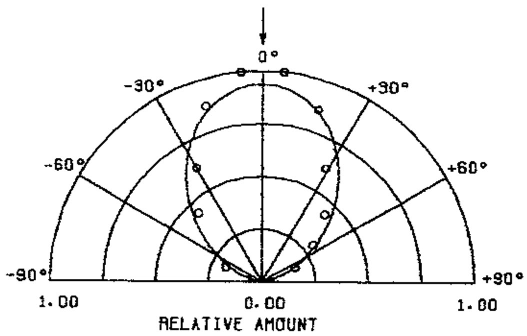
INFORMATION

84 9 1

AU ⇒ CU

INCIDENT ANGLE	0 °	ENERGY (EV)	1.25×10^{5}
TARGET	POLY	EPSILON	9.26×10^{-2}
ENVIRONMENT	UHV	GAMMA	7.38×10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.15×10^{-3}
		COS* N	1.99
ION	AU 79 197	REFERENCE	84 . 3
TARGET	CU 29 63.5		

PIXE



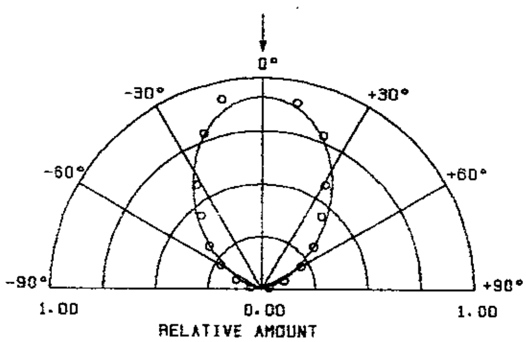
INFORMATION

84 9 2

AU ⇒ CU

INCIDENT ANGLE	0 °	ENERGY (EV)	1.25×10^{5}
TARGET	POLY	EPSILON	9.26×10^{-2}
ENVIRONMENT	UHV	GAMMA	7.38×10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.15×10^{-3}
		COS* N	2.35
ION	AU 79 197	REFERENCE	84 . 3
TARGET	CU 29 63.5		

RBS



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INFORMATION

84 5 3

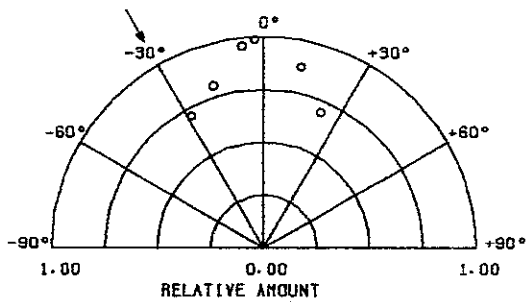
AU ⇒ CU

INCIDENT ANGLE	30°		ENERGY (EV)	1.25×10^{5}
TARGET	POLY		EPSILON	9.26×10^{-2}
ENVIRONMENT	UHV		GAMMA	7.38×10^{-1}
SPUTTERED ATOM(S)	CU		Q	6.15×10^{-3}
			EJECTION ANGLE EXP.	0.00°
			CAL.	61.1°

ION	AU	79	197
TARGET	CU	29	63.5

REFERENCE 84.3

PIXE



INFORMATION

84 5 4

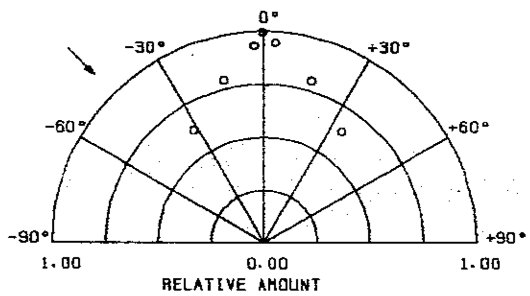
AU ⇒ CU

INCIDENT ANGLE	45°		ENERGY (EV)	1.25×10^{5}
TARGET	POLY		EPSILON	9.26×10^{-2}
ENVIRONMENT	UHV		GAMMA	7.38×10^{-1}
SPUTTERED ATOM(S)	CU		Q	6.15×10^{-3}
			EJECTION ANGLE EXP.	0.00°
			CAL.	45.8°

ION	AU	79	197
TARGET	CU	29	63.5

REFERENCE 84.3

PIXE



INFORMATION

84 3 5

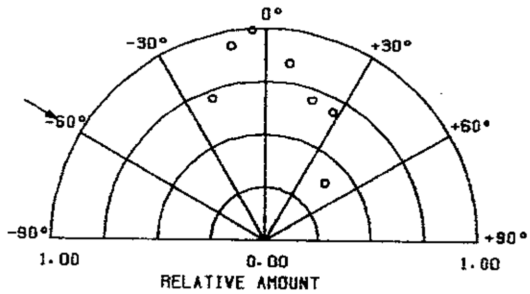
AU ⇒ CU

INCIDENT ANGLE	60°	ENERGY (EV)	1.25×10^{5}
TARGET	POLY	EPSILON	9.26×10^{-2}
ENVIRONMENT	UHV	GAMMA	7.38×10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.15×10^{-3}
		EJECTION ANGLE EXP.	30.0°
		CAL.	30.6°

ION	AU	79	197
TARGET	CU	29	63.5

REFERENCE 84.3

PIXE



INFORMATION

84 3 6

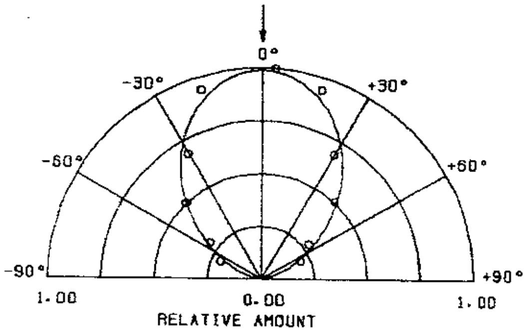
AU ⇒ CU

INCIDENT ANGLE	0°	ENERGY (EV)	1.25×10^{5}
TARGET	POLY	EPSILON	9.26×10^{-2}
ENVIRONMENT	UHV	GAMMA	7.38×10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.15×10^{-3}
		$\cos^{N}$ N	2.01

ION	AU	79	197
TARGET	CU	29	63.5

REFERENCE 84.3

PIXE



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INFORMATION

84 9 7

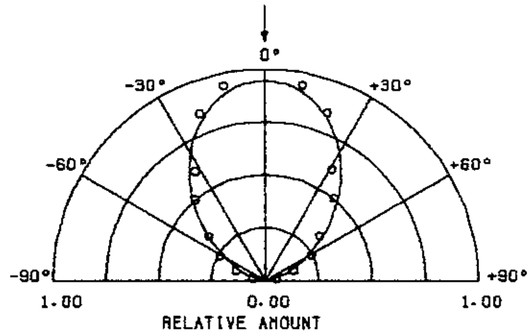
AU ⇒ CU

INCIDENT ANGLE	0 °		ENERGY (EV)	1.25×10^{5}
TARGET	POLY		EPSILON	9.26×10^{-2}
ENVIRONMENT	UHV		GAMMA	7.38×10^{-1}
SPUTTERED ATOM (S)	CU		Q	6.15×10^{-3}
			COS^{N} N	2.14

ION	AU	79	197
TARGET	CU	29	63.5

REFERENCE 84.3

RBS



INFORMATION

84 9 8

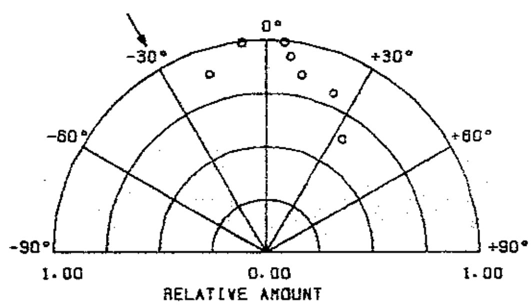
AU ⇒ CU

INCIDENT ANGLE	30°		ENERGY (EV)	1.25×10^{5}
TARGET	POLY		EPSILON	9.26×10^{-2}
ENVIRONMENT	UHV		GAMMA	7.38×10^{-1}
SPUTTERED ATOM (S)	CU		Q	6.15×10^{-3}
			EJECTION ANGLE EXP.	0.00°
			CAL.	61.1°

ION	AU	79	197
TARGET	CU	29	63.5

REFERENCE 84.3

PIXE



INFORMATION

84 3 9

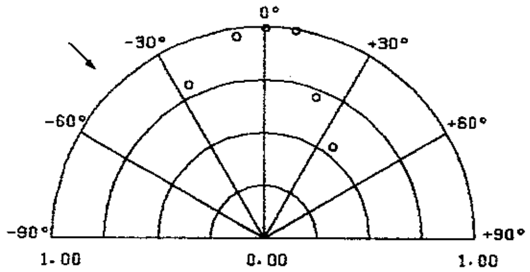
AU ⇒ CU

INCIDENT ANGLE	45°	ENERGY (EV)	1.25×10^{5}
TARGET	POLY	EPSILON	9.26×10^{-2}
ENVIRONMENT	UHV	GAMMA	7.38×10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.15×10^{-3}
		EJECTION ANGLE EXP.	0.00°
		CAL.	45.8°

ION	AU	79	197
TARGET	CU	29	63.5

REFERENCE 84.3

PIXE



INFORMATION

84 3 10

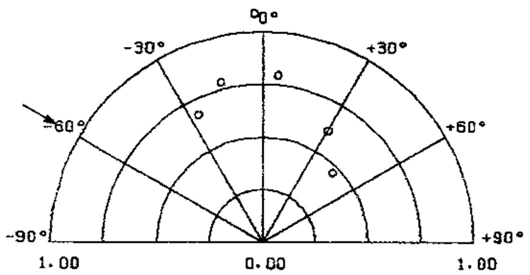
AU ⇒ CU

INCIDENT ANGLE	60°	ENERGY (EV)	1.25×10^{5}
TARGET	POLY	EPSILON	9.26×10^{-2}
ENVIRONMENT	UHV	GAMMA	7.38×10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.15×10^{-3}
		EJECTION ANGLE EXP.	0.00°
		CAL.	30.6°

ION	AU	79	197
TARGET	CU	29	63.5

REFERENCE 84.3

PIXE



INFORMATION

85 2 1

AR ⇒ AU

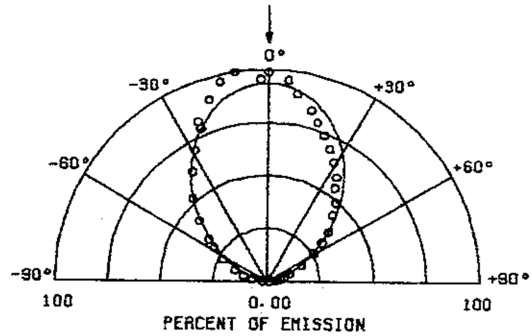
INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	AU

ION	AR	18	39.9
TARGET	AU	79	197

ENERGY (EV)	5.00×10^{5}
EPSILON	2.14
GAMMA	5.61×10^{-1}
Q	3.69×10^{-3}
COS^{N} N	2.02

REFERENCE 85.2

D=1.3 N=3.3 F=1.4E+18 ION/SQ.CM



INFORMATION

85 2 2

AR ⇒ AU

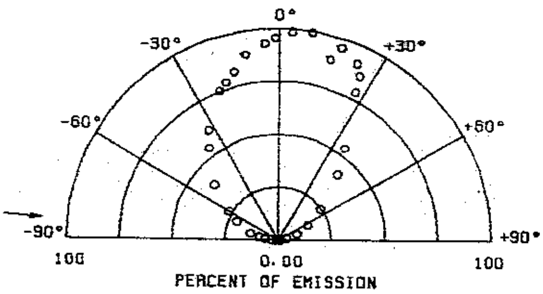
INCIDENT ANGLE	85°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	AU

ION	AR	18	39.9
TARGET	AU	79	197

ENERGY (EV)	5.00×10^{5}
EPSILON	2.14
GAMMA	5.61×10^{-1}
Q	3.69×10^{-3}
EJECTION ANGLE	
EXP.	10.08
CAL.	5.32°

REFERENCE 85.2

D=0.5 N=1.4 F=5.4E+18 ION/SQ.CM



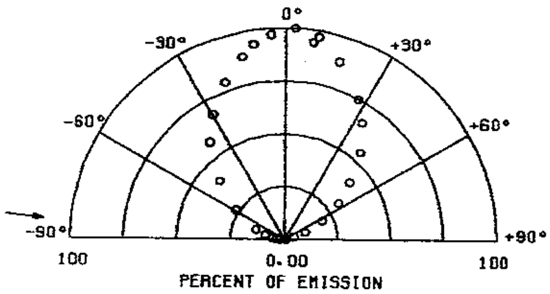
INFORMATION

85 2 3

AR ⇒ AU

INCIDENT ANGLE	85°		ENERGY (EV)	1.50×10^{5}
TARGET	POLY		EPSILON	6.41×10^{-1}
ENVIRONMENT	UHV		GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU		Q	6.73×10^{-3}
			EJECTION ANGLE EXP.	5.00°
ION	AR 18	39.9	CAL.	5.58°
TARGET	AU 79	197	REFERENCE	85.2

D=0.5 F=2.6E+16 ION/SQ.CM



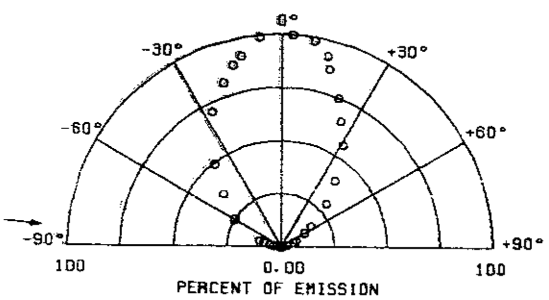
INFORMATION

85 2 4

AR ⇒ AU

INCIDENT ANGLE	85°		ENERGY (EV)	9.00×10^{5}
TARGET	POLY		EPSILON	3.84
ENVIRONMENT	UHV		GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU		Q	2.75×10^{-3}
			EJECTION ANGLE EXP.	5.00°
ION	AR 18	39.9	CAL.	5.24°
TARGET	AU 79	197	REFERENCE	85.2

D=0.5 N=1.3 F=5.7E+16 ION/SQ.CM



131

INFORMATION

85 2 5

XE ⇒ AU

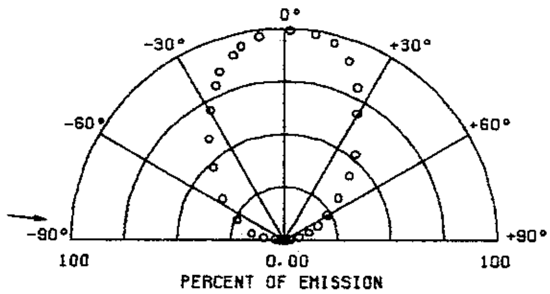
INCIDENT ANGLE	85°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM(S)	AU

ION	XE	54	131
TARGET	AU	79	197

ENERGY (EV)	2.00×10^{5}
EPSILON	1.81×10^{-1}
GAMMA	9.60×10^{-1}
Q	4.45×10^{-3}
EJECTION ANGLE EXP.	5.00°
CAL.	5.38°

REFERENCE 85.2

D=0.5 N=1.4 F=1.6E+16 IONS/SQ.CM



INFORMATION

85 2 6

AR ⇒ CU

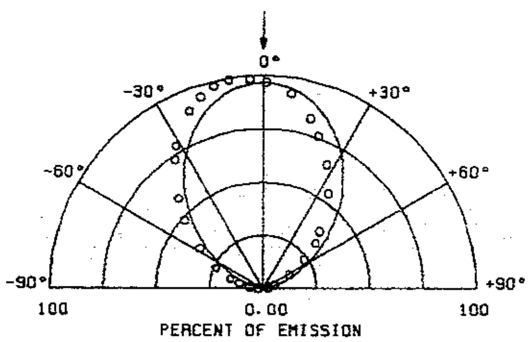
INCIDENT ANGLE	0°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM(S)	CU

ION	AR	18	39.9
TARGET	CU	29	63.5

ENERGY (EV)	5.00×10^{5}
EPSILON	5.35
GAMMA	9.48×10^{-1}
Q	2.71×10^{-3}
COS^{N} N	1.99

REFERENCE 85.2

D=4.4 N=1.6 F=7.4E+18 IONS/SQ.CM



INFORMATION

85 2 7

AR ⇒ CU

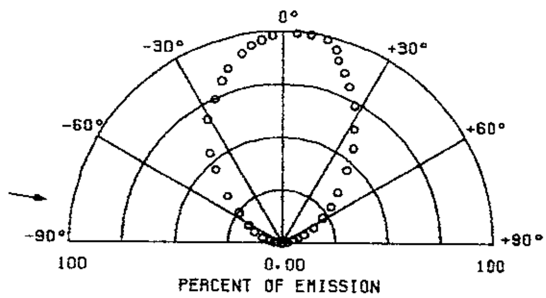
INCIDENT ANGLE	80°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	CU

ION	AR	18	39.9
TARGET	CU	29	63.5

ENERGY (EV)	5.00×10^{5}
EPSILON	5.35
GAMMA	9.48×10^{-1}
Q	2.71×10^{-9}
EJECTION ANGLE EXP.	10.08
CAL.	10.2°

REFERENCE 85 - 2

D=3.2 N=1.7 F=1.0E+18 IONS/SQ.CM



INFORMATION

85 2 8

AR ⇒ CU

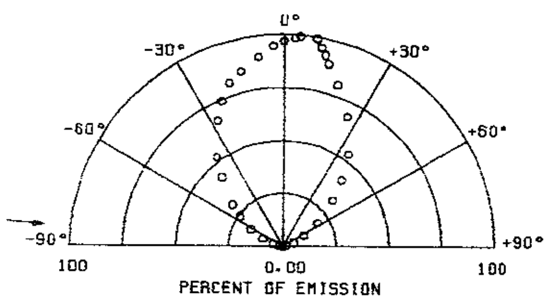
INCIDENT ANGLE	85°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	CU

ION	AR	18	39.9
TARGET	CU	29	63.5

ENERGY (EV)	5.00×10^{5}
EPSILON	5.35
GAMMA	9.48×10^{-1}
Q	2.71×10^{-9}
EJECTION ANGLE EXP.	5.00°
CAL.	5.23°

REFERENCE 85 - 2

D=0.2 N=0.6 F=5.8E+16 IONS/SQ.CM



INFORMATION

85 2 9

AR ⇒ CU

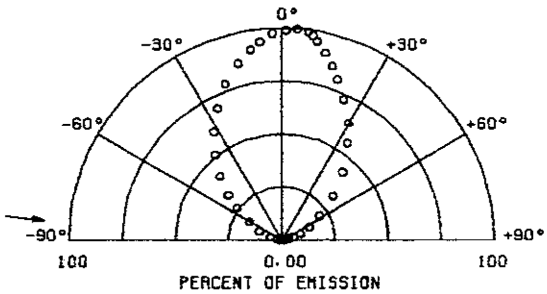
INCIDENT ANGLE	85°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	CU

ION	AR	18	39.9
TARGET	CU	29	63.5

ENERGY (EV)	1.50×10^{5}
EPSILON	1.61
GAMMA	9.48×10^{-1}
Q	4.95×10^{-3}
EJECTION ANGLE EXP.	5.00°
EJECTION ANGLE CAL.	5.43°

REFERENCE 85.2

Q=0.1 N=1.3 F=2.3E+16 IONS/SQ.CM



INFORMATION

85 2 10

AR ⇒ CU

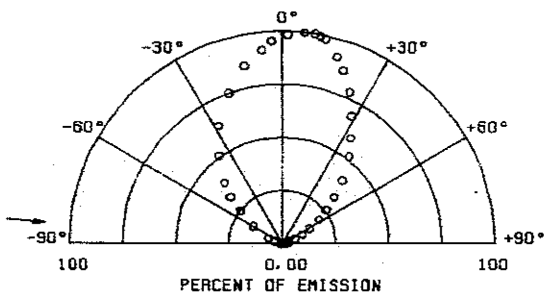
INCIDENT ANGLE	85°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	CU

ION	AR	18	39.9
TARGET	CU	29	63.5

ENERGY (EV)	9.00×10^{5}
EPSILON	9.63
GAMMA	9.48×10^{-1}
Q	2.02×10^{-3}
EJECTION ANGLE EXP.	5.00°
EJECTION ANGLE CAL.	5.17°

REFERENCE 85.2

Q=0.3 N=0.8 F=9.3E+16 IONS/SQ.CM



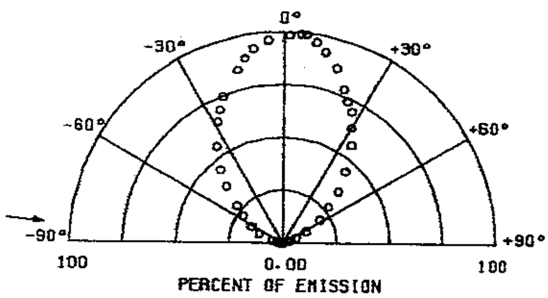
INFORMATION

85 2 11

XE ⇒ CU

INCIDENT ANGLE	85°		ENERGY (EV)	2.00×10^{5}
TARGET	POLY		EPSILON	3.14×10^{-1}
ENVIRONMENT	UHV		GAMMA	8.79×10^{-1}
SPUTTERED ATOM (S)	CU		Q	4.46×10^{-3}
ION	XE 54	131	EJECTION ANGLE EXP.	5.00°
TARGET	CU 29	63.5	CAL.	5.38°
			REFERENCE	85.2

D=0.5 N=1.4 F=4.4E+16 IONS/SQ.CM



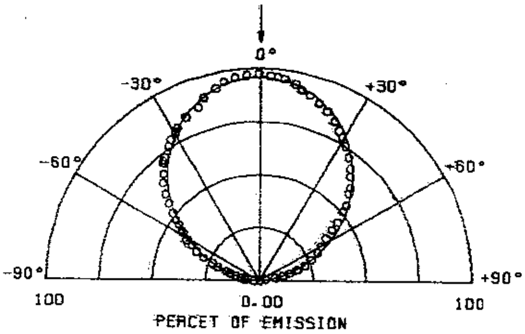
INFORMATION

85 2 12

AR ⇒ ZR

INCIDENT ANGLE	0°		ENERGY (EV)	5.00×10^{5}
TARGET	POLY		EPSILON	4.12
ENVIRONMENT	UHV		GAMMA	8.47×10^{-1}
SPUTTERED ATOM (S)	ZR		Q	3.84×10^{-9}
			COS^{N} N	1.33
ION	AR 18	39.9		
TARGET	ZR 40	91.2	REFERENCE	85.2

D=0.3 MICRO-METER N=3.5
F=6.0E+16 IONS/SQ.CM



INFORMATION

85 2 13

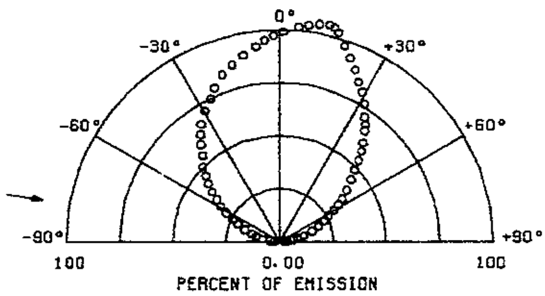
AR ⇒ ZR

INCIDENT ANGLE	80°		ENERGY (EV)	5.00×10^{5}
TARGET	POLY		EPSILON	4.12
ENVIRONMENT	UHV		GAMMA	8.47×10^{-1}
SPUTTERED ATOM (S)	ZR		Q	3.84×10^{-3}
			EJECTION ANGLE EXP.	11.0°
			CAL.	10.3°

ION	AR	18	39.9
TARGET	ZR	40	91.2

REFERENCE 85.2

D=4.2 MICRO-METER N=1.7
F=2.8E+18 IONS/SQ.CM



INFORMATION

85 2 14

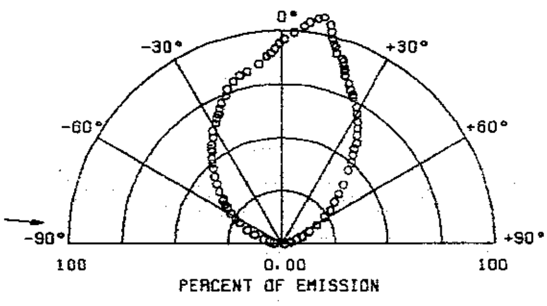
AR ⇒ ZR

INCIDENT ANGLE	85°		ENERGY (EV)	5.00×10^{5}
TARGET	POLY		EPSILON	4.12
ENVIRONMENT	UHV		GAMMA	8.47×10^{-1}
SPUTTERED ATOM (S)	ZR		Q	3.84×10^{-3}
			EJECTION ANGLE EXP.	9.00°
			CAL.	5.33°

ION	AR	18	39.9
TARGET	ZR	40	91.2

REFERENCE 85.2

D=0.1 MICRO-METER N=3.5
F=6.0E+16 IONS/SQ.CM



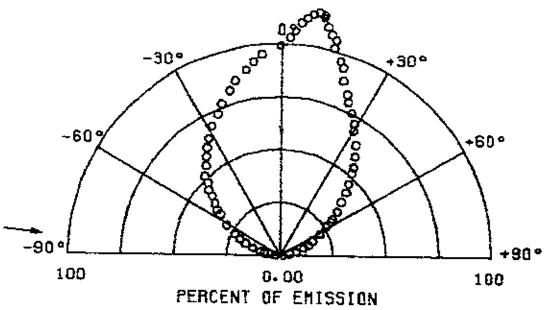
INFORMATION

85 2 15

AR ⇒ ZR

INCIDENT ANGLE	85°		ENERGY (EV)	1.50×10^{5}
TARGET	POLY		EPSILON	1.24
ENVIRONMENT	UHV		GAMMA	8.47×10^{-1}
SPUTTERED ATOM (S)	ZR		Q	7.01×10^{-3}
			EJECTION ANGLE EXP.	9.00°
ION	AR 18	39.9	CAL.	5.60°
TARGET	ZR 40	91.2	REFERENCE	85.2

D=0.08 MICRO-METER N=2.2
F=4.1E+16 IONS/SQ.CM



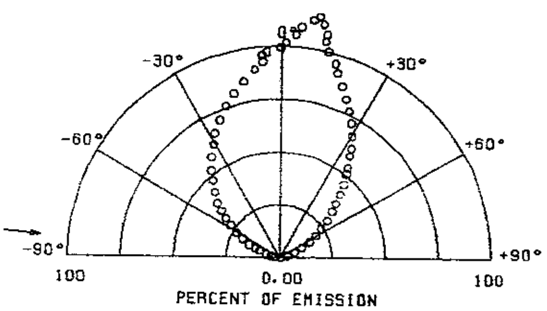
INFORMATION

85 2 16

AR ⇒ ZR

INCIDENT ANGLE	85°		ENERGY (EV)	9.00×10^{5}
TARGET	POLY		EPSILON	7.41
ENVIRONMENT	UHV		GAMMA	8.47×10^{-1}
SPUTTERED ATOM (S)	ZR		Q	2.86×10^{-3}
			EJECTION ANGLE EXP.	8.00°
ION	AR 18	39.9	CAL.	5.25°
TARGET	ZR 40	91.2	REFERENCE	85.2

D=0.1 MICRO-METER N=3.3
F=7.0E+16 IONS/SQ.CM



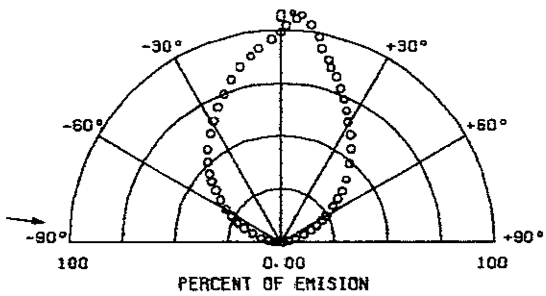
INFORMATION

85 2 17

XE ⇒ ZR

INCIDENT ANGLE	85°	ENERGY (EV)	2.00×10^{5}
TARGET	POLY	EPSILON	2.74×10^{-1}
ENVIRONMENT	UHV	GAMMA	9.68×10^{-1}
SPUTTERED ATOM (S)	ZR	Q	5.68×10^{-3}
		EJECTION ANGLE EXP.	5.00°
		CAL.	5.49°
ION	XE 54 131	REFERENCE	85.2
TARGET	ZR 40 91.2		

D=0.05 MICRO-METER N=1.1
F=6.6E+15 IONS/SQ.CM



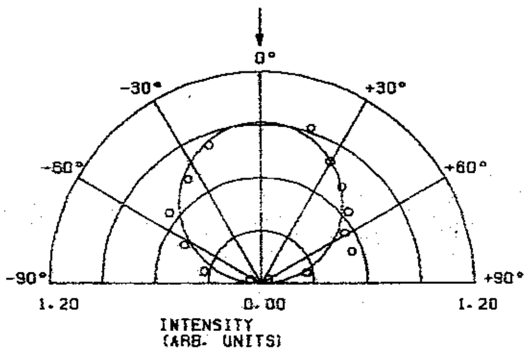
INFORMATION

85 3 1

NE ⇒ AG

INCIDENT ANGLE	0°	ENERGY (EV)	3.00×10^{4}
TARGET	POLY	EPSILON	4.70×10^{-1}
ENVIRONMENT	HV	GAMMA	5.31×10^{-1}
SPUTTERED ATOM (S)	AG	Q	1.36×10^{-2}
		COS^{N} N	9.80×10^{-1}
ION	NE 10 20.2	REFERENCE	85.3
TARGET	AG 47 108		

10E-5TORR 1.0E+19 IONS/SQ.CM



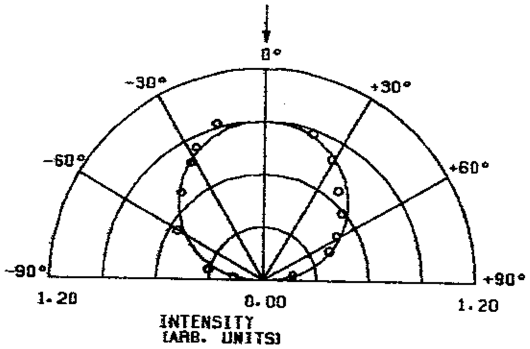
INFORMATION

85 3 2

AR ⇒ AG

INCIDENT ANGLE	0 °		ENERGY (EV)	2.00×10^{4}
TARGET	POLY		EPSILON	1.42×10^{-1}
ENVIRONMENT	HV		GAMMA	7.89×10^{-1}
SPUTTERED ATOM (S)	AG		Q	1.37×10^{-2}
			COS^{n} N	8.40×10^{-1}
ION	AR	18 39.9	REFERENCE	85.3
TARGET	AG	47 108		

2.0E+19 IONS/SQ.CM



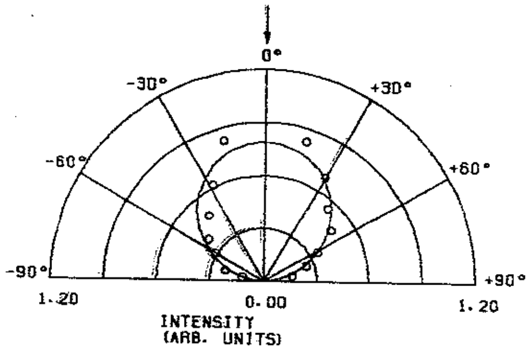
INFORMATION

85 3 3

KR ⇒ AG

INCIDENT ANGLE	0 °		ENERGY (EV)	2.00×10^{4}
TARGET	POLY		EPSILON	5.00×10^{-2}
ENVIRONMENT	HV		GAMMA	9.84×10^{-1}
SPUTTERED ATOM (S)	AG		Q	1.22×10^{-2}
			COS^{n} N	1.15
ION	KR	36 83.8	REFERENCE	85.3
TARGET	AG	47 108		

1.0E+19 IONS/SQ.CM



INFORMATION

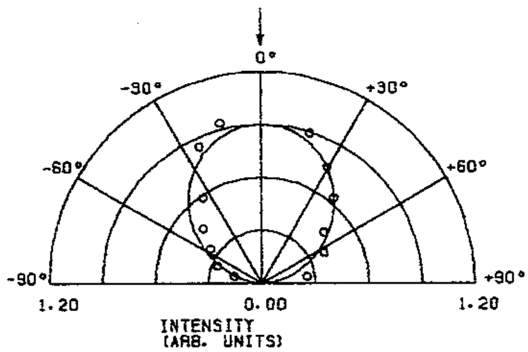
85 9 4

XE ⇒ AG

INCIDENT ANGLE	0 °	ENERGY (EV)	3.00×10^{4}
TARGET	POLY	EPSILON	3.75×10^{-2}
ENVIRONMENT	HV	GAMMA	9.90×10^{-1}
SPUTTERED ATOM (S)	AG	Q	9.96×10^{-3}
		COS^{N} N	1.31

ION	XE	54	131	REFERENCE	85.3
TARGET	AG	47	108		

7.8E+18 IONS/SQ.CM



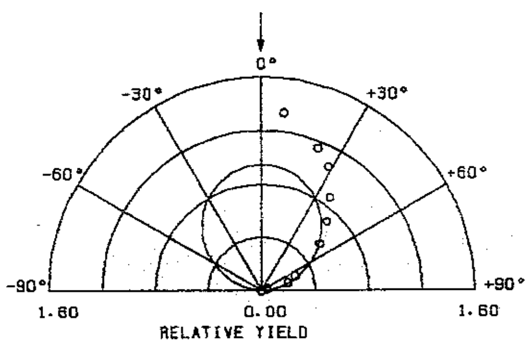
INFORMATION

85 4 1

AR ⇒ GE

INCIDENT ANGLE	0 °	ENERGY (EV)	8.00×10^{4}
TARGET	POLY	EPSILON	7.99×10^{-1}
ENVIRONMENT	UHV	GAMMA	9.16×10^{-1}
SPUTTERED ATOM (S)	GE	Q	7.25×10^{-3}
		COS^{N} N	1.17

ION	AR	18	39.9	REFERENCE	85.4
TARGET	GE	32	72.5		



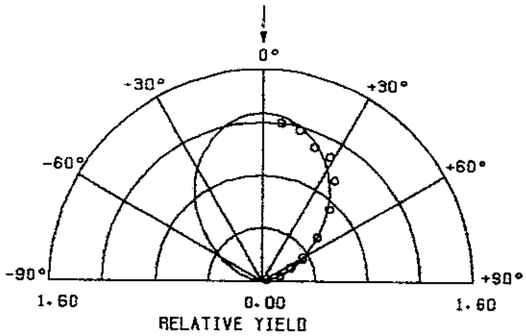
INFORMATION

85 4 2

AR ⇒ CU

INCIDENT ANGLE	0 °	ENERGY (EV)	8.00×10^{4}
TARGET	POLY	EPSILON	8.56×10^{-1}
ENVIRONMENT	UHV	GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.78×10^{-3}
		COS^{N} N	1.82

ION	AR	18	39.9	REFERENCE	85.4
TARGET	CU	29	63.5		



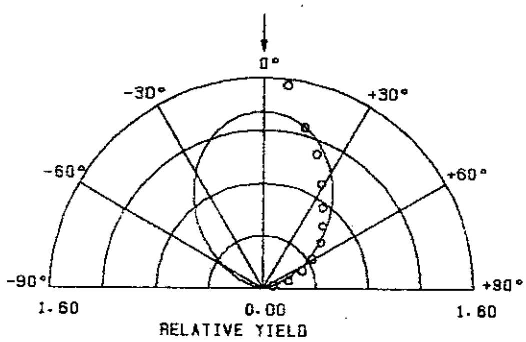
INFORMATION

85 4 3

AR ⇒ PT

INCIDENT ANGLE	0 °	ENERGY (EV)	8.00×10^{4}
TARGET	POLY	EPSILON	3.47×10^{-1}
ENVIRONMENT	UHV	GAMMA	5.64×10^{-1}
SPUTTERED ATOM (S)	PT	Q	1.14×10^{-2}
		COS^{N} N	1.96

ION	AR	18	39.9	REFERENCE	85.4
TARGET	PT	78	195		



INFORMATION

85 5 1

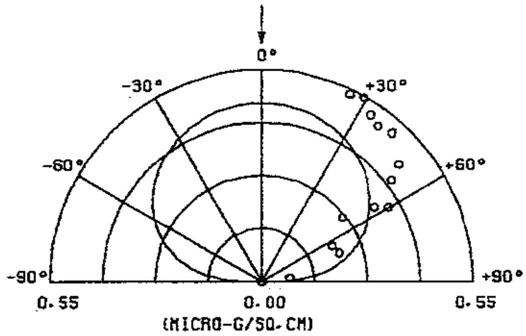
AR ⇒ AU

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	AU

ION	AR	18	39.9
TARGET	AU	79	197

ENERGY (EV)	2.30×10^{3}
EPSILON	9.83×10^{-3}
GAMMA	5.61×10^{-1}
Q	5.44×10^{-2}
COS* N	5.40×10^{-1}

REFERENCE 85.5



INFORMATION

85 5 2

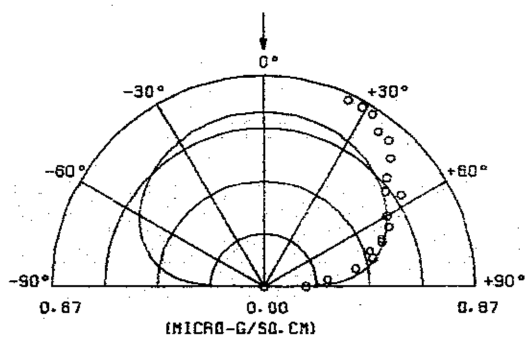
AR ⇒ AU

INCIDENT ANGLE	0 °
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	AU

ION	AR	18	39.9
TARGET	AU	79	197

ENERGY (EV)	5.00×10^{3}
EPSILON	2.14×10^{-2}
GAMMA	5.61×10^{-1}
Q	3.69×10^{-2}
COS* N	3.00×10^{-1}

REFERENCE 85.5

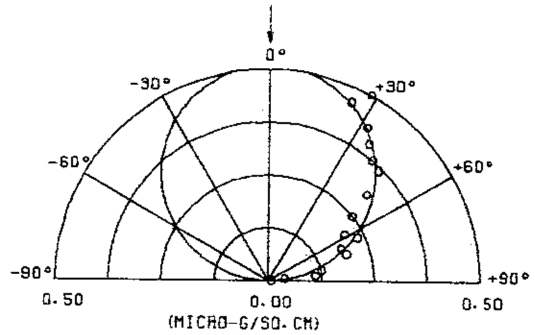


INFORMATION

85 5 3

AR ⇒ AU

INCIDENT ANGLE	0 °			ENERGY (EV)	7.80×10^{3}
TARGET	POLY			EPSILON	3.33×10^{-2}
ENVIRONMENT	UHV			GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU			Q	2.95×10^{-2}
				$\cos^{N}$ N	1.04
ION	AR	18	39.9		
TARGET	AU	79	197	REFERENCE	85.5



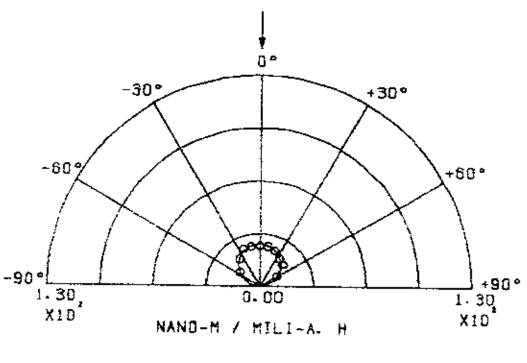
INFORMATION

85 11 1

N ⇒ SI-N

INCIDENT ANGLE	0 °			ENERGY (EV)	1.00×10^{4}
TARGET	POLY			EPSILON	8.13×10^{-1}
ENVIRONMENT	UHV			GAMMA	8.88×10^{-1}
SPUTTERED ATOM (S)	SI			Q	2.29×10^{-2}
				$\cos^{N}$ N	1.03
ION	N	7	14.0		
TARGET	SI	14	28.1	REFERENCE	85.11
	N	7	14.0		

SI



INFORMATION

85 11 2

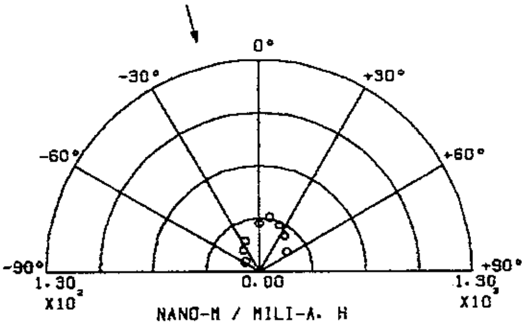
N ⇒ SI-N

INCIDENT ANGLE	15°		ENERGY (EV)	1.00×10^{4}
TARGET	POLY		EPSILON	8.13×10^{-1}
ENVIRONMENT	UHV		GAMMA	8.88×10^{-1}
SPUTTERED ATOM (S)	SI		Q	2.29×10^{-2}
			EJECTION ANGLE EXP.	83.7°
			CAL.	90.0°

ION	N	7	14.0
TARGET	SI	14	28.1
	N	7	14.0

REFERENCE 85.11

SI



INFORMATION

85 11 3

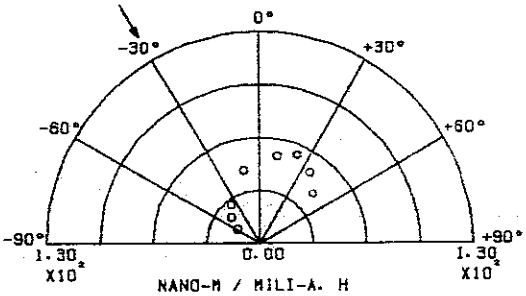
N ⇒ SI-N

INCIDENT ANGLE	30°		ENERGY (EV)	1.00×10^{4}
TARGET	POLY		EPSILON	8.13×10^{-1}
ENVIRONMENT	UHV		GAMMA	8.88×10^{-1}
SPUTTERED ATOM (S)	SI		Q	2.29×10^{-2}
			EJECTION ANGLE EXP.	83.7°
			CAL.	64.2°

ION	N	7	14.0
TARGET	SI	14	28.1
	N	7	14.0

REFERENCE 85.11

SI



INFORMATION

85 11 4

N ⇒ SI-N

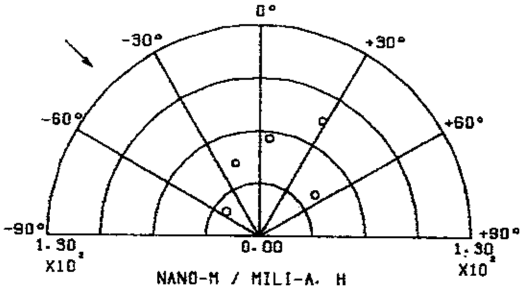
INCIDENT ANGLE	45°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	SI

ION	N	7	14.0
TARGET	SI	14	28.1
	N	7	14.0

ENERGY (EV)	1.00×10^{4}
EPSILON	8.13×10^{-1}
GAMMA	8.88×10^{-1}
Q	2.29×10^{-2}
EJECTION ANGLE EXP.	53.3°
EJECTION ANGLE CAL.	47.8°

REFERENCE 85.11

SI



INFORMATION

85 11 5

N ⇒ SI-N

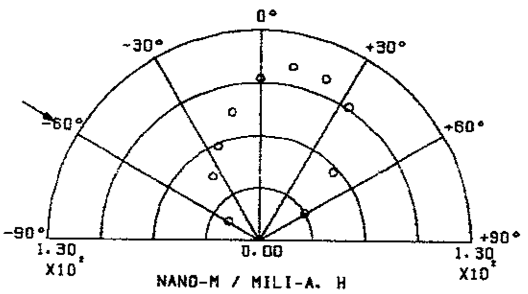
INCIDENT ANGLE	60°
TARGET	POLY
ENVIRONMENT	UHV
SPUTTERED ATOM (S)	SI

ION	N	7	14.0
TARGET	SI	14	28.1
	N	7	14.0

ENERGY (EV)	1.00×10^{4}
EPSILON	8.13×10^{-1}
GAMMA	8.88×10^{-1}
Q	2.29×10^{-2}
EJECTION ANGLE EXP.	33.9°
EJECTION ANGLE CAL.	32.3°

REFERENCE 85.11

SI



INFORMATION

85 11 6

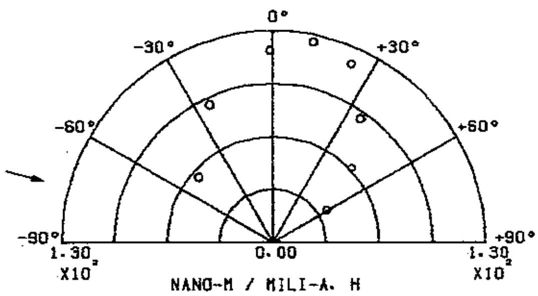
N ⇒ SI-N

INCIDENT ANGLE	75°	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	EPSILON	8.13×10^{-1}
ENVIRONMENT	UHV	GAMMA	8.88×10^{-1}
SPUTTERED ATOM (S)	SI	Q	2.29×10^{-2}
		EJECTION ANGLE EXP.	23.8°
		CAL.	17.0°

ION	N	7	14.0
TARGET	SI	14	28.1
	N	7	14.0

REFERENCE 85.11

SI



INFORMATION

85 11 7

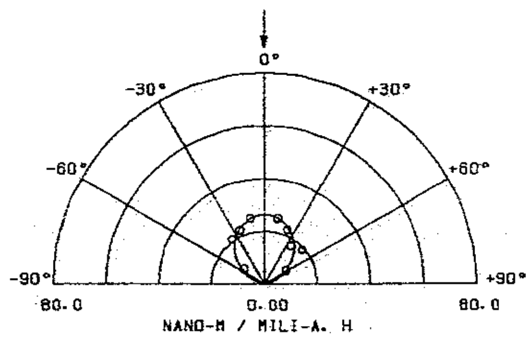
N ⇒ SI-N

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	EPSILON	1.39
ENVIRONMENT	UHV	GAMMA	8.88×10^{-1}
SPUTTERED ATOM (S)	N	Q	2.22×10^{-2}
		COS * N	1.57

ION	N	7	14.0
TARGET	SI	14	28.1
	N	7	14.0

REFERENCE 85.11

N



INFORMATION

85 11 8

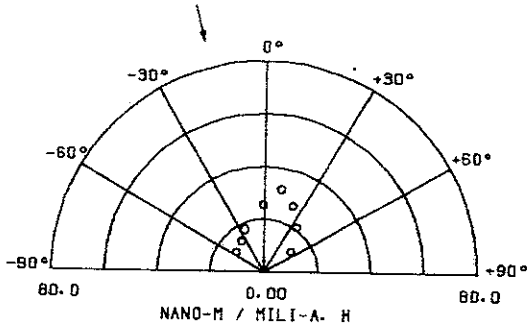
N ⇒ SI-N

INCIDENT ANGLE	15°	ENERGY (EV)	1.00 X10^{4}
TARGET	POLY	EPSILON	1.39
ENVIRONMENT	UHV	GAMMA	8.88 X10^{-1}
SPUTTERED ATOM (S)	N	Q	2.22 X10^{-2}
		EJECTION ANGLE EXP.	11.4°
		CAL.	87.8°

ION	N	7	14.0
TARGET	SI	14	28.1
	N	7	14.0

REFERENCE 85.11

N



INFORMATION

85 11 9

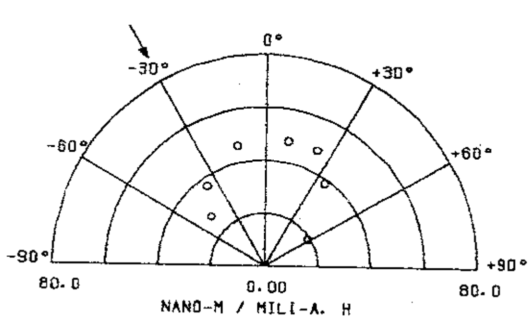
N ⇒ SI-N

INCIDENT ANGLE	30°	ENERGY (EV)	1.00 X10^{4}
TARGET	POLY	EPSILON	1.39
ENVIRONMENT	UHV	GAMMA	8.88 X10^{-1}
SPUTTERED ATOM (S)	N	Q	2.22 X10^{-2}
		EJECTION ANGLE EXP.	23.8°
		CAL.	64.1°

ION	N	7	14.0
TARGET	SI	14	28.1
	N	7	14.0

REFERENCE 85.11

N



147

INFORMATION

85 11 10

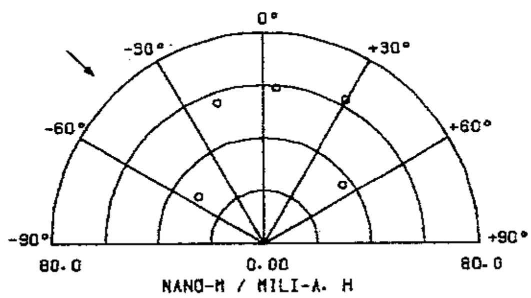
N ⇒ SI-N

INCIDENT ANGLE	45°	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	EPSILON	1.39
ENVIRONMENT	UHV	GAMMA	8.88×10^{-1}
SPUTTERED ATOM(S)	N	Q	2.22×10^{-2}
		EJECTION ANGLE EXP.	53.3°
		CAL.	47.8°

ION	N	7	14.0
TARGET	SI	14	28.1
	N	7	14.0

REFERENCE 85.11

N



INFORMATION

85 11 11

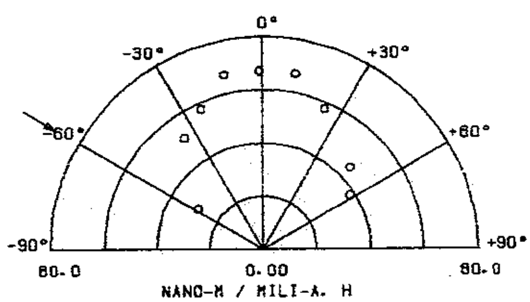
N ⇒ SI-N

INCIDENT ANGLE	60°	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	EPSILON	1.39
ENVIRONMENT	UHV	GAMMA	8.88×10^{-1}
SPUTTERED ATOM(S)	N	Q	2.22×10^{-2}
		EJECTION ANGLE EXP.	46.7°
		CAL.	32.2°

ION	N	7	14.0
TARGET	SI	14	28.1
	N	7	14.0

REFERENCE 85.11

N



INFORMATION

85 11 12

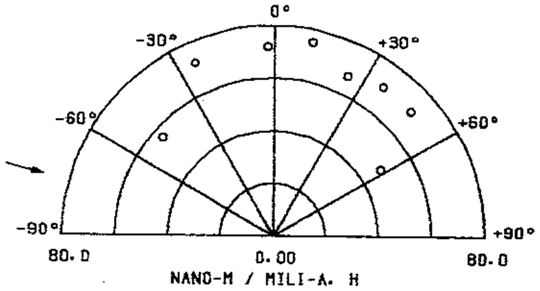
N ⇒ SI-N

INCIDENT ANGLE	75°	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	EPSILON	1.39
ENVIRONMENT	UHV	GAMMA	8.88×10^{-1}
SPUTTERED ATOM (S)	N	Q	2.22×10^{-2}
		EJECTION ANGLE EXP.	36.2°
		CAL.	17.0°

ION	N	7	14.0
TARGET	SI	14	28.1
	N	7	14.0

REFERENCE 85.11

N



INFORMATION

85 11 19

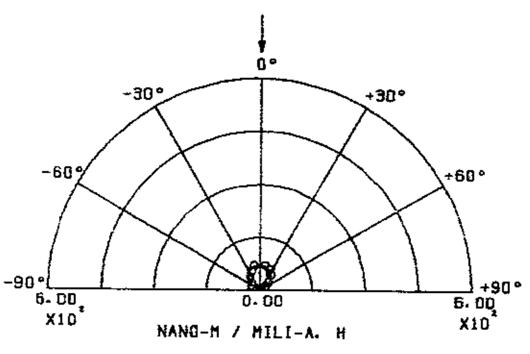
AR ⇒ SI-N

INCIDENT ANGLE	0°	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	EPSILON	1.69×10^{-1}
ENVIRONMENT	UHV	GAMMA	9.70×10^{-1}
SPUTTERED ATOM (S)	SI	Q	2.19×10^{-2}
		COS^{N} N	5.10×10^{-1}

ION	AR	18	39.9
TARGET	SI	14	28.1
	N	7	14.0

REFERENCE 85.11

SI



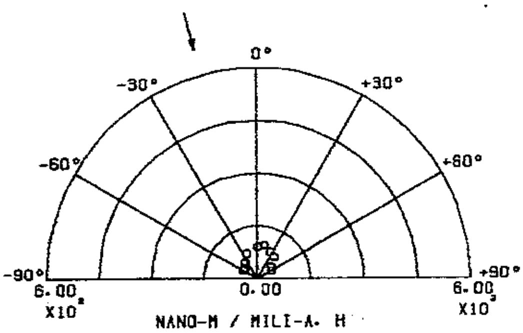
INFORMATION

85 11 14

AR ⇒ SI-N

INCIDENT ANGLE	15°	ENERGY (EV)	1.00 X10^{4}
TARGET	POLY	EPSILON	1.69 X10^{-1}
ENVIRONMENT	UHV	GAMMA	9.70 X10^{-1}
SPUTTERED ATOM (S)	SI	Q	2.19 X10^{-2}
		EJECTION ANGLE EXP.	12.6°
		CAL.	87.1°
ION	AR 18 39.9	REFERENCE	85.11
TARGET	SI 14 28.1 / N 7 14.0		

SI



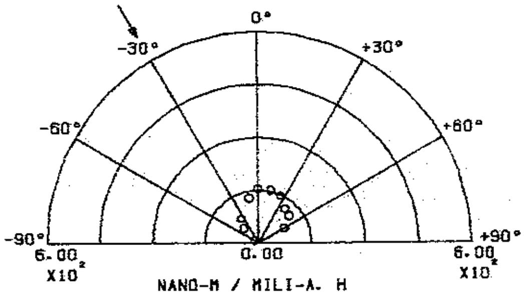
INFORMATION

85 11 15

AR ⇒ SI-N

INCIDENT ANGLE	30°	ENERGY (EV)	1.00 X10^{4}
TARGET	POLY	EPSILON	1.69 X10^{-1}
ENVIRONMENT	UHV	GAMMA	9.70 X10^{-1}
SPUTTERED ATOM (S)	SI	Q	2.19 X10^{-2}
		EJECTION ANGLE EXP.	60.0°
		CAL.	64.0°
ION	AR 18 39.9	REFERENCE	85.11
TARGET	SI 14 28.1 / N 7 14.0		

SI



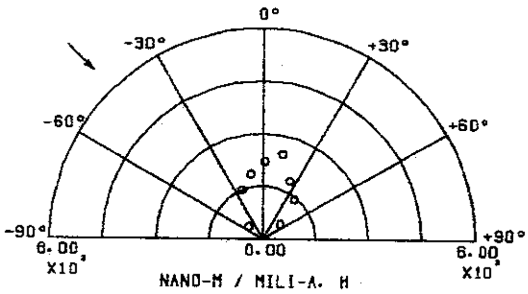
INFORMATION

85 11 16

AR ⇒ SI-N

INCIDENT ANGLE	45°		ENERGY (EV)	1.00 X10^{4}
TARGET	POLY		EPSILON	1.69 X10^{-1}
ENVIRONMENT	UHV		GAMMA	9.70 X10^{-1}
SPUTTERED ATOM (S)	SI		Q	2.19 X10^{-2}
			EJECTION ANGLE EXP.	50.2°
			CAL.	47.7°
ION	AR	18	39.9	
TARGET	SI	14	28.1	
	N	7	14.0	
			REFERENCE	85.11

SI



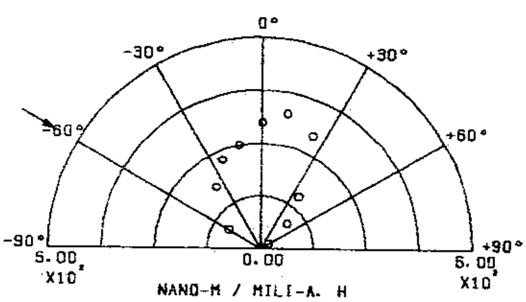
INFORMATION

85 11 17

AR ⇒ SI-N

INCIDENT ANGLE	60°		ENERGY (EV)	1.00 X10^{4}
TARGET	POLY		EPSILON	1.69 X10^{-1}
ENVIRONMENT	UHV		GAMMA	9.70 X10^{-1}
SPUTTERED ATOM (S)	SI		Q	2.19 X10^{-2}
			EJECTION ANGLE EXP.	36.0°
			CAL.	32.2°
ION	AR	18	39.9	
TARGET	SI	14	28.1	
	N	7	14.0	
			REFERENCE	85.11

SI



INFORMATION

85 11 18

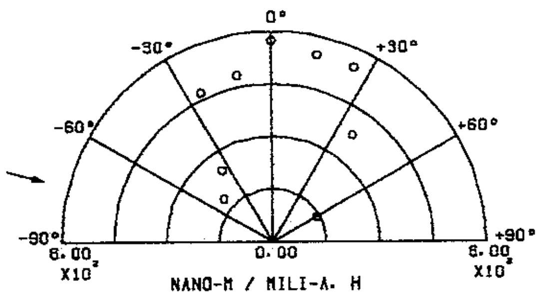
AR ⇒ SI-N

INCIDENT ANGLE	75°	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	EPSILON	1.69×10^{-1}
ENVIRONMENT	UHV	GAMMA	9.70×10^{-1}
SPUTTERED ATOM (S)	SI	Q	2.19×10^{-2}
		EJECTION ANGLE EXP.	25.2°
		CAL.	16.9°

ION	AR	18	39.9
TARGET	SI	14	28.1
	N	7	14.0

REFERENCE 85.11

SI



INFORMATION

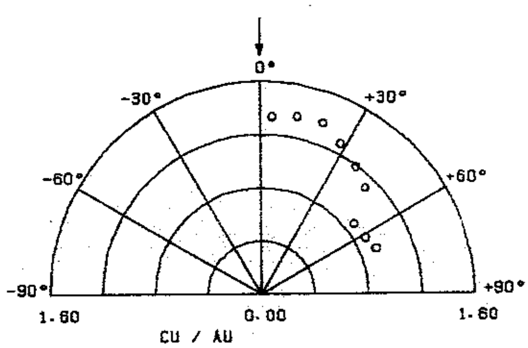
86 1 1

AR ⇒ AU-CU

INCIDENT ANGLE	0°	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	REFERENCE	86.1
ENVIRONMENT	UHV		
SPUTTERED ATOM (S)	CU / AU		

ION	AR	18	39.9
TARGET	AU	79	197
	CU	29	63.5

AU-CU (43 AT %)



INFORMATION

86 1 2

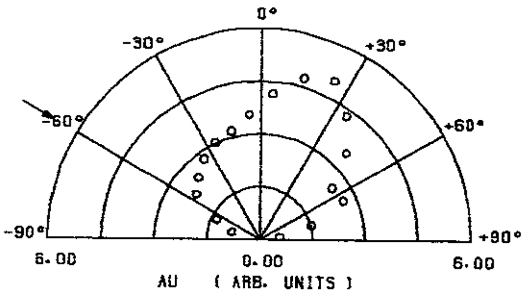
AR ⇒ AU-CU

INCIDENT ANGLE	60°	ENERGY (EV)	8.00×10^{2}
TARGET	POLY	EPSILON	3.42×10^{-3}
ENVIRONMENT	UHV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	AU	Q	9.22×10^{-2}
		EJECTION ANGLE EXP.	34.9°
		CAL.	39.5°

ION	AR	18	39.9
TARGET	AU	79	197
	CU	29	63.5

REFERENCE 86 . 1

OBLIQUE INCIDENCE



INFORMATION

86 1 3

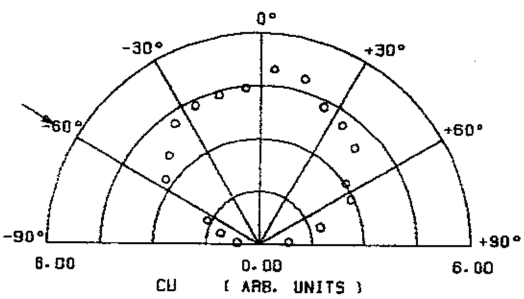
AR ⇒ AU-CU

INCIDENT ANGLE	60°	ENERGY (EV)	8.00×10^{2}
TARGET	POLY	EPSILON	8.56×10^{-3}
ENVIRONMENT	UHV	GAMMA	5.61×10^{-1}
SPUTTERED ATOM (S)	CU	Q	6.78×10^{-2}
		EJECTION ANGLE EXP.	34.8°
		CAL.	36.9°

ION	AR	18	39.9
TARGET	AU	79	197
	CU	29	63.5

REFERENCE 86 . 1

OBLIQUE INCIDENCE

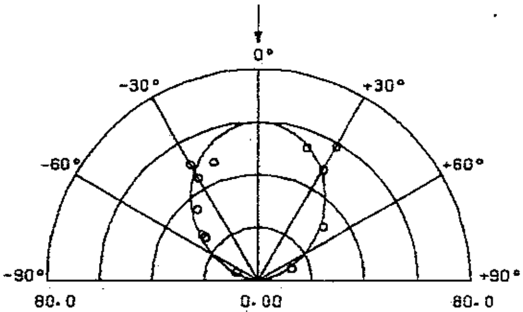


INFORMATION

86 2 1

BR ⇒ NB

INCIDENT ANGLE	0 °	ENERGY (EV)	0.00
TARGET	POLY	EPSILON	0.00
ENVIRONMENT	UHV	GAMMA	9.94×10^{-1}
SPUTTERED ATOM (S)	NB	Q	0.00
		COS* N	1.61
ION	BR 35 79.9		
TARGET	NB 41 92.9	REFERENCE	86.2

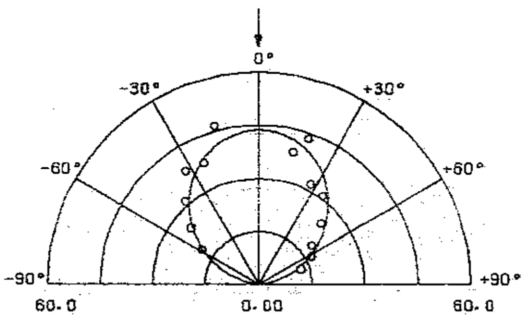


INFORMATION

86 2 2

BR ⇒ NB

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{5}
TARGET	POLY	EPSILON	2.90×10^{-1}
ENVIRONMENT	UHV	GAMMA	9.94×10^{-1}
SPUTTERED ATOM (S)	NB	Q	8.73×10^{-3}
		COS* N	1.36
ION	BR 35 79.9		
TARGET	NB 41 92.9	REFERENCE	86.2



INFORMATION

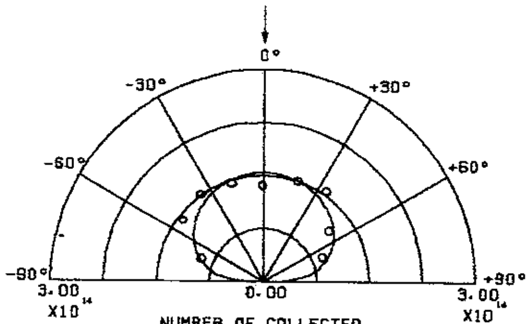
86 9 1

AR ⇒ NI-FE

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	1.08×10^{-2}
ENVIRONMENT	HV	GAMMA	9.64×10^{-1}
SPUTTERED ATOM (S)	NI	Q	6.79×10^{-2}
		COS^{N} N	4.50×10^{-1}

ION	AR	18	39.9
TARGET	NI	28	58.7
	FE	26	55.8

REFERENCE 86.3



NUMBER OF COLLECTED PARTICLES (ATOMS / SQ. CM. SEC) NI

INFORMATION

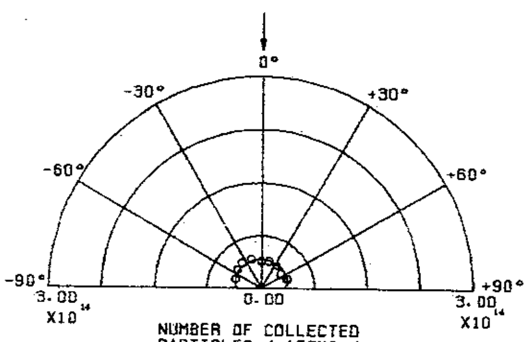
86 9 2

AR ⇒ NI-FE

INCIDENT ANGLE	0 °	ENERGY (EV)	1.00×10^{3}
TARGET	POLY	EPSILON	1.16×10^{-2}
ENVIRONMENT	HV	GAMMA	9.64×10^{-1}
SPUTTERED ATOM (S)	FE	Q	6.63×10^{-2}
		COS^{N} N	6.00×10^{-2}

ION	AR	18	39.9
TARGET	NI	28	58.7
	FE	26	55.8

REFERENCE 86.3



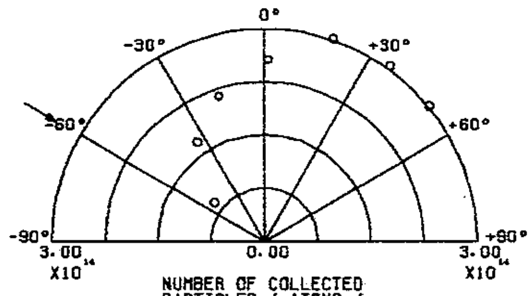
NUMBER OF COLLECTED PARTICLES (ATOMS / SQ. CM. SEC) FE

INFORMATION

86 3 3

AR ⇒ NI-FE

INCIDENT ANGLE	60°			ENERGY (EV)	1.00×10^{3}
TARGET	POLY			EPSILON	1.08×10^{-2}
ENVIRONMENT	HV			GAMMA	9.64×10^{-1}
SPUTTERED ATOM (S)	NI			Q	6.79×10^{-2}
				EJECTION ANGLE	
				EXP.	35.6°
ION	AR	18	39.9	CAL.	38.9°
TARGET	NI	28	58.7		
	FE	26	55.8	REFERENCE	86.3



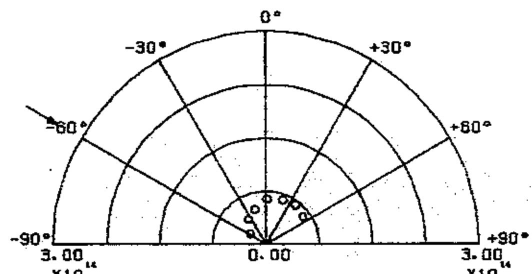
NUMBER OF COLLECTED PARTICLES (ATOMS / SQ.CM.SEC) NI

INFORMATION

86 3 4

AR ⇒ NI-FE

INCIDENT ANGLE	60°			ENERGY (EV)	1.00×10^{3}
TARGET	POLY			EPSILON	1.16×10^{-2}
ENVIRONMENT	HV			GAMMA	9.64×10^{-1}
SPUTTERED ATOM (S)	FE			Q	6.63×10^{-2}
				EJECTION ANGLE	
				EXP.	36.7°
ION	AR	18	39.9	CAL.	36.8°
TARGET	NI	28	58.7		
	FE	26	55.8	REFERENCE	86.3



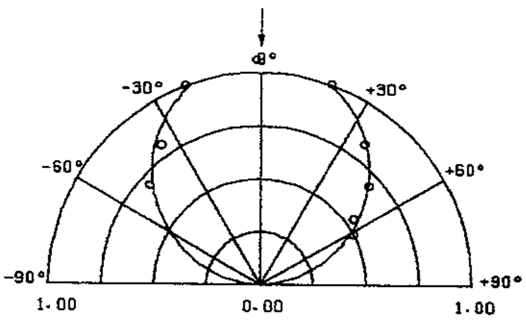
NUMBER OF COLLECTED PARTICLES (ATOMS /SQ.CM.SEC) FE

INFORMATION

86 6 1

AR ⇒ FE

INCIDENT ANGLE	0 °			ENERGY (EV)	1.00×10^{3}
TARGET	POLY			EPSILON	1.16×10^{-2}
ENVIRONMENT	HV			GAMMA	9.72×10^{-1}
SPUTTERED ATOM (S)	FE			Q	6.63×10^{-2}
				$\cos^{N}$ N	1.12
ION	AR	18	39.9		
TARGET	FE	26	55.8	REFERENCE	86.6

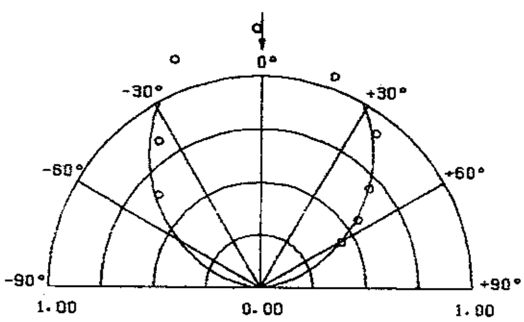


INFORMATION

86 6 2

AR ⇒ FE

INCIDENT ANGLE	0 °			ENERGY (EV)	3.00×10^{3}
TARGET	POLY			EPSILON	3.47×10^{-2}
ENVIRONMENT	HV			GAMMA	9.72×10^{-1}
SPUTTERED ATOM (S)	FE			Q	3.83×10^{-2}
				$\cos^{N}$ N	1.45
ION	AR	18	39.9		
TARGET	FE	26	55.8	REFERENCE	86.6



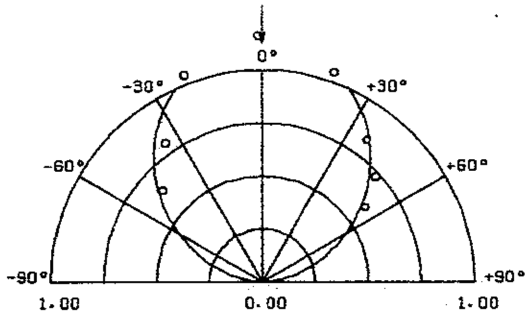
INFORMATION

86 6 9

AR ⇒ FE

INCIDENT ANGLE	0 °	ENERGY (EV)	2.00×10^{3}
TARGET	POLY	EPSILON	2.31×10^{-2}
ENVIRONMENT	HV	GAMMA	9.72×10^{-1}
SPUTTERED ATOM (S)	FE	Q	4.69×10^{-2}
		COS * N	1.31

ION	AR	18	39.9	REFERENCE	86.6
TARGET	FE	26	55.8		



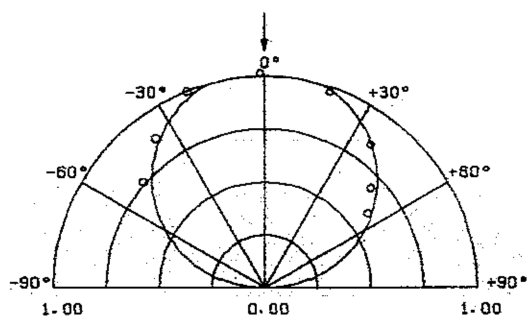
INFORMATION

86 6 4

AR ⇒ FE

INCIDENT ANGLE	0 °	ENERGY (EV)	6.00×10^{2}
TARGET	POLY	EPSILON	6.94×10^{-3}
ENVIRONMENT	HV	GAMMA	9.72×10^{-1}
SPUTTERED ATOM (S)	FE	Q	8.56×10^{-2}
		COS * N	9.30×10^{-1}

ION	AR	18	39.9	REFERENCE	86.6
TARGET	FE	26	55.8		



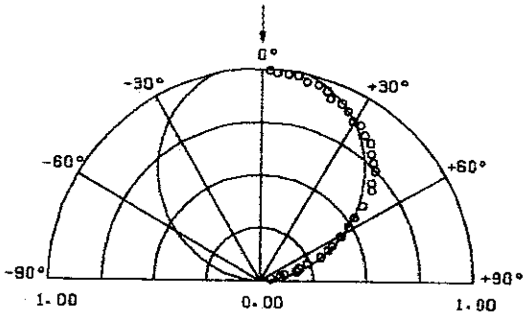
INFORMATION

86 7 1

AR ⇒ AG

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00 $\times 10^{3}$
TARGET	POLY	EPSILON	3.55 $\times 10^{-2}$
ENVIRONMENT	UHV	GAMMA	7.89 $\times 10^{-1}$
SPUTTERED ATOM (S)	AG	Q	2.73 $\times 10^{-2}$
		COS^{N} N	1.18
ION	AR 18 39.9	REFERENCE	86.7
TARGET	AG 47 108		

TOTAL FLUENCE 1.5E+17 UHV



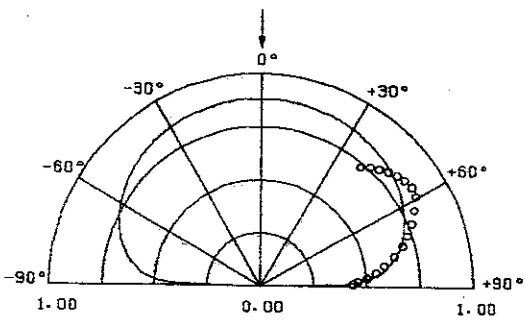
INFORMATION

86 7 2

AR ⇒ AG

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00 $\times 10^{3}$
TARGET	POLY	EPSILON	3.55 $\times 10^{-2}$
ENVIRONMENT	UHV	GAMMA	7.89 $\times 10^{-1}$
SPUTTERED ATOM (S)	AG	Q	2.73 $\times 10^{-2}$
		COS^{N} N	2.00 $\times 10^{-1}$
ION	AR 18 39.9	REFERENCE	86.7
TARGET	AG 47 108		

TOTAL FLUENCE 5E+17 HIGH DOSE



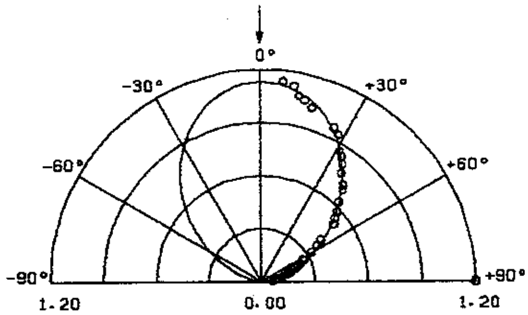
INFORMATION

86 7 3

AR ⇒ AG

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{3}
TARGET	POLY	EPSILON	3.55×10^{-2}
ENVIRONMENT	UHV	GAMMA	7.89×10^{-1}
SPUTTERED ATOM (S)	AG	Q	2.73×10^{-2}
		COS^{N} N	1.74
ION	AR 18 39.9	REFERENCE	86.7
TARGET	AG 47 108		

TOTAL FLUENCE (IONS / SQ. CM)
2E-5 TORR

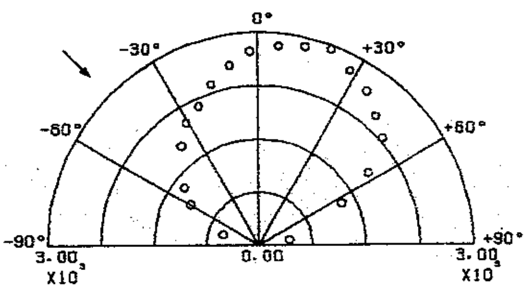


INFORMATION

86 8 1

XE ⇒ U-O2

INCIDENT ANGLE	45°	ENERGY (EV)	8.00×10^{3}
TARGET	POLY	EPSILON	6.48×10^{-3}
ENVIRONMENT	----------	GAMMA	9.16×10^{-1}
SPUTTERED ATOM (S)	U	Q	2.75×10^{-2}
		EJECTION ANGLE EXP.	49.2°
		CAL.	46.4°
ION	XE 54 131	REFERENCE	86.8
TARGET	U 92 238 O 8 16.0		



INFORMATION

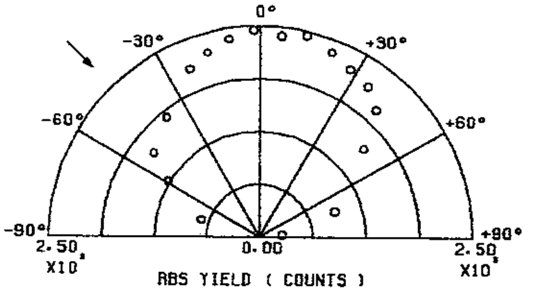
86 8 2

AR ⇒ U-O2

INCIDENT ANGLE	45°	ENERGY (EV)	1.00×10^{4}
TARGET	POLY	EPSILON	8.09×10^{-3}
ENVIRONMENT	----------	GAMMA	9.16×10^{-1}
SPUTTERED ATOM(S)	U	Q	2.46×10^{-2}
		EJECTION ANGLE EXP.	49.3°
		CAL.	48.1°

ION	XE	54	131
TARGET	U	92	238
	O	8	16.0

REFERENCE 86.8



INFORMATION

86 12 1

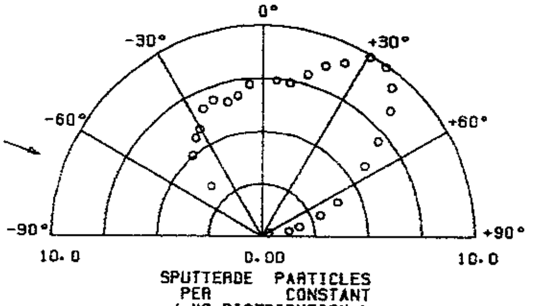
HE ⇒ MO

INCIDENT ANGLE	70°	ENERGY (EV)	6.00×10^{3}
TARGET	POLY	EPSILON	6.81×10^{-1}
ENVIRONMENT	UHV	GAMMA	1.54×10^{-1}
SPUTTERED ATOM(S)	MO	Q	8.60×10^{-2}
		EJECTION ANGLE EXP.	35.0°
		CAL.	28.0°

ION	HE	2	4.00
TARGET	MO	42	95.9

REFERENCE 86.12

5E-8 TORR



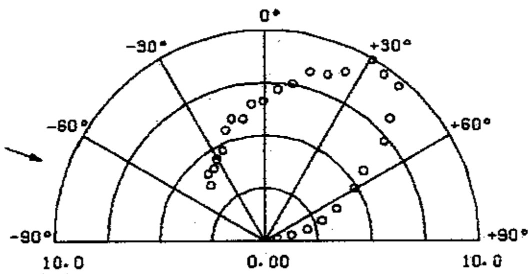
INFORMATION

86 12 2

HE ⇒ MO

INCIDENT ANGLE	70°			ENERGY (EV)	6.00×10^{3}
TARGET	POLY			EPSILON	6.81×10^{-1}
ENVIRONMENT	HV			GAMMA	1.54×10^{-1}
SPUTTERED ATOM (S)	MO			Q	8.60×10^{-2}
				EJECTION ANGLE EXP.	30.0°
				CAL.	28.0°
ION	HE	2	4.00	REFERENCE	86.12
TARGET	MO	42	95.9		

2E-5 TORR



SPUTTERED PARTICLES
PER CONSTANT
(MO-DISTRIBUTION)

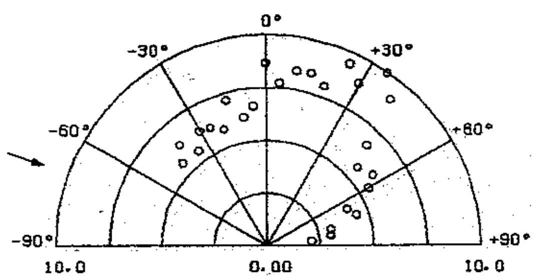
INFORMATION

86 12 3

HE ⇒ MO

INCIDENT ANGLE	70°			ENERGY (EV)	6.00×10^{3}
TARGET	POLY			EPSILON	4.66
ENVIRONMENT	HV			GAMMA	1.54×10^{-1}
SPUTTERED ATOM (S)	O			Q	2.60×10^{-2}
				EJECTION ANGLE EXP.	30.0°
				CAL.	22.4°
ION	HE	2	4.00	REFERENCE	86.12
TARGET	MO	42	95.9		
	O	8	16.0		

2E-5 TORR



SPUTTERED PARTICLES
PER CONSTANT
(O-DISTRIBUTION)

INFORMATION

86 14 1

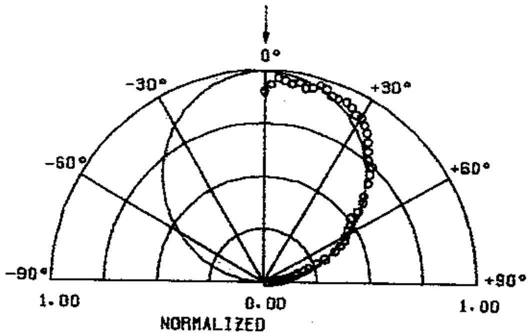
AR ⇒ RH

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{3}
TARGET	POLY	EPSILON	3.70×10^{-2}
ENVIRONMENT	UHV	GAMMA	8.06×10^{-1}
SPUTTERED ATOM (S)	RH	Q	3.78×10^{-2}
		COS^{N} N	1.11

ION	AR	18	39.9
TARGET	RH	45	103

REFERENCE 86.14

ENERGY-RESOLVED DISTRIBUTION
2EV



INFORMATION

86 14 2

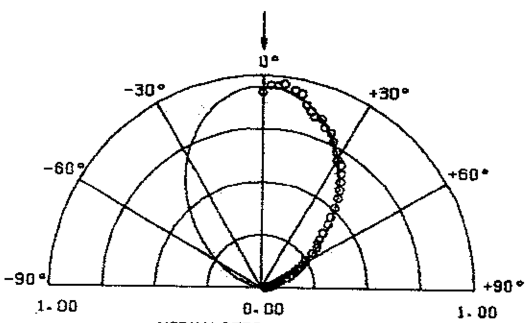
AR ⇒ RH

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{3}
TARGET	POLY	EPSILON	3.70×10^{-2}
ENVIRONMENT	UHV	GAMMA	8.06×10^{-1}
SPUTTERED ATOM (S)	RH	Q	3.78×10^{-2}
		COS^{N} N	2.03

ION	AR	18	39.9
TARGET	RH	45	103

REFERENCE 86.14

ENERGY-RESOIVED DISTRIBUTION
12EV



INFORMATION

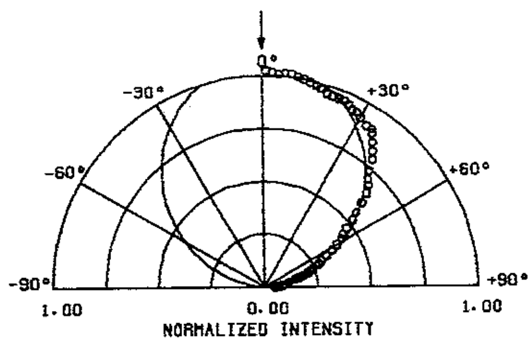
86 15 1

AR ⇒ IN

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{3}
TARGET	POLY	EPSILON	3.43×10^{-2}
ENVIRONMENT	UHV	GAMMA	7.66×10^{-1}
SPUTTERED ATOM (S)	IN	Q	2.57×10^{-2}
		$\cos^{N}$ N	1.31

ION	AR	18	39.9	REFERENCE	86.15
TARGET	IN	49	115		

ENERGY-INTEGRATED POLAR ANGLE DISTRIBUTION



INFORMATION

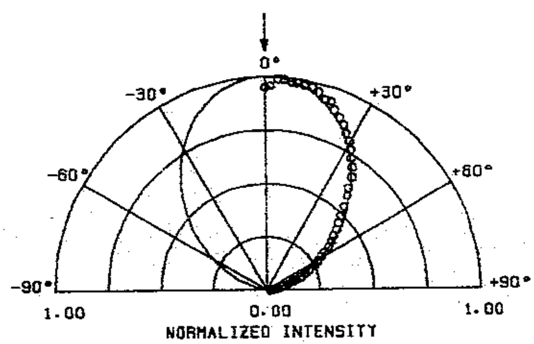
86 15 2

AR ⇒ RH

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{3}
TARGET	POLY	EPSILON	3.70×10^{-2}
ENVIRONMENT	UHV	GAMMA	8.06×10^{-1}
SPUTTERED ATOM (S)	RH	Q	3.78×10^{-2}
		$\cos^{N}$ N	1.81

ION	AR	18	39.9	REFERENCE	86.15
TARGET	RH	45	103		

ENERGY-INTEGRATED POLAR ANGLE DISTRIBUTION



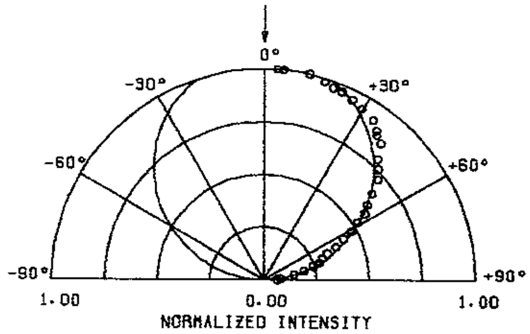
INFORMATION

86 15 3

AR ⇒ IN

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{3}
TARGET	POLY	EPSILON	3.43×10^{-2}
ENVIRONMENT	UHV	GAMMA	7.66×10^{-1}
SPUTTERED ATOM(S)	IN	Q	2.57×10^{-2}
		COS^{N} N	1.06
ION	AR 18 39.9		
TARGET	IN 49 115	REFERENCE	86.15

ENRGY-RESOLVED POLAR ANGLE
DISTIBUTION 2-4EV



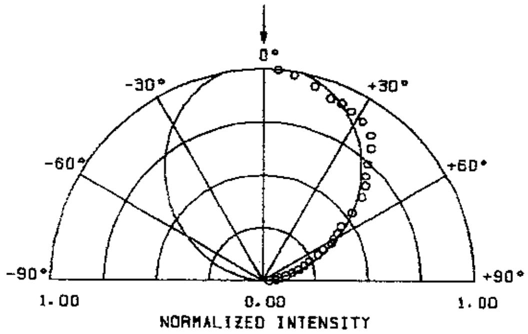
INFORMATION

86 15 4

AR ⇒ IN

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{3}
TARGET	POLY	EPSILON	3.43×10^{-2}
ENVIRONMENT	UHV	GAMMA	7.66×10^{-1}
SPUTTERED ATOM(S)	IN	Q	2.57×10^{-2}
		COS^{N} N	1.31
ION	AR 18 39.9		
TARGET	IN 49 115	REFERENCE	86.15

ENRGY-RESOLVED POLAR ANGLE
DISTRIBUTION 4-6EV



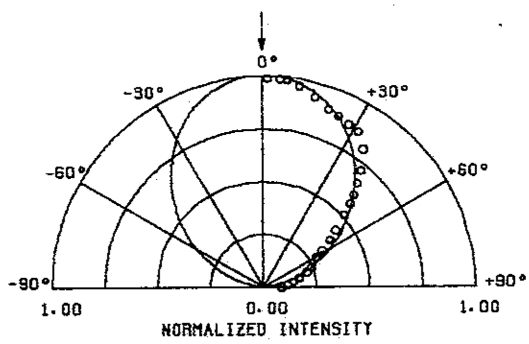
INFORMATION

86 15 5

AR ⇒ IN

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{3}
TARGET	POLY	EPSILON	3.43×10^{-2}
ENVIRONMENT	UHV	GAMMA	7.66×10^{-1}
SPUTTERED ATOM (S)	IN	Q	2.57×10^{-2}
		COS^{N} N	1.49
ION	AR 18 39.9	REFERENCE	86.15
TARGET	IN 49 115		

ENRGY-RESOLVED POLAR ANGLE
DISTRIBUTION 14-16EV



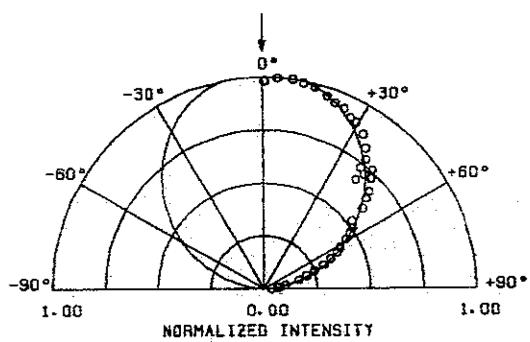
INFORMATION

86 15 6

AR ⇒ RH

INCIDENT ANGLE	0 °	ENERGY (EV)	5.00×10^{3}
TARGET	POLY	EPSILON	3.70×10^{-2}
ENVIRONMENT	UHV	GAMMA	8.06×10^{-1}
SPUTTERED ATOM (S)	RH	Q	3.78×10^{-2}
		COS^{N} N	1.22
ION	AR 18 39.9	REFERENCE	86.15
TARGET	RH 45 103		

ENRGY-RESOLVED POLAR ANGLE
DISTRIBUTION 2-4EV



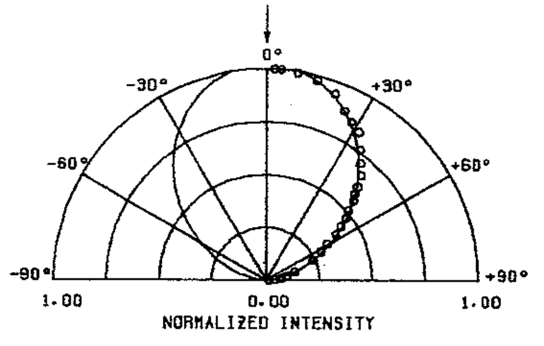
INFORMATION

86 15 7

AR ⇒ RH

INCIDENT ANGLE	0 °		ENERGY (EV)	5.00×10^{3}	
TARGET	POLY		EPSILON	3.70×10^{-2}	
ENVIRONMENT	UHV		GAMMA	8.06×10^{-1}	
SPUTTERED ATOM (S)	RH		Q	3.78×10^{-2}	
			COS^{N} N	1.56	
ION	AR	18	39.9		
TARGET	RH	45	103	REFERENCE	86.15

ENRGY-RESOLVED POLAR ANGLE
DISTRIBUTION 4-6EV



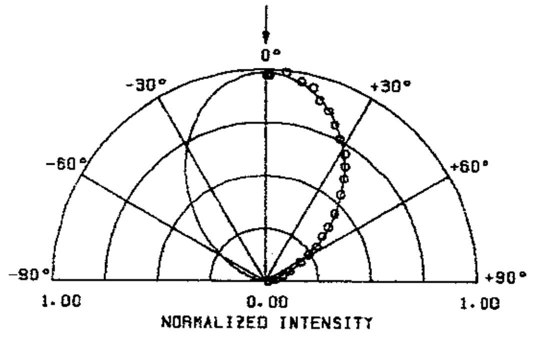
INFORMATION

86 15 8

AR ⇒ RH

INCIDENT ANGLE	0 °		ENERGY (EV)	5.00×10^{3}	
TARGET	POLY		EPSILON	3.70×10^{-2}	
ENVIRONMENT	UHV		GAMMA	8.06×10^{-1}	
SPUTTERED ATOM (S)	RH		Q	3.78×10^{-2}	
			COS^{N} N	2.11	
ION	AR	18	39.9		
TARGET	RH	45	103	REFERENCE	86.15

ENRGY-RESOLVED POLAR ANGLE
DISTRIBUTION 14-16EV



INFORMATION

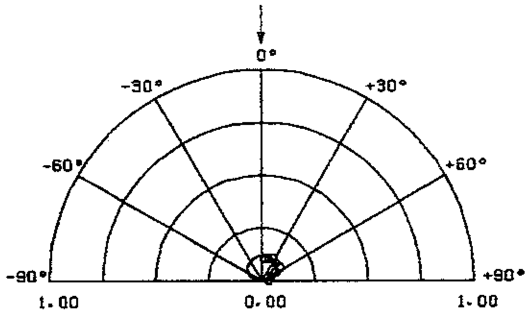
86 16 1

AR ⇒ CU

INCIDENT ANGLE	0 °	ENERGY (EV)	2.00×10^{3}
TARGET	POLY	EPSILON	2.14×10^{-2}
ENVIRONMENT	UHV	GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU	Q	4.29×10^{-2}
		$\cos^{n}$ N	7.20×10^{-1}

ION	AR	18	39.9	REFERENCE	86 . 16
TARGET	CU	29	63.5		

F=1.9E+17 IONS/SQ.CM



INFORMATION

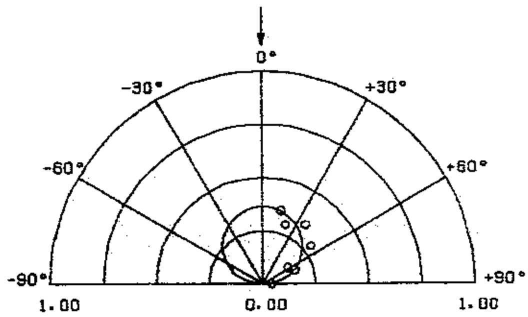
86 16 2

AR ⇒ CU

INCIDENT ANGLE	0 °	ENERGY (EV)	2.00×10^{3}
TARGET	POLY	EPSILON	2.14×10^{-2}
ENVIRONMENT	UHV	GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU	Q	4.29×10^{-2}
		$\cos^{n}$ N	8.80×10^{-1}

ION	AR	18	39.9	REFERENCE	86 . 16
TARGET	CU	29	63.5		

F=4.8E+17 IONS/SQ.CM



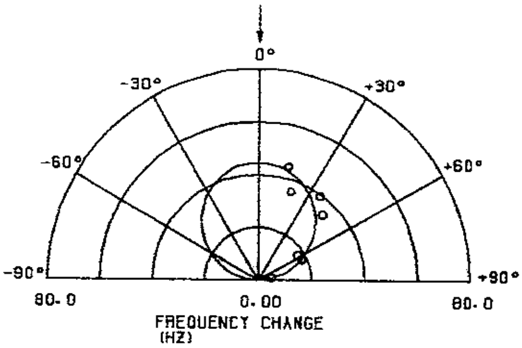
INFORMATION

86 16 3

AR ⇒ CU

INCIDENT ANGLE	0 °			ENERGY (EV)	2.00×10^{3}
TARGET	POLY			EPSILON	2.14×10^{-2}
ENVIRONMENT	UHV			GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU			Q	4.29×10^{-2}
				$\cos^{N}$ N	1.12
ION	AR	18	39.9		
TARGET	CU	29	63.5	REFERENCE	86.16

F=7.4E+17 IONS/SQ.CM



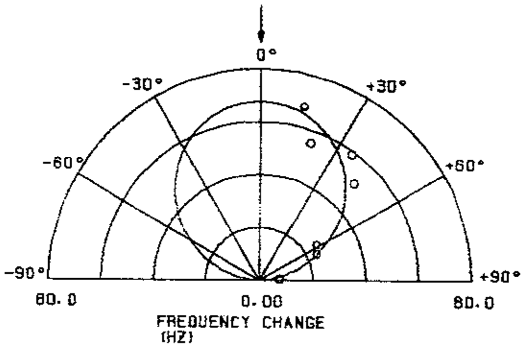
INFORMATION

86 16 4

AR ⇒ CU

INCIDENT ANGLE	0 °			ENERGY (EV)	2.00×10^{3}
TARGET	POLY			EPSILON	2.14×10^{-2}
ENVIRONMENT	UHV			GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU			Q	4.29×10^{-2}
				$\cos^{N}$ N	1.17
ION	AR	18	39.9		
TARGET	CU	29	63.5	REFERENCE	86.16

F=1.1E+18 IONS/SQ.CM



INFORMATION

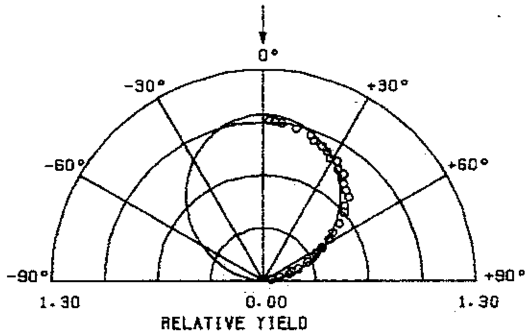
86 17 1

AR ⇒ AG

INCIDENT ANGLE	0 °		ENERGY (EV)	5.00×10^{3}
TARGET	POLY		EPSILON	3.55×10^{-2}
ENVIRONMENT	UHV		GAMMA	7.89×10^{-1}
SPUTTERED ATOM (S)	AG		Q	2.73×10^{-2}
			COS * N	1.23

ION	AR	18	39.9	REFERENCE	86.17
TARGET	AG	47	108		

P=6.8E-8 TORR
F=1.5E+17 IONS/SQ.CM



INFORMATION

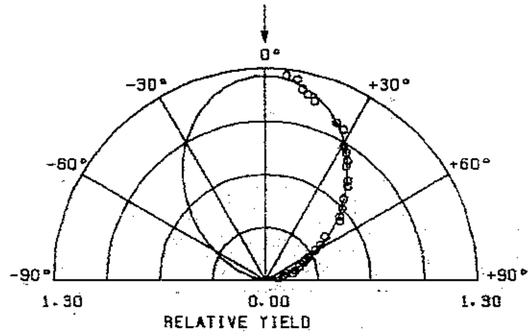
86 17 2

AR ⇒ AG

INCIDENT ANGLE	0 °		ENERGY (EV)	5.00×10^{3}
TARGET	POLY		EPSILON	3.55×10^{-2}
ENVIRONMENT	HV		GAMMA	7.89×10^{-1}
SPUTTERED ATOM (S)	AG		Q	2.73×10^{-2}
			COS * N	1.77

ION	AR	18	39.9	REFERENCE	86.17
TARGET	AG	47	108		

P=4E-5 TORR
F=2E+17 IONS/SQ.CM



INFORMATION

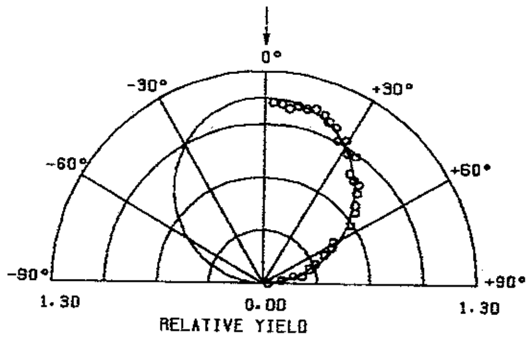
86 17 3

N2 ⇒ AG

INCIDENT ANGLE	0 °		ENERGY (EV)	5.00×10^{3}
TARGET	POLY		EPSILON	1.21×10^{-1}
ENVIRONMENT	UHV		GAMMA	4.07×10^{-1}
SPUTTERED ATOM (S)	AG		Q	3.81×10^{-2}
			COS^{N} N	1.11

ION	N	7	14.0	REFERENCE	86 . 17
TARGET	AG	47	108		

P=1.2E-7 TORR
F=3E+17 IONS/SQ.CM



INFORMATION

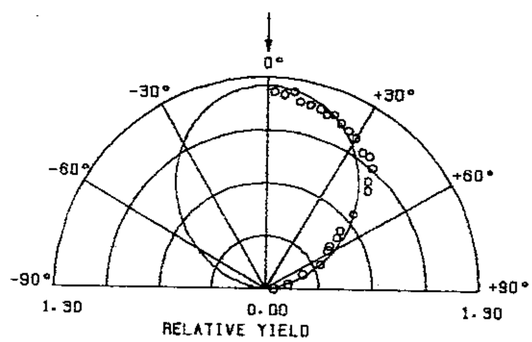
86 17 4

N2 ⇒ AG

INCIDENT ANGLE	0 °		ENERGY (EV)	5.00×10^{3}
TARGET	POLY		EPSILON	1.21×10^{-1}
ENVIRONMENT	HV		GAMMA	4.07×10^{-1}
SPUTTERED ATOM (S)	AG		Q	3.81×10^{-2}
			COS^{N} N	1.38

ION	N	7	14.0	REFERENCE	86 . 17
TARGET	AG	47	108		

P=4E-5 TORR
F=3E+17 IONS/SQ.CM



INFORMATION

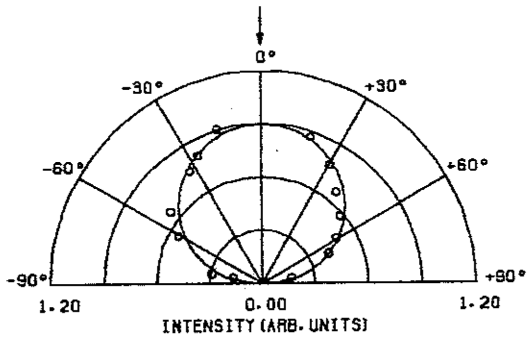
86 18 1

AR ⇒ AG

INCIDENT ANGLE	0°	ENERGY (EV)	2.00×10^{4}
TARGET	POLY	EPSILON	1.42×10^{-1}
ENVIRONMENT	HV	GAMMA	7.89×10^{-1}
SPUTTERED ATOM (S)	AG	Q	1.37×10^{-2}
		COS^{n} N	8.50×10^{-1}

ION	AR	18	39.9
TARGET	AG	47	108

REFERENCE 86.18



INFORMATION

87 2 1

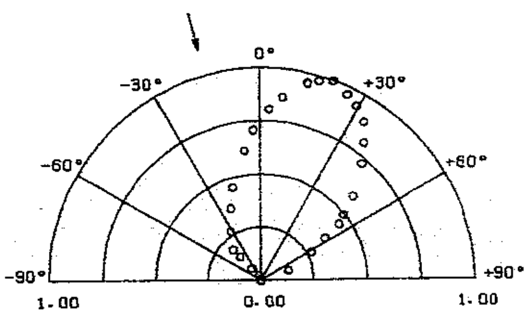
XE ⇒ SI

INCIDENT ANGLE	15°	ENERGY (EV)	2.00×10^{4}
TARGET	POLY	EPSILON	3.82×10^{-2}
ENVIRONMENT	UHV	GAMMA	5.81×10^{-1}
SPUTTERED ATOM (S)	SI	Q	2.00×10^{-2}
		EJECTION ANGLE EXP.	13.9°
		CAL.	84.8°

ION	XE	54	131
TARGET	SI	14	28.1

REFERENCE 87.2

TRAPPED XE



INFORMATION

87 2 2

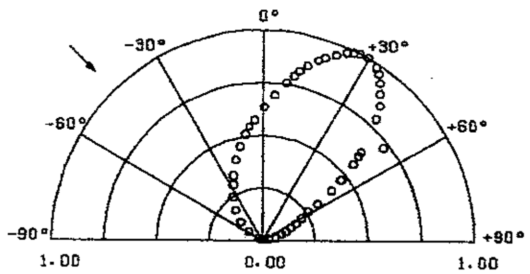
XE ⇒ SI

INCIDENT ANGLE	45°		ENERGY (EV)	2.00×10^{4}
TARGET	POLY		EPSILON	3.82×10^{-2}
ENVIRONMENT	UHV		GAMMA	5.81×10^{-1}
SPUTTERED ATOM (S)	SI		Q	2.00×10^{-2}
			EJECTION ANGLE EXP.	52.2°
			CAL.	47.5°

ION	XE	54	131
TARGET	SI	14	28.1

REFERENCE 87.2

TRAPPED XE



INFORMATION

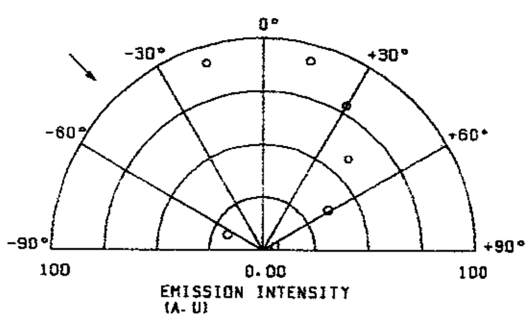
87 2 3

XE ⇒ SI

INCIDENT ANGLE	45°		ENERGY (EV)	2.00×10^{4}
TARGET	POLY		EPSILON	3.82×10^{-2}
ENVIRONMENT	UHV		GAMMA	5.81×10^{-1}
SPUTTERED ATOM (S)	SI		Q	2.00×10^{-2}
			EJECTION ANGLE EXP.	0.00°
			CAL.	47.5°

ION	XE	54	131
TARGET	SI	14	28.1

REFERENCE 87.2



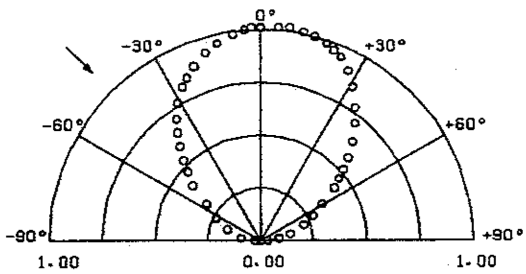
INFORMATION

87 2 4

AR ⇒ SI

INCIDENT ANGLE	45°	ENERGY (EV)	2.00×10^{4}
TARGET	POLY	EPSILON	3.38×10^{-1}
ENVIRONMENT	UHV	GAMMA	9.70×10^{-1}
SPUTTERED ATOM (S)	SI	Q	1.55×10^{-2}
		EJECTION ANGLE EXP.	0.00°
		CAL.	46.9°
ION	AR 18 39.9	REFERENCE	87.2
TARGET	SI 14 28.1		

SI



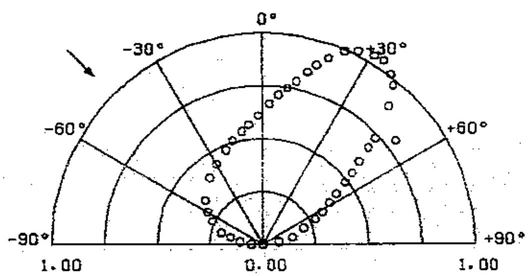
INFORMATION

87 2 5

AR ⇒ SI

INCIDENT ANGLE	45°	ENERGY (EV)	2.00×10^{4}
TARGET	POLY	EPSILON	3.38×10^{-1}
ENVIRONMENT	UHV	GAMMA	9.70×10^{-1}
SPUTTERED ATOM (S)	SI	Q	1.55×10^{-2}
		EJECTION ANGLE EXP.	52.2°
		CAL.	46.9°
ION	AR 18 39.9	REFERENCE	87.2
TARGET	SI 14 28.1		

TRAPPED AR



INFORMATION

87 2 6

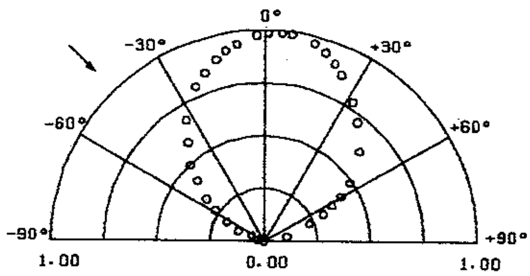
KR ⇒ SI

INCIDENT ANGLE	45°		ENERGY (EV)	2.00×10^{4}
TARGET	POLY		EPSILON	8.95×10^{-2}
ENVIRONMENT	UHV		GAMMA	7.52×10^{-1}
SPUTTERED ATOM (S)	SI		Q	1.76×10^{-2}
			EJECTION ANGLE	
			EXP.	10.08
			CAL.	47.2°

ION	KR	36	83.8
TARGET	SI	14	28.1

REFERENCE 87.2

SI



INFORMATION

87 2 7

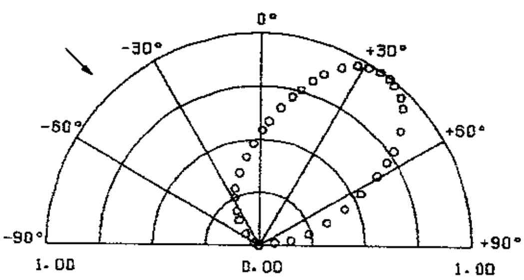
KR ⇒ SI

INCIDENT ANGLE	45°		ENERGY (EV)	2.00×10^{4}
TARGET	POLY		EPSILON	8.95×10^{-2}
ENVIRONMENT	UHV		GAMMA	7.52×10^{-1}
SPUTTERED ATOM (S)	SI		Q	1.76×10^{-2}
			EJECTION ANGLE	
			EXP.	45.9°
			CAL.	47.2°

ION	KR	36	83.8
TARGET	SI	14	28.1

REFERENCE 87.2

TRAPPED KR



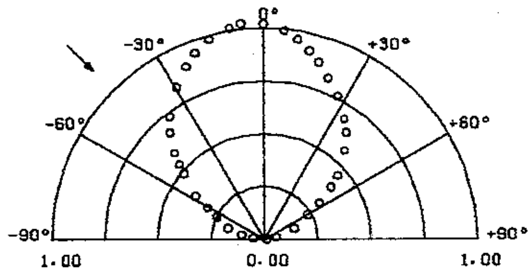
INFORMATION

87 2 8

XE ⇒ SI

INCIDENT ANGLE	45°	ENERGY (EV)	2.00×10^{4}
TARGET	POLY	EPSILON	3.82×10^{-2}
ENVIRONMENT	UHV	GAMMA	5.81×10^{-1}
SPUTTERED ATOM (S)	SI	Q	2.00×10^{-2}
		EJECTION ANGLE EXP.	0.00°
		CAL.	47.5°
ION	XE 54 131	REFERENCE	87.2
TARGET	SI 14 28.1		

SI



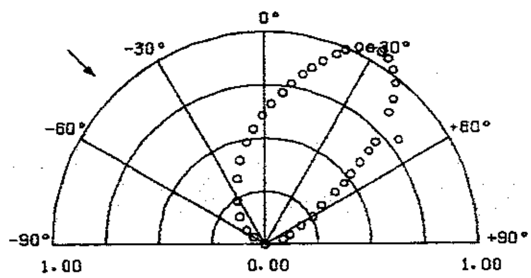
INFORMATION

87 2 9

XE ⇒ SI

INCIDENT ANGLE	45°	ENERGY (EV)	2.00×10^{4}
TARGET	POLY	EPSILON	3.82×10^{-2}
ENVIRONMENT	UHV	GAMMA	5.81×10^{-1}
SPUTTERED ATOM (S)	SI	Q	2.00×10^{-2}
		EJECTION ANGLE EXP.	52.2°
		CAL.	47.5°
ION	XE 54 131	REFERENCE	87.2
TARGET	SI 14 28.1		

TRAPPED XE



INFORMATION

87 3 1

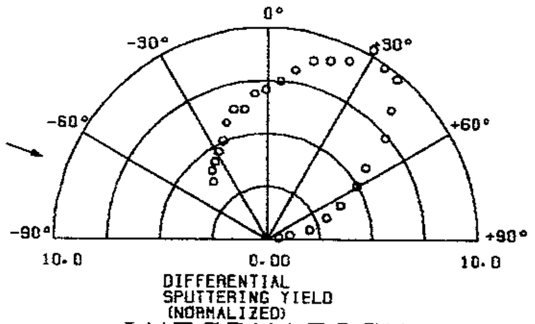
HE ⇒ MO

INCIDENT ANGLE	70°	ENERGY (EV)	6.00×10^{3}
TARGET	POLY	EPSILON	6.81×10^{-1}
ENVIRONMENT	UHV	GAMMA	1.54×10^{-1}
SPUTTERED ATOM (S)	MO	Q	8.60×10^{-2}
		EJECTION ANGLE	
		EXP.	29.2°
		CAL.	28.0°

ION	HE	2	4.00
TARGET	MO	42	95.9

REFERENCE 87.3

2.5E-5 MBAR O2



INFORMATION

87 3 2

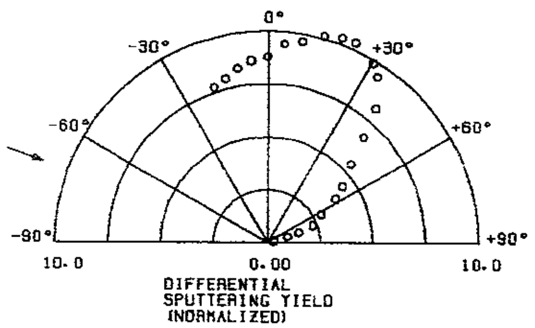
HE ⇒ MO

INCIDENT ANGLE	70°	ENERGY (EV)	6.00×10^{3}
TARGET	POLY	EPSILON	6.81×10^{-1}
ENVIRONMENT	HV	GAMMA	1.54×10^{-1}
SPUTTERED ATOM (S)	MO	Q	8.60×10^{-2}
		EJECTION ANGLE	
		EXP.	25.0°
		CAL.	28.0°

ION	HE	2	4.00
TARGET	MO	42	95.9

REFERENCE 87.3

640C AND 1.0E-5 MBAR O2



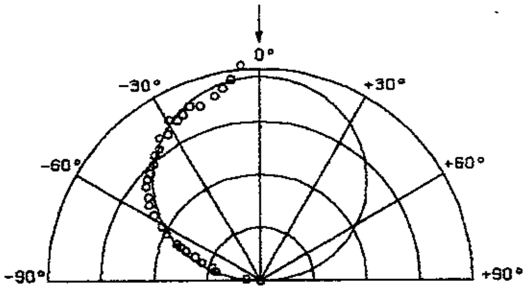
INFORMATION

88 1 1

N ⇒ AG

INCIDENT ANGLE	0 °		ENERGY (EV)	5.00×10^{3}	
TARGET	POLY		EPSILON	1.21×10^{-1}	
ENVIRONMENT	UHV		GAMMA	4.07×10^{-1}	
SPUTTERED ATOM(S)	AG		Q	3.81×10^{-2}	
			$\cos^{N}$ N	8.80×10^{-1}	
ION	N	7	14.0		
TARGET	AG	47	108		
			REFERENCE	88.1	

P=3.5E-8 TORR F=2.5E17 IONS/SQ.CM



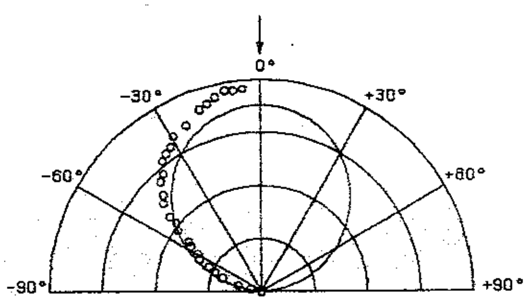
INFORMATION

88 1 2

N ⇒ AR

INCIDENT ANGLE	0 °		ENERGY (EV)	5.00×10^{3}	
TARGET	POLY		EPSILON	3.33×10^{-1}	
ENVIRONMENT	HV		GAMMA	7.69×10^{-1}	
SPUTTERED ATOM(S)	AR		Q	4.56×10^{-3}	
			$\cos^{N}$ N	1.13	
ION	N	7	14.0		
TARGET	AR	18	39.9		
			REFERENCE	88.1	

P=2E-5 TORR F=1.7E+17 IONS/SQ.CM



INFORMATION

88 2 1

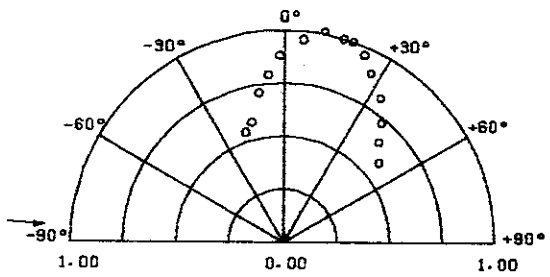
AR ⇒ CU

INCIDENT ANGLE	86°
TARGET	POLY
ENVIRONMENT	----------
SPUTTERED ATOM (S)	CU

ION	AR	18	39.9
TARGET	CU	29	63.5

ENERGY (EV)	3.00×10^{4}
EPSILON	3.21×10^{-1}
GAMMA	9.48×10^{-1}
Q	1.11×10^{-2}
EJECTION ANGLE EXP.	10.0°
EJECTION ANGLE CAL.	4.94°

REFERENCE 88.2



INFORMATION

88 2 2

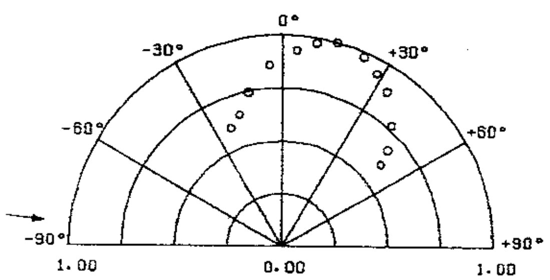
AR ⇒ CU

INCIDENT ANGLE	84°
TARGET	POLY
ENVIRONMENT	----------
SPUTTERED ATOM (S)	CU

ION	AR	18	39.9
TARGET	CU	29	63.5

ENERGY (EV)	3.00×10^{4}
EPSILON	3.21×10^{-1}
GAMMA	9.48×10^{-1}
Q	1.11×10^{-2}
EJECTION ANGLE EXP.	15.0°
EJECTION ANGLE CAL.	6.95°

REFERENCE 88.2



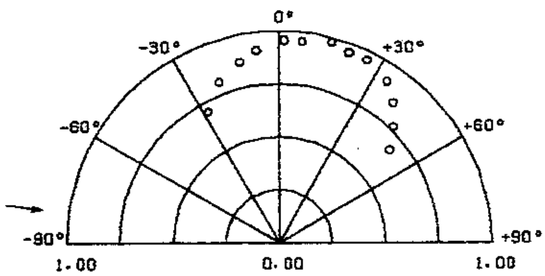
179

INFORMATION

88 2 3

AR ⇒ CU

INCIDENT ANGLE	82°		ENERGY (EV)	3.00×10^{4}
TARGET	POLY		EPSILON	3.21×10^{-1}
ENVIRONMENT	----------		GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU		Q	1.11×10^{-2}
			EJECTION ANGLE EXP.	15.0°
			CAL.	8.96°
ION	AR 18	39.9	REFERENCE	88.2
TARGET	CU 29	63.5		

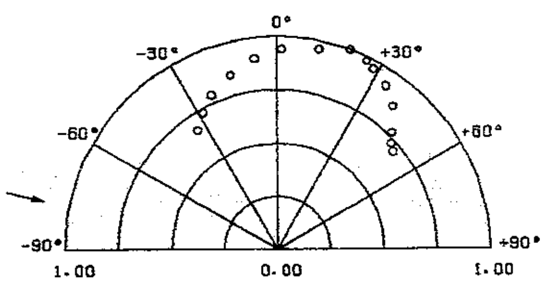


INFORMATION

88 2 4

AR ⇒ CU

INCIDENT ANGLE	78°		ENERGY (EV)	3.00×10^{4}
TARGET	POLY		EPSILON	3.21×10^{-1}
ENVIRONMENT	----------		GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU		Q	1.11×10^{-2}
			EJECTION ANGLE EXP.	20.0°
			CAL.	13.0°
ION	AR 18	39.9	REFERENCE	88.2
TARGET	CU 29	63.5		



INFORMATION

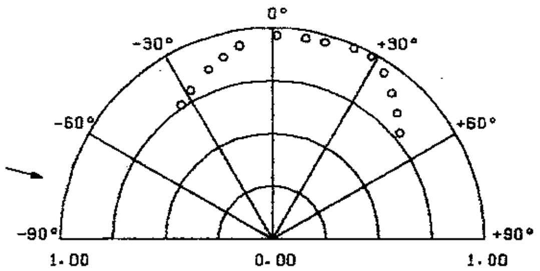
88 2 5

AR ⇒ CU

INCIDENT ANGLE	75°	ENERGY (EV)	3.00×10^{4}
TARGET	POLY	EPSILON	3.21×10^{-1}
ENVIRONMENT	----------	GAMMA	9.48×10^{-1}
SPUTTERED ATOM(S)	CU	Q	1.11×10^{-2}
		EJECTION ANGLE EXP.	25.7°
		CAL.	16.0°

ION	AR	18	39.9
TARGET	CU	29	63.5

REFERENCE 88.2



INFORMATION

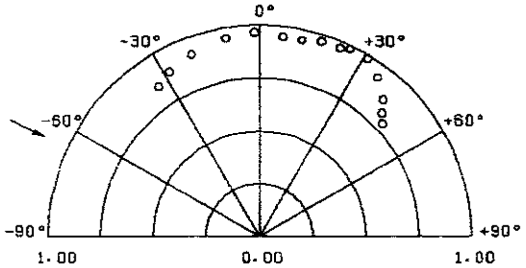
88 2 6

AR ⇒ CU

INCIDENT ANGLE	65°	ENERGY (EV)	3.00×10^{4}
TARGET	POLY	EPSILON	3.21×10^{-1}
ENVIRONMENT	----------	GAMMA	9.48×10^{-1}
SPUTTERED ATOM(S)	CU	Q	1.11×10^{-2}
		EJECTION ANGLE EXP.	30.0°
		CAL.	26.1°

ION	AR	18	39.9
TARGET	CU	29	63.5

REFERENCE 88.2

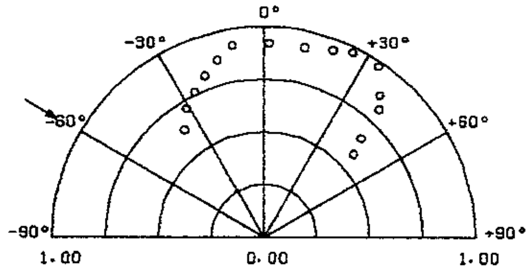


INFORMATION

88 2 7

AR ⇒ CU

INCIDENT ANGLE	60°		ENERGY (EV)	3.00×10^{4}
TARGET	POLY		EPSILON	3.21×10^{-1}
ENVIRONMENT	----------		GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU		Q	1.11×10^{-2}
			EJECTION ANGLE EXP.	29.7°
			CAL.	31.1°
ION	AR 18	39.9	REFERENCE	88.2
TARGET	CU 29	63.5		

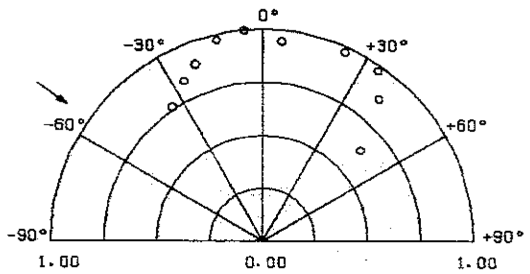


INFORMATION

88 2 8

AR ⇒ CU

INCIDENT ANGLE	55°		ENERGY (EV)	3.00×10^{4}
TARGET	POLY		EPSILON	3.21×10^{-1}
ENVIRONMENT	----------		GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU		Q	1.11×10^{-2}
			EJECTION ANGLE EXP.	30.5°
			CAL.	36.2°
ION	AR 18	39.9	REFERENCE	88.2
TARGET	CU 29	63.5		

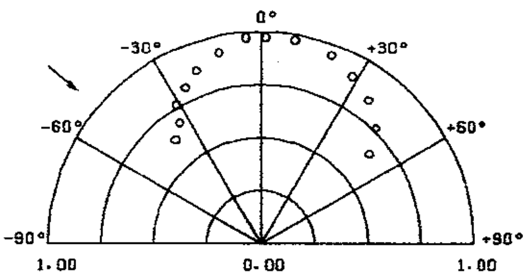


INFORMATION

88 2 9

AR ⇒ CU

INCIDENT ANGLE	50°	ENERGY (EV)	3.00×10^{4}
TARGET	POLY	EPSILON	3.21×10^{-1}
ENVIRONMENT	----------	GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU	Q	1.11×10^{-2}
		EJECTION ANGLE EXP.	0.00°
ION	AR 18 39.9	CAL.	41.3°
TARGET	CU 29 63.5	REFERENCE	88.2

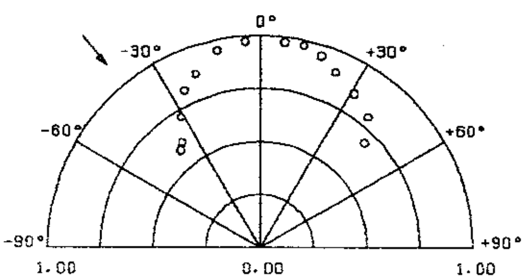


INFORMATION

88 2 10

AR ⇒ CU

INCIDENT ANGLE	40°	ENERGY (EV)	3.00×10^{4}
TARGET	POLY	EPSILON	3.21×10^{-1}
ENVIRONMENT	----------	GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU	Q	1.11×10^{-2}
		EJECTION ANGLE EXP.	0.00°
ION	AR 18 39.9	CAL.	51.5°
TARGET	CU 29 63.5	REFERENCE	88.2



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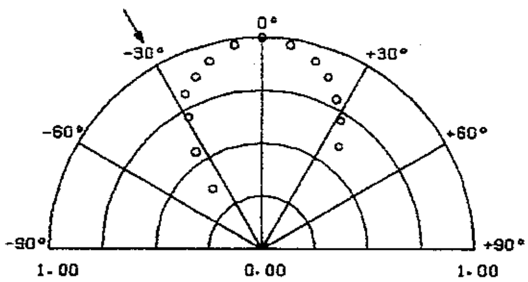
INFORMATION

88 2 11

AR ⇒ CU

INCIDENT ANGLE	30°			ENERGY (EV)	3.00×10^{4}
TARGET	POLY			EPSILON	3.21×10^{-1}
ENVIRONMENT	----------			GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU			Q	1.11×10^{-2}
				EJECTION ANGLE EXP.	0.00°
				CAL.	62.0°
ION	AR	18	39.9		
TARGET	CU	29	63.5	REFERENCE	88.2



INFORMATION

88 2 12

AR ⇒ CU

INCIDENT ANGLE	0°			ENERGY (EV)	3.00×10^{4}
TARGET	POLY			EPSILON	3.21×10^{-1}
ENVIRONMENT	----------			GAMMA	9.48×10^{-1}
SPUTTERED ATOM (S)	CU			Q	1.11×10^{-2}
				COS* N	3.26
ION	AR	18	39.9		
TARGET	CU	29	63.5	REFERENCE	88.2